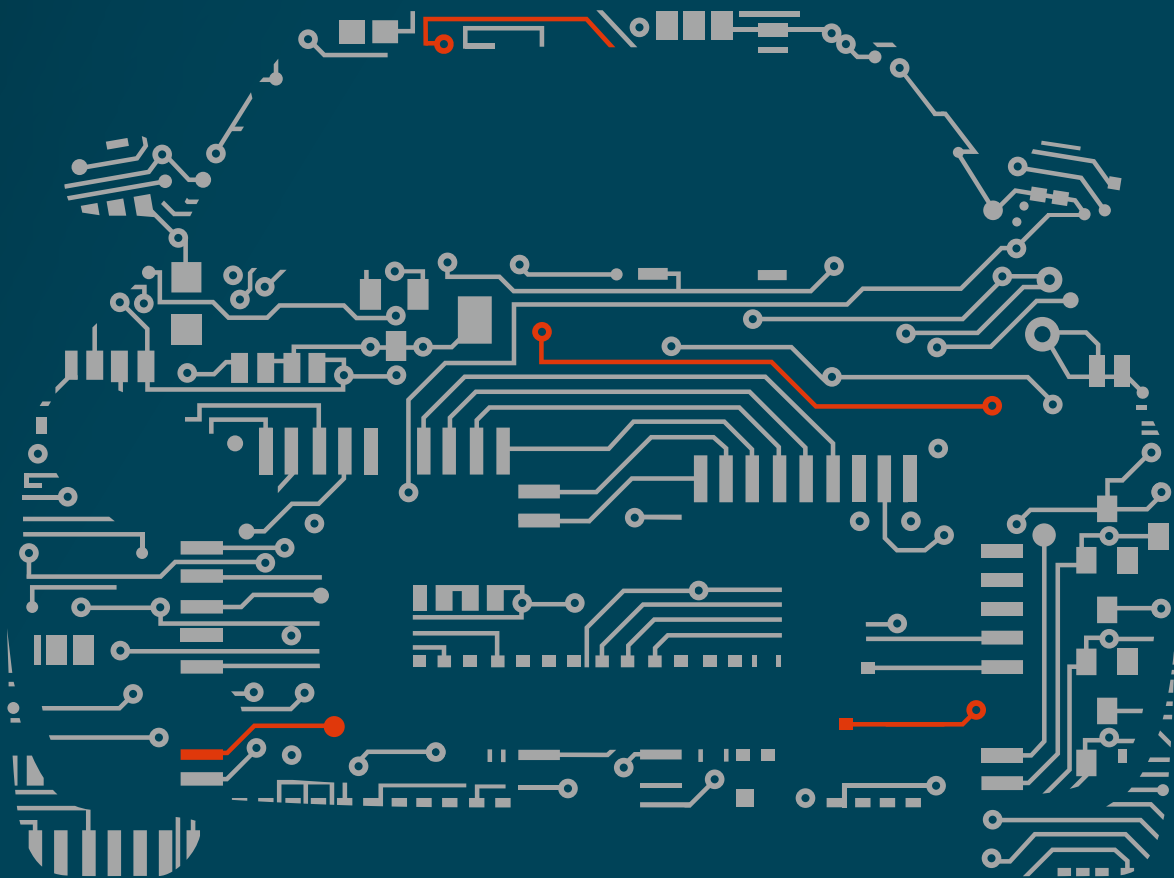


Automotive Selection guide 2019

Discretes, logic and MOSFETs

AEC-Q100/Q101 qualified



nexperia

EFFICIENCY WINS.

Driving efficiency takes pole position

Today's cars are undergoing the greatest transformation the industry has seen. Continued electrification is resulting in significant changes from the engine right through to the cloud. A lot of this is because vehicles need to be energy efficient, even as ever more electronic functionality is added to increase our safety and comfort.

Governments across the globe are stipulating mandates to reduce automotive CO₂ emissions to combat climate change and maintain resources. Obviously, the main focus is on the drivetrain – whether that is combustion, hybrid, or full electrical. However innovative technologies and systems for chassis, safety, lighting and body electronics are also helping drive up overall vehicle efficiency and reducing fuel consumption, CO₂ emissions and costs.

Consistently delivering the right functionality, with the right performance, in the right package is how Nexperia is helping 'driving efficiency' win. All our dedicated automotive devices are fully AEC-Q100/Q101 qualified. Our rigorous attention to detail and commitment to automotive quality yields sub-part-per-million (sub-ppm) failure rates.

Our energy- and design-efficient products are backed up by our own dedicated manufacturing facilities along with industry leading, proven supply chains that meet the long-term volume needs of the automotive industry. And along with traditional powertrain, chassis and body electronics our product and package innovation supports new and future system designs, from wireless car safety all the way through to electric vehicles.

So discover our complete dedicated automotive portfolio of Bipolar transistors, Diodes, ESD protection, MOSFETs and Logic devices in the **Nexperia Automotive Selection Guide 2019**. There is also a dedicated section on packages, highlighting the latest package innovations and packing options helping you to save space and weight. We hope this document makes it even easier for you to find the right product for your design.

Dirk Hildebrandt

VP Sales & Marketing Global Automotive

Our commitment: quality and reliability



AEC-Q100/Q101 qualified

We qualify our products according to the automotive AEC-Q100/Q101 standard and even exceed it's requirements, for instance when doing extended lifetime testing.



Go for quality

All our processes and manufacturing plants are subject to regular international and internal audits, including the following:

- › ISO9001
- › IATF16949 for automotive sites
- › ISO14001
- › OHSAS18001



Design for excellence

Nexperia's Design for Excellence (DfX) program ensures that each new development builds on past learning and that best practices are always employed. The result is continual product improvement.



Zero defect

Zero defect is our goal. To ensure continuous improvement failure analysis and the determination to find root causes is performed at all stages of development and production by adoption of quality-analysis tools and methods (e.g. Six-Sigma, Safe-Launch).

Rigorous attention to detail and commitment to quality have yielded a very low product failure rate of a single-digit part per billion (ppb).



Automotive Selection guide 2019

Discretes, Logic and MOSFETs
AEC-Q100/Q101 qualified

Bipolar
transistors

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TVS, filtering
and signal
conditioning

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Discrete, Logic and MOSFET devices for automotive applications

Powertrain 48V

- › DCDC converter 48V:12V
- › Battery management system
- › Belt-starter-generator
- › Electric super charger
- › Water pump

Powertrain 12V ICE

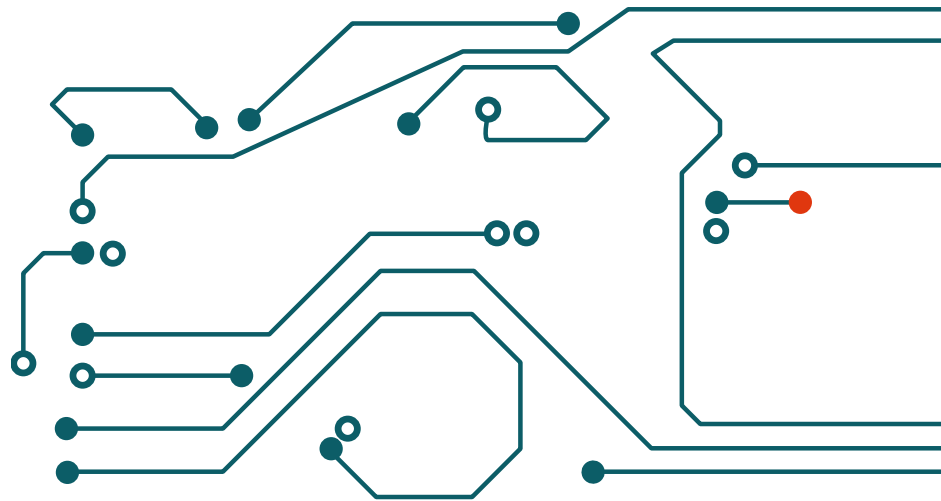
- › Engine control
- › Fuel pump
- › Transmission
- › Alternator, battery, and starter

Lighting

- › Front LED lighting
- › LED Daytime running light
- › Rear LED lighting
- › Interior LED lighting

Infotainment

- › Dashboard
- › Car audio
- › Connectivity audio
- › Entertainment
- › GPS
- › Car navigation display



Covering all basic functions enabling automotive electronic applications

- › Switching MOSFETs
- › ESD / surge protection
- › Battery protection
- › Free-wheeling diode

Networking & Diagnostic

- › CAN
- › LIN
- › FlexRay
- › Ethernet
- › BroadR-Reach
- › Bluetooth, WiFi
- › USB

Safety and control

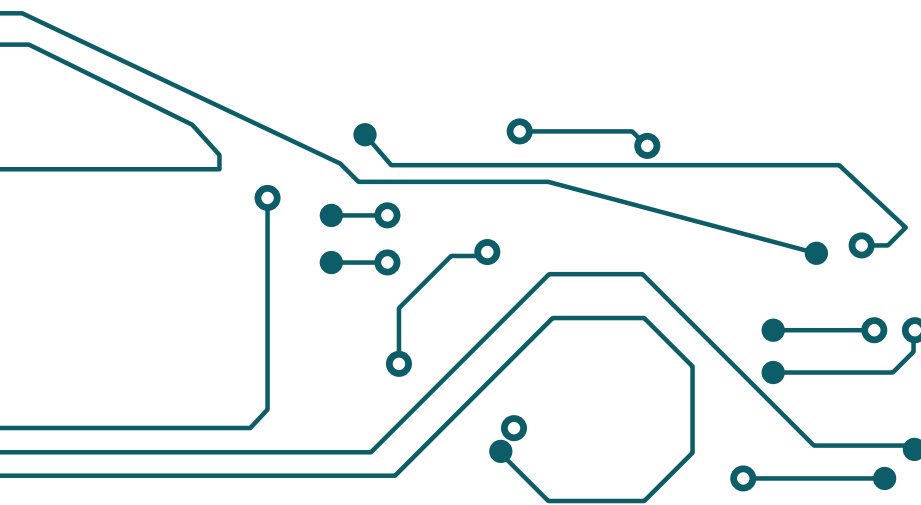
- › ADAS (camera, radar, lidar)
- › Airbag
- › TPMS
- › Collision warning
- › Parking assistant
- › Back monitor

Chassis

- › Steering / EPS
- › Braking / ABS
- › Electronic Parking Brake
- › Traction control
- › Suspension
- › Roll stabiliation

Comfort and control

- › Power door
- › Power window
- › Climate control
- › Seat control
- › Mirrow and wiper control



- › Flyback diode
- › DCDC conversion

- › Voltage regulation
- › Shift register

- › I/O expansion
- › LED drive

Technology focus: clip-bond packages

Thermally enhanced, space-saving, rugged package solutions

2 Pins
Schottky diodes,
PN rectifiers

CFP3 (SOD123W) 2.6 x 1.7 x 1.1	CFP5 (SOD128) 3.8 x 2.6 x 1.0	CFP15 (SOT1289) 5.8 x 4.3 x 0.78
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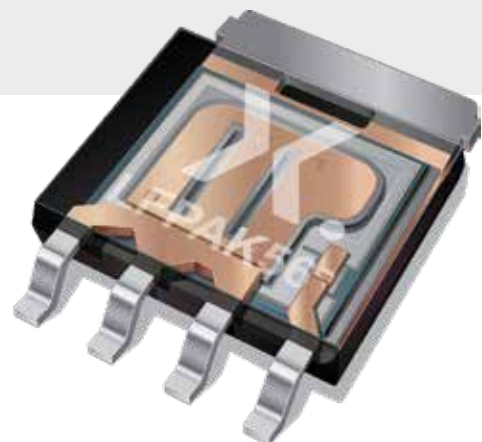
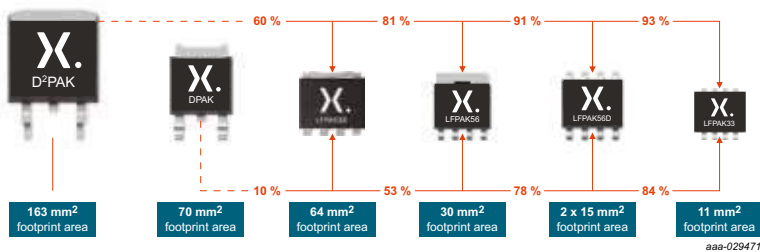
>4 Pins
MOSFETs,
Bipolar transistors

LFPAK33 (SOT1210) 3.3 x 3.3 x 0.85	LFPAK56 (SOT669) 5.0 x 6.0 x 1.0	LFPAK56D (SOT1205) 5.0 x 6.0 x 1.0	LFPAK88 (SOT1235) 8.0 x 8.0 x 1.75
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Miniaturization of Power





- > Solid wireless clip-bond packages for extra rugged and reliable operation
- > High-temperature use
- > High power density & efficiency
- > Space-saving solution for MOSFETs, diodes, bipolar transistors

LFPAK space efficiency



Technology focus: Leadless package solutions

Leadless D(Q)FN packages with side-wettable flanks, AOI capable. The ultimate space saving solution

<p>2 Pins Diodes, ESD protection</p>	 <p>DFN1006D-2 (SOD882D) 1.0 x 0.6 x 0.37</p> <p>DFN1608D-2 (SOD1608) 1.6 x 0.8 x 0.37</p>	<p>3 Pins MOSFETs, bipolar transistors, diodes</p>	 <p>DFN1010D-3 (SOT1215) 1.1 x 1.0 x 0.37</p> <p>DFN2020D-3 (SOT1061D) 2.0 x 2.0 x 0.62</p>
<p>6 Pins MOSFETs, bipolar transistors</p>	 <p>DFN2020D-6 (SOT1118D) 2.0 x 2.0 x 0.62</p> <p>DFN2020MD-6 (SOT1220) 2.0 x 2.0 x 0.62</p>	<p>>10 Pins Logic</p>	 <p>DHVQFN20 (SOT764-1) 2.5 x 4.5 x 0.85</p> <p>14 pin 16 pin 20 pin 24 pin versions</p>

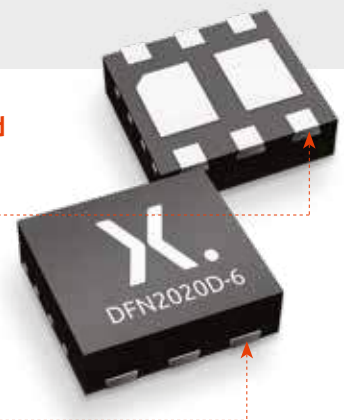
Automotive leadless

- > The ultimate space saving solution for automotive
- > High board level reliability, robust solder joints
- > Easy optical inspection, AOI capable
- > For Logic, ESD protection, diodes, bipolar transistors and MOSFETs



"Dimples"

Exposed tin-plated side-pads (side-wettable flanks)



Electrification of the car

Supported by product portfolio and roadmap

Increased electronic functions

(Braking, steering, fuel injection, automatic transmission)



Better safety

- › Schottkys and FRDs up to 200V with low IR and low VF
- › MOSFETs with high drain current capability. (ID), Avalanche ruggedness and low RDSon

Replacement of electric/mechanical relays



Higher reliability through MOSFETs

- › Power MOSFETs and Bipolar transistors
- › Space saving, power efficient, low noise

Increased information sensing & processing

(Networks, infotainment)



Protection for In-Vehicle Networking

ESD protection devices to safeguard interfaces of communication buses, IVN, infotainment systems (incl. solutions for Type-C connector)

ADAS *(Vision & Safety)*



Compact designs through Discretes in advanced packages

- › Schottky rectifiers up to 100V in DFN and CFP packages
- › Low VCEsat power bipolar transistors in LFPACK (175 °C) to support voltage regulation / core supply
- › ESD Protection

Electrification of the powertrain *(e.g. mild hybrids, plug-in hybrids)*



48V Power rail

- › DCDC converter 48V:12V
- › Battery management system
- › Belt-starter-generator
- › Electric super charger
- › Water pump
- › Power MOSFET 80V and 100V
- › Schottky rectifier up to 100V
- › FRD up to 200V



Bipolar transistors






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

General purpose bipolar transistors

Transistors single NPN


Types in **bold** represent new products

Package					SOT23	SOT323 (SC-70)	DFN1010D-3 (SOT1215)	DFN1006-3 (SOT883)	DFN1006B-3 (SOT883B)
									
Size (mm)					2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	1.1 x 1.0 x 0.37	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37
P _{tot} (mW)					250	200	750	250	250
V _{CE0} (V)	I _C (mA)	h _{FE} min/typ	h _{FE} max	f _T min (MHz)					
25	100	450	1200	100		PMST5089			
30	100	110 - 200	450 - 800	100	BC848B	BC848W			
		350	900	100		PMST5088			
32	100	110 - 420	220 - 800	100	BCW31 / 32 / 33				
		180 - 380	310 - 630	250	BCW60B / C / D				
45	100	110 - 420	220 - 800	100	BC847 / A / B / C	BC847W / AW / BW / CW	BC847AQA / BQA / CQA	BC847AM / BM / CM	BC847AMB / BMB / CMB
		120 - 380	220 - 630	100	BCX70G / H / J / K				
		110 - 200	220 - 450	100	BCW71 / 72				
		500	1250	100	PMBT6429	PMST6429			
50	100	210 - 290	340 - 460	100 - 150	2PD601ART 2PD601ARL 2PD601ASL	2PD601ARW / SW			
		250	650	100	PMBT6428	PMST6428			
60	100	110 - 200	220 - 450	100	BCV71 / 72				
65	100	110 - 200	220 - 450	100	BC846 / A / B	BC846W / AW / BW		BC846BM	BC846BMB
50	150	120 - 200	240 - 400	80	NXP3875Y / G				
		120 - 270	270 - 560	100		2PC4081Q / R / S		2PC4617QM / RM	2PC4617QMB / RMB
	200	210	340	100	2PD601BRL				
		290	460	100	2PD601BSL				
45	500	100 - 250	250 - 600	100	BC817 / -16 / -25 / -40	BC817W / -16W / -25W / -40W	BC817-25QA/-40QA		
		100	600	100	BCX19				
50	500	85 - 170	170 - 340	140 - 180	2PD602AQL 2PD602ARL 2PD602ASL	2PD1820AR / S			
60	500	50	-	100		PMSTA05			
80	500	100	-	50	PMBTA06	PMSTA06			
45	800	100-250	250-600	100	BCW66F/G/H				





Transistors single PNP

Package					SOT23	SOT323 (SC-70)	DFN1010D-3 (SOT1215)	DFN1006-3 (SOT883)	DFN1006B-3 (SOT883B)
									
Size (mm)					2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	1.1 x 1.0 x 0.37	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37
P _{tot} (mW)					250	200	750	250	250
V _{CE0} (V)	I _C (mA)	h _{FE} min/typ	h _{FE} max	f _T min (MHz)					
30	100	125 - 220	500 - 800	100	BC858B	BC858W			
32	100	120 - 215	260 - 500	100	BCW29 / 30				
		180 - 380	310 - 630	100	BCW61B / C / D				
45	100	210 - 290	340 - 460	70 - 80	2PB709ART 2PB709ARL 2PB709ASL	2PB709ARW / SW			
		180 - 380	310 - 630	100	BCX71H / J / K				
		120 - 215	260 - 500	100	BCW69 / 70				
		125 - 420	250 - 800	100	BC857 / A / B / C	BC857W / AW / BW / CW	BC857AQA / BQA / CQA	BC857AM / BM / CM	BC857AMB / BMB / CMB
60	100	120	260	150	BCW89				
65	100	125 - 200	250 - 475	100	BC856 / A / B	BC856W / AW / BW		BC856BM	BC856BMB
100	100	30	-	50	BSS63				
50	150	120 - 270	270 - 560	100		2PA1576Q / R / S		2PA1774QM / RM / SM	2PA1774QMB / RMB / SMB
		210	340	100	2PB709BRL				
	200	290	460	100	2PB709BSL				
25	500	100	600	80	BCX18				
45	500	100 - 250	250 - 600	80	BC807 / -16 / -25 / -40	BC807W / -16W / -25W / -40W	BC807-25QA/-40QA		
		100	600	80	BCX17				
50	500	85 - 170	170 - 340	100 - 140	2PB710ARL 2PB710ASL	2PB1219AQ / R / S			
60	500	100	-	50		PMSTA55			
80	500	100	-	50	PMBTA56	PMSTA56			
45	800	100-250	250-600	80	BCW68F/G/H				

High performance transistors (superior power dissipation)

Package							SOT23
							
Size (mm)							2.9 x 1.3 x 1.0
P _{tot} (mW)							775
Polarity	V _{CEO} (V)	V _{ebo} (V)	I _C (mA)	h _{FE} min	h _{FE} max	f _T min (MHz)	
NPN	45	5	0.5	100	250	100	BC817K-16
				160	400	100	BC817K-25
				250	600	100	BC817K-40
PNP	45	5	0.5	100	250	80	BC807K-16
				160	400	80	BC807K-25
				250	600	80	BC807K-40

Transistors double

Package						SOT457 (SC-74)	SOT363 (SC-88)	DFN1412-6 (SOT1268)	DFN1010B-6 (SOT1216)	
										
Size (mm)						2.9 x 1.5 x 1.0	2.0 x 1.25 x 0.95	1.4 x 1.2 x 0.5	1.0 x 1.0 x 0.37	
P _{tot} (mW)						750	300	480	350	
Polarity	V _{CEO} (V)	I _C (mA)	h _{FE} min	h _{FE} max	f _T min (MHz)					
NPN	40	100	120	450	100		PUMX1			
	45	100	200	450	100	BC847DS	BC847BS	BC847RA	BC847QAS	
	65	100	110	-	100			BC846S		
			200	450	100	BC846DS	BC846BS			
	50	150	120	560	100			PUMX2		
45	500	160	400	80	BC817DS			BC817RA		
PNP	40	100	120	450	100	PIMT1	PUMT1			
	45	100	200	450	100		BC857BS	BC857RA	BC857QAS	
	65	100	110	-	100			BC856S		
			200	450	100		BC856BS			
45	500	160	400	80	BC807DS			BC807RA		
NPN / PNP	40	100	120	450	100			PUMZ1		
	45	100	200	450	100			BC847BPN	BC847RAPN	BC847QAPN
	50	100	120	560	100	PIMZ2		PUMZ2		
	65	100	200	450	100			BC846BPN		
	45	500	160	160	100 / 800	BC817DPN			BC817RAPN	

General purpose bipolar transistors

Medium power transistors high performance (175°C capable)

Package							SOT223 (SC-73)
Size (mm)							6.5 x 3.5 x 1.65
P _{tot} (mW)							1700
Polarity	V _{CEO} (V)	V _{EBO} (V)	I _C (A)	h _{FE} min	h _{FE} max	f _T min(MHz)	
NPN	80	7	1	63	250	100	BCP56H
					160	100	BCP56-10H
				100	250	100	BCP56-16H
PNP	80	7	1	63	250	100	BCP53H
					100	100	BCP53-10H
				100	250	100	BCP53-16H

NPN High performance transistors (175°C capable & superior power dissipation)

Package							SOT23	
Size (mm)							2.9 x 1.3 x 1.0	
P _{tot} (mW)							950	
Polarity	V _{CEO} (V)	V _{EBO} (V)	I _C (A)	h _{FE} min	h _{FE} max	f _T min(MHz)		
NPN	45	7	0.5	100	250	100	BC817K-16H	
					160	400	100	BC817K-25H
				250	600	100	BC817K-40H	

PNP High performance transistors (175°C capable & superior power dissipation)

Types in **bold** represent new products

Package							SOT23	
Size (mm)							2.9 x 1.3 x 1.0	
P _{tot} (mW)							675	
Polarity	V _{CEO} (V)	V _{EBO} (V)	I _C (A)	h _{FE} min	h _{FE} max	f _T min(MHz)		
NPN	45	7	0.5	100	250	80	BC807-16H	
					160	400	80	BC807-25H
				250	600	80	BC807-40H	

Medium power transistors

Package						SOT223 (SC-73)	SOT89 (SC-62)	DFN2020-3 (SOT1061)	DFN2020D-3 (SOT1061D)
Size (mm)						6.5 x 3.5 x 1.65	4.5 x 2.5 x 1.5	2.0 x 2.0 x 0.62	2.0 x 2.0 x 0.62
P _{tot} (mW)						1700	1300	1300	1300
Polarity	V _{CEO} (V)	I _C (mA)	h _{FE} min	h _{FE} max	f _T min (MHz)				
NPN	20	2	85 - 160	375	40	BCP68 / -25	BC868 / -25	BC68PA / BC68-25PA	BC68PAS / BC68-25PAS
	45	1	63 - 100	160 - 250	100	BCP54 / -10 / -16	BCX54 / -10 / -16	BC54PA / BC54-10PA / BC54-16PA	BC54PAS / BC54-10PAS / BC54-16PAS
	60	1	63 - 100	160 - 250	100	BCP55 / -10 / -16	BCX55 / -10 / -16	BC55PA / BC55-10PA / BC55-16PA	BC55PAS / BC55-10PAS / BC55-16PAS
			100	300	100	BSP41	BSR41		
	80	1	63 - 100	160 - 250	100	BCP56 / -10 / -16	BCX56 / -10 / -16	BC56PA / BC56-10PA / BC56-16PA	BC56PAS / BC56-10PAS / BC56-16PAS
			40 - 100	120 - 300	100	BSP43	BSR43		
PNP	20	2	85 - 160	250 - 375	40	BCP69 / -16 / -25	BC869 / -16 / -25	BC69PA / BC69-16PA / BC69-25PA	BC69PAS / BC69-16PAS / BC69-25PAS
	45	1	63 - 100	160 - 250	115 ¹⁾ - 145 ¹⁾	BCP51 / -10 / -16	BCX51 / -10 / -16	BC51PA / BC51-10PA / BC51-16PA	BC51PAS / BC51-10PAS / BC51-16PAS
	60	1	63 - 100	160 - 250	100	BCP52 / -10 / -16	BCX52 / -10 / -16	BC52PA / BC52-10PA / BC52-16PA	BC52PAS / BC52-10PAS / BC52-16PAS
			40 - 100	120 - 300	100	BSP31	BSR30 / 31		
	80	1	63 - 100	160 - 250	115 ¹⁾ - 145 ¹⁾	BCP53 / -10 / -16	BCX53 / -10 / -16	BC53PA / BC53-10PA / BC53-16PA	BC53PAS / BC53-10PAS / BC53-16PAS
			40 - 100	120 - 300	100	BSP32 / 33	BSR33		

¹⁾ Typical value



High voltage transistors

Package						SOT223 (SC-73)	SOT89 (SC-62)	SOT457 (SC-74)	SOT23	SOT323 (SC-70)
Size (mm)						6.5 x 3.5 x 1.65	4.5 x 2.5 x 1.5	2.9 x 1.5 x 1.0	2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95
P _{tot} (mW)						1700	1300	750	250	200
Polarity	V _{CEO} (V)	I _C (mA)	h _{FE} min	h _{FE} max	f _T min (MHz)					
NPN	140	300	60	250	100				PMBT5550	PMST5550
	160	300	80	250	100				PMBT5551 / BSR19A	PMST5551
	250	100	50		60	BF722	BF622		BF822	
	300	100	50		60	BF720	BF620		BF820	BF820W
			40		50	PZTA42	PXTA42		PMBTA42	PMSTA42
	350	100	40		70	BSP19	BST39			
400	300	50	200	20	PZTA44			PMBTA44		
PNP	100	100	30		50				BSS63	
	250	100	50		60	BF723				
			50		60		BF623		BF823	
	300	100	50		60		BF621		BF821	
40				50	PZTA92	PXTA92		PMBTA92	PMSTA92	
2 x NPN	300	100	40		50				PMBTA42DS	


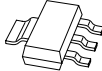
For high-voltage transistors with increased performance please refer to our high-voltage low V_{CEsat} (BISS) transistor portfolio on page 23.

General purpose bipolar transistors


LED driver

Package		SOT457	SOT23
			
Size (mm)		2.9 x 1.5 x 1.0	2.9 x 1.3 x 1.0
P _{tot} (mW)		750	480
Vs supply voltage [V]		LED drive current [mA] @ Vs=10V	
18			NCR401T
		10	NCR402T
40		10	NCR401U
		20	NCR402U
		50	NCR405U




LED driver NPN

Package		SOT457	SOT223
			
Size (mm)		2.9 x 1.5 x 1.0	6.5 x 3.5 x 1.65
P _{tot} (mW)		750	1250
Vs supply voltage [V]		Max Output Current I _{Out} [mA]	
16		250	NCR320U
			NCR321U
40		150	NCR420U
			NCR421U
16		250	NCR320Z
			NCR321Z
40		150	NCR420Z
			NCR421Z


Constant current source

SOT353 (SC-88A)					
Package					
Size (mm)	2.0 x 1.25 x 0.95				
P _{tot} (mW)	335				
Type	PSSI2021SAY				
Description	Maximum supply voltage	Maximum supply current	Typical stabilized output current	Minimum stabilized output current	Maximum stabilized output current
Parameter	V _s max (V)	I _s max (mA)	I _{out} typ (μA)	I _{out} min (mA)	I _{out} max (mA)
Value	75	2.2	15	0.015	50



Darlington transistors

Package					SOT223 (SC-73)	SOT89 (SC-62)	SOT23	
								
Size (mm)					6.5 x 3.5 x 1.65	4.5 x 2.5 x 1.5	2.9 x 1.3 x 1.0	
P _{tot} (mW)					1700	1300	250	
Polarity	V _{CEO} (V)	I _C (mA)	h _{FE} min	f _T min (MHz)				
NPN	30	500	10000	125	PMBTA13			
			20000		PZTA14	PXTA14	PMBTA14	
	45	1000	1000	2000	200	BCV29		BCV27
				2000	200	BCV49		BCV47
				10000	220	BSP51		BST51
				2000	200	BSP52		BST52
PNP	30	500	20000	125	PMBTA64			
			2000	200	BCV28		BCV26	
	45	1000	1000	2000	200	BSP60		BST60
				10000	220	BCV48		BCV46
60	1000	2000	2000	200	BSP61		BST61	
			2000	200	BSP62		BST62	

Schmitt triggers









Package							SOT143B
							
Size (mm)							2.9 x 1.3 x 1.0
P _{tot} (mW)							250
Polarity	V _{CEO} (V) TR1	V _{CEO} (V) TR2	I _C (mA)	h _{FE} min	h _{FE} max	V _{CEsat} typ (mV)	
NPN	30	6	100	110	800	250	BCV63 / B
PNP	30	6	100	220	475	250	BCV64B

Low noise transistors

Package							SOT23	SOT323 (SC-70)
								
Size (mm)							2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95
P _{tot} (mW)							250	200
Polarity	V _{CEO} (V)	I _C (mA)	Noise figure max (dB)	h _{FE} min	h _{FE} max	f _T min (MHz)		
NPN	30	100	4	200	450	100	BC849B	BC849BW
				420	800	100	BC849C	BC849CW
	45	100	4	200	450	100	BC850B	BC850BW
				420	800	100	BC850C	BC850CW
PNP	30	100	4	220	475	100	BC859B	BC859BW
				420	800	100	BC859C	BC859CW
	45	100	4	220	475	100	BC860B	BC860BW
				420	800	100	BC860C	BC860CW









General purpose bipolar transistors

Matched pair transistors - part 1

Package							SOT143B	SOT457 (SC-74)	LFPAK56D (SOT1205)	
Size (mm)							2.9 x 1.3 x 1.0	2.9 x 1.5 x 1.0	5 x 6 x 1.1	
P _{tot} (mW)							250	750	1250	
Polarity	V _{CEO} (V)	I _C (mA)	h _{FE} min	h _{FE} max	h _{FE1} /h _{FE2}	V _{BE1} - V _{BE2} (mV)				
NPN	30	100	110	800	0.7 ¹⁾	n.a.	BCV61/A/B/C			
	45	100	200	450	0.9 ¹⁾	n.a.	BCM61B			
						2		BCM847DS		
	80	1000	63	250	0.95	n.a.		BCM56DS		
	100	3000	150	-	0.95	n.a.			PHPT61003SNK	
Configuration										
PNP	30	100	100	800	0.7 ¹⁾	n.a.	BCV62/A/B/C			
	45	100	200	450	0.9 ¹⁾	n.a.	BCM62B			
						2		BCM857DS		
	65	100	200	450	0.9	2		BCM856DS		
	80	1000	63	250	0.95	n.a.		BCM53DS		
	100	3000	150	-	0.9	n.a.			PHPT61003SPK	
Configuration										


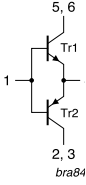

¹⁾ I_{C1} / I_{E2}

Matched pair transistors - part 2



Package							SOT353 (SC-88A)	SOT363 (SC-88)	SOT1216 (DFN1010B-6)		
Size (mm)							2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.1 x 1.0 x 0.37		
P _{tot} (mW)							300	300	350		
Polarity	V _{CEO} (V)	I _C (mA)	h _{FE} min	h _{FE} max	h _{FE1} /h _{FE2}	V _{BE1} - V _{BE2} (mV)					
NPN	45	100	200	450	0.9 ¹⁾	2		BCM847BS			
					0.95	2	PMP4501G	PMP4501Y	BCM847QAS	PMP4501QAS	
					0.98	2	PMP4201G	PMP4201Y			
	65	100	200	450	0.9	2		BCM846BS			
	Configuration										
PNP	45	100	200	450	0.9 ¹⁾	2		BCM857BS			
					0.95	2	PMP5501G	PMP5501Y	BCM857QAS	PMP5501QAS	
					0.98	2	PMP5201G	PMP5201Y			
	65	100	200	450	0.9	2		BCM856BS			
	Configuration										

¹⁾ I_{C1} / I_{E2}





MOSFET driver

V_{CE0} (V)	I_C (A)	I_{cm} [A]	Type	Package	Remark	Configuration
30	0.1	0.2	BCV65	SOT143B 	General-purpose transistors	
40	0.6	1	PMD2001D	SOT457 	Switching transistors with reduced storage time	
	1	2	PMD3001D		Low V_{CEsat}	

Medium frequency transistors

						SOT23	SOT323 (SC-70)
Package							
Size (mm)						2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95
P_{tot} (mW)						250	200
Polarity	V_{CE0} (V)	I_C (mA)	h_{FE} min	h_{FE} max	f_T typ (MHz)		
NPN	15	100	40	-	500	BF570	
	20	25		85	>275	BF520	BF520W
		30	65	225	260	BF519	
	40	25	67	220	380	BF840	
PNP	30	25	25	50	250	BF824	BF824W
	40		50	-	>325	BF550	







Low V_{CEsat} (BISS) transistors single NPN up to 2000 mW

Package							SOT223 (SC-73)	SOT89 (SC-62)	SOT457 (SC-74)	DFN2020D-3 (SOT1061D)
										
Size (mm)							6.5 x 3.5 x 1.65	4.5 x 2.5 x 1.5	2.9 x 1.5 x 1.0	2.0 x 2.0 x 0.62
P_{tot} (mW)							1700	1650	750	1300
V_{CE0} (V)	I_C (A)	I_{CM} (A)	h_{FE} min/typ	@ I_C (A)	@ V_{CE} (V)	V_{CEsat} typ (mV); $I_C = 0.5$ A; $I_B =$ 0.05 A				
12	5.3	10.6	300/530	0.5	2	18		PBSS301NX		
	5.8	11.6	300/530	0.5	2	18	PBSS301NZ			
	6	7	280/440	0.5	2	20				
20	3	5	220/390	0.5	2	40		PBSS4320X		
	4	15	300/450	0.5	2	30			PBSS301ND	
	5	10	300/450	0.5	2	35		PBSS4520X		
	5.3	10.6	300/570	0.5	2	20		PBSS302NX		
	5.8	10.2	300/570	0.5	2	20	PBSS302NZ			
	6	7	280/440	0.5	2	20				
	7	15	300/550	0.5	2	12		PBSS4021NX		
	8	20	300/550	0.5	2	9	PBSS4021NZ			
30	3	5	300/490	0.5	2	45		PBSS4330X		
	3	5	300/465	0.5	2	40				PBSS4330PAS
	3.5	6	300/500	0.5	2	70			PBSS4032ND ³⁾	
	4.7	10	300/500	0.5	2	57		PBSS4032NX ³⁾		
	5.1	10.2	300/480	0.5	2	20		PBSS303NX		
	5.4	10	300/500	0.5	2	57	PBSS4032NZ ³⁾			
	5.5	11	300/480	0.5	2	20	PBSS303NZ			
	6	7	280/450	0.5	2	21				
40	2	3	300/-	0.5	5	140		PBSS4240X		
	4	15	300/520	0.5	2	35			PBSS302ND	
		10	300/500	0.5	2	21		PBSS4540X		
	5	10	300/500	0.5	2	25	PBSS4540Z			
50	2	5	300/-	0.5	2	90 ²⁾		PBSS4250X		
	3	5	200/280	0.5	2	65			PBSS4350D	
			300/460	0.5	2	50		PBSS4350X		
			200/280	0.5	2	60 ¹⁾	PBSS4350Z			
60	1	2	170/-	0.5	10	200 ²⁾		PBSS4160X		
	3	6	200/360	0.5	5	45				PBSS4360PAS
			200/-	0.5	5	45	PBSS4360Z	PBSS4360X		
			345/570	0.5	2	40			PBSS303ND	
	4.7	9.4	300/520	0.5	2	25		PBSS304NX		
	5.2	10.4	300/520	0.5	2	25	PBSS304NZ			
	6	7	280/440	0.5	2	22				
	6.2	15	300/500	0.5	2	17		PBSS4041NX		
7	15	300/500	0.5	2	13	PBSS4041NZ				
80	3	6	240/360	0.5	2	40			PBSS304ND	
	4	10	250/400	0.5	2	25		PBSS4480X		
	4.6	9.2	300/470	0.5	2	25		PBSS305NX		
	5.1	10.2	300/470	0.5	2	25	PBSS305NZ			
	5.6	7	270/425	0.5	2	25				
100	1	3	150/290	0.25	10	75			PBSS8110D	
			150/290	0.25	10	73		PBSS8110X		
			150/290	0.25	10	73	PBSS8110Z			
	3	4	170/275	0.5	2	45			PBSS305ND	
	4.5	9	200/330	0.5	2	27		PBSS306NX		
	5.1	10.2	200/330	0.5	2	27	PBSS306NZ			

¹⁾ $I_C/I_B = 20$ ²⁾ V_{CEsat} (max) ³⁾ Optimized for high-speed switching





Low V_{CEsat} (BISS) transistors single NPN up to 750 mW

Types in **bold** represent new products

Package							SOT23	SOT323 (SC-70)	SOT363 (SC-88)	DFN1006-3 (SOT883)	DFN1006B-3 (SOT883B)	DFN1010D-3 (SOT1215)
												
Size (mm)							2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37	1.1 x 1.0 x 0.37
P _{tot} (mW)							480	350	430	250	250	750
V _{CE0} (V)	I _C (A)	I _{CM} (A)	h _{FE} min/typ	@ I _C (A)	@ V _{CE} (V)	V _{CEsat} typ (mV); I _C = 0.5 A; I _B = 0.05 A						
15	0.5	1	200/325	0.01	2	-				PBSS2515M	PBSS2515MB	
20	1	3	350/470	0.1	2	110 ²⁾	PBSS4120T					
	2	5	220/330	0.1	2	45	PBSS4320T					
	4.3	8	300/550	0.5	2	21	PBSS4021NT					
30	1	1.5	230/380	0.5	2	90						PBSS4130QA
		3	300/450	0.5	2	120 ²⁾	PBSS4130T					
	2	3	300/450	0.5	2	70	PBSS4230T					
			230/380	0.5	2	75						PBSS4230QA
2.6	5	300/500	0.5	2	80	PBSS4032NT ³⁾						
40	0.5	1	200/550	0.01	2	200 ²⁾				PBSS2540M	PBSS2540MB	
			300/440	0.5	5	130		PBSS4140U				
			300/510	0.5	5	120	PMMT491A					
	2	3	300/420	0.5	5	130	PBSS4140T					
			350/470	0.1	2	70			PBSS4240Y			
300/450	0.5	2	70	PBSS4240T								
50	2	5	300/495	0.5	2	60	PBSS4350T					
60	1	1.5	150/240	0.5	2	90						PBSS4160QA
			200/420	0.5	5	120		PBSS4160U				
		200/350	0.5	5	110	PBSS4160T						
	2	3	150/240	0.5	2	75					PBSS4260QA	
	3.8	8	300/500	0.5	2	29	PBSS4041NT					
100	1	3	150/400	0.25	10	80			PBSS8110Y			
			150/300	0.25	10	70	PBSS8110T					







¹⁾ I_C/I_B = 20 ²⁾ V_{CEsat} (max) ³⁾ Optimized for high-speed switching

Low V_{CEsat} (BISS) transistors single PNP up to 2000 mW

Package							SOT223 (SC-73)	SOT89 (SC-62)	SOT457 (SC-74)	DFN2020D-3 (SOT1061D)
										
Size (mm)							6.5 x 3.5 x 1.65	4.5 x 2.5 x 1.5	2.9 x 1.5 x 1.0	2.0 x 2.0 x 0.62
P _{tot} (mW)							1700	1650	750	1300
V _{CEO} (V)	I _C (A)	I _{CM} (A)	h _{FE} min/typ	@ I _C (A)	@ V _{CE} (V)	V _{CEsat} typ (mV); I _C = 0.5 A; I _B = 0.05 A				
12	5.3	10.6	250/400	0.5	2	20		PBSS301PX		
	5.7	11.4	250/400	0.5	2	20	PBSS301PZ			
	6	7	220/335	0.5	2	20				
20	3	5	200/-	0.5	2	80 ²⁾			PBSS5320D	
			220/450	0.5	2	50		PBSS5320X		
	4	15	250/400	0.5	2	35			PBSS301PD	
	5	10	300/430	0.5	2	45				
	5.1	10.2	250/370	0.5	2	25			PBSS302PX	
	5.5	11	250/370	0.5	2	25	PBSS302PZ			
	6	7	230/345	0.5	2	25				
	6.2	15	250/400	0.5	2	18			PBSS4021PX	
	6.6	20	250/400	0.5	2	16	PBSS4021PZ			
30	2.7	5	200/350	0.5	2	87			PBSS4032PD ³⁾	
	3	5	200/380	0.5	2	50			PBSS5330X	
			200/320	0.5	2	45				PBSS5330PAS
	4.2	10	200/350	0.5	2	70			PBSS4032PX ³⁾	
	4.4	10	200/350	0.5	2	70	PBSS4032PZ ³⁾			
	5.1	10.2	250/400	0.5	2	25			PBSS303PX	
	5.3	10.6	250/400	0.5	2	25	PBSS303PZ			
6	7	200/335	0.5	2	25					
40	2	3	215/-	0.5	5	170			PBSS5240X	
	4	15	200/310	0.5	2	46				PBSS302PD
			250/370	0.5	2	33			PBSS5540X	
5	10	250/350	0.5	2	40 ¹⁾	PBSS5540Z				
50	2	5	200/-	0.5	2	90 ²⁾			PBSS5250X	
	3	5	200/300	0.5	2	70				PBSS5350D
			200/375	0.5	2	70			PBSS5350X	
			200/300	0.5	2	70	PBSS5350Z			
60	3	6	130/220	0.5	5	55				PBSS5360PAS
			130/-	0.5	5	55	PBSS5360Z	PBSS5360X		
			180/265	0.5	2	55				PBSS303PD
	4.2	8.4	200/295	0.5	2	35			PBSS304PX	
	4.5	9	200/295	0.5	2	35	PBSS304PZ			
	5	6	170/260	0.5	2	35				
	5	15	200/300	0.5	2	30			PBSS4041PX	
5.7	200/300		0.5	2	22	PBSS4041PZ				
80	3	5	155/225	0.5	2	55				PBSS304PD
			180/265	0.5	2	40				
	4	10	200/300	0.5	2	35			PBSS5480X	
			200/280	0.5	2	36			PBSS305PX	
4.5	9	200/280	0.5	2	36	PBSS305PZ				
100	1	3	150/350	0.5	5	100				PBSS9110D
			150/350	0.5	5	90			PBSS9110X	
			150/-	0.5	5	90	PBSS9110Z			
	2	3	175/275	0.5	2	65				PBSS305PD
	2.7	4	180/295	0.5	2	45				
	3.7	7.4	200/300	0.5	2	45			PBSS306PX	
4.1	8.2	200/300	0.5	5	45	PBSS306PZ				




¹⁾ I_C / I_B = 20 ²⁾ V_{CEsat} (max) ³⁾ Optimized for high-speed switching

Low V_{CEsat} (BISS) transistors single PNP up to 750 mW

Package							SOT23	SOT323 (SC-70)	SOT363 (SC-88)	DFN1006-3 (SOT883)	DFN1006B-3 (SOT883B)	DFN1010D-3 (SOT1215)
												
Size (mm)							2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37	1.1 x 1.0 x 0.37
P _{tot} (mW)							480	350	430	250	250	750
V _{CE0} (V)	I _C (A)	I _{CM} (A)	h _{FE} min/typ	@ I _C (A)	@ V _{CE} (V)	V _{CEsat, typ} (mV); I _C = 0.5 A; I _B = 0.05 A						
15	0.5	1	200/260	0.01	2	150			PBSS3515M	PBSS3515MB		
20	1	2	300/450	0.1	2	125 ²⁾	PBSS5120T					
	2	3	225/-	0.5	2	80 ²⁾	PBSS5220T					
		5	220/420	0.5	2	50	PBSS5320T					
	3.5	8	250/400	0.5	2	35	PBSS4021PT					
30	1	1.5	180/295	0.5	2	85						PBSS5130QA
			260/350	0.5	2	110	PBSS5130T					
	2	3	300/450	0.1	2	70	PBSS5230T					
			180/295	0.5	2	70						PBSS5230QA
	2.4	5	200/320	0.5	2	95	PBSS4032PT ³⁾					
40	0.5	1	200/380	0.01	2	220			PBSS3540M	PBSS3540MB		
		1	2	300/520	0.1	5	130		PBSS5140U			
				300/800	0.1	5	130	PMMT591A				
		300/510	0.1	5	130	PBSS5140T						
	2	3	300/-	0.1	2	110 ²⁾			PBSS5240Y			
			300/450	0.1	2	70	PBSS5240T					
50	2	3	200/-	0.5	2	90 ²⁾	PBSS5250T					
		5	200/360	0.5	2	55	PBSS5350T					
	3	3	200/-	0.5	2	90 ²⁾	PBSS5250TH PBSS5350TH					
60	1	1.5	120/185	0.5	2	125						PBSS5160QA
		2	150/250	0.5	5	135		PBSS5160U				
			150/250	0.5	5	120	PBSS5160T					
	1.7	2.5	120/185	0.5	2	105						PBSS5260QA
	2.7	8	200/300	0.5	2	49	PBSS4041PT					
100	1	3	150/-	0.25	5	93			PBSS9110Y			
			150/350	0.5	5	95	PBSS9110T					



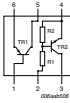
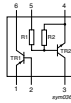
¹⁾ IC / IB = 20 ²⁾ V_{CEsat} (max) ³⁾ Optimized for high-speed switching

Low V_{CEsat} (BISS) transistors double

Package										SOT457 (SC-74)	DFN2020-6 (SOT1118)	DFN2020D-6 (SOT1118D)	
													
Size (mm)										2.9 x 1.5 x 1.0	2.0 x 2.0 x 0.62	2.0 x 2.0 x 0.62	
P_{tot} (mW)										750	1300	1300	
V_{CE0} (V)	I_c (A)	Polarity	h_{FE} min/typ	@ I_c (A)	@ V_{CE} (V)	V_{CEsat} typ (mV); $I_c = 0.5$ A; $I_b = 0.05$ A	V_{CEsat} max (mV)	@ I_c (A)	@ I_b (A)				
15	0.5	2 x NPN	200	0.01	2	170 ¹⁾	250	0.5	0.05				
		2 x PNP	200	0.01	2	170 ¹⁾	250	0.5	0.05				
		NPN / PNP	200	0.01	2	170 ¹⁾	250	0.5	0.05				
		NPN / PNP	200	0.01	2	170 ¹⁾	250	0.5	0.05				
20	2	NPN / NPN	230	0.5	2	60	90	0.5	0.05			PBSS4220PANS	
	2	PNP / PNP	210	0.5	2	70	110	0.5	0.05			PBSS5220PAPS	
	7.5	NPN / NPN	300	0.5	2	15	150	4	0.2				
	6.3	PNP / PNP	250	0.5	2	24	225	4	0.2				
	7.5 / 6.3	NPN / PNP	300 / 250	0.5	2	15 / 24	150 / 225	4	0.2				
30	1	NPN / NPN	210	0.5	2	75	100	0.5	0.05			PBSS4130PAN	
		PNP / PNP	170	0.5	2	85	140	0.5	0.05			PBSS5130PAP	
		NPN / PNP	210 / 170	0.5	2	75 / 85	100 / 140	0.5	0.05			PBSS4130PANP	
	2	NPN / NPN	230	0.5	2	60	80	0.5	0.05			PBSS4230PAN	
		PNP / PNP	210	0.5	2	75	110	0.5	0.05			PBSS5230PAP	
		NPN / PNP	230 / 210	0.5	2	60 / 75	80 / 100	0.5	0.05			PBSS4230PANP	
	5.7	NPN / NPN	300	0.5	2	57	250	4	0.4				
	4.8	PNP / PNP	200	0.5	2	70	390	4	0.4				
	5.7 / 4.8	NPN / PNP	300 / 200	0.5	2	57 / 70	250 / 390	4	0.4				
	40	1	NPN / PNP	300 / 250	0.5	5	130 / 150	500	1	0.1			PBSS4140DPN
2		NPN / PNP	300 / 250	0.5	5	80 / 100	400 / 530	2	0.2			PBSS4240DPN	
50	2.7	2 x NPN	300	0.5	2	50	340	2.7	0.27				
		2 x PNP	200	0.5	2	60	370	2.7	0.27				
		NPN / PNP	300 / 200	0.5	2	50 / 60	340 / 370	2.7	0.27				
60	1	2 x NPN	200	0.5	5	115	250	1	0.1			PBSS4160DS	
		2 x PNP	150	0.5	5	120	330	1	0.1			PBSS5160DS	
		NPN / PNP	200 / 150	0.5	5	115 / 120	250 / 330	1	0.1			PBSS4160DPN	
	1	NPN / NPN	150	0.5	2	90	120	0.5	0.05			PBSS4160PAN	PBSS4160PANS
		PNP / PNP	120	0.5	2	125	180	0.5	0.05			PBSS5160PAP	PBSS5160PAPS
		NPN / PNP	150 / 120	0.5	2	90 / 125	120 / 180	0.5	0.05			PBSS4160PANP	PBSS4160PANPS
	2	NPN / NPN	210	0.5	2	70	90	0.5	0.05			PBSS4260PAN	PBSS4260PANS
		PNP / PNP	140	0.5	2	100	140	0.5	0.05			PBSS5260PAP	PBSS5260PAPS
		NPN / PNP	210 / 140	0.5	2	70 / 100	90 / 140	0.5	0.05			PBSS4260PANP	PBSS4260PANPS
	6.7	NPN / NPN	300	0.5	2	20	190	4	0.2				
	5.9	PNP / PNP	200	0.5	2	35	330	4	0.2				
	6.7 / 5.9	NPN / PNP	300 / 200	0.5	2	20 / 35	190 / 330	4	0.2				
	120	1	NPN / NPN	240	0.1	2	90	120	0.5	0.05			PBSS4112PAN
PNP / PNP			190	0.1	2	150	220	0.5	0.05			PBSS5112PAP	
NPN / PNP			240 / 190	0.1	2	90 / 150	120 / 220	0.5	0.05			PBSS4112PANP	

¹⁾ $I_c / I_b = 20$ ²⁾ Device mounted on a ceramic PCB, Al₂O₃, standard footprint ³⁾ Optimized for high-speed switching

Low V_{CEsat} (BISS) transistors load switches

Package				SOT457 (SC-74)	SOT363 (SC-88)	
						
Size (mm)				2.9 x 1.5 x 1.0		
P _{tot} (mW)				750 ¹⁾	600 ¹⁾	
V _{CEO} (V)	I _C (A)	V _{CEsat} max (mV); I _C = 0.5 A; I _B = 0.05 A	R1, R2 (kΩ)			
15	0.5	250	2.2		PBLS1501Y	
			4.7		PBLS1502Y	
			10		PBLS1503Y	
			22		PBLS1504Y	
20	1	150	2.2		PBLS2001D	
			4.7		PBLS2002D	
			10		PBLS2003D	
			22		PBLS2004D	
	1.8	70	2.2	PBLS2021D		
			4.7	PBLS2022D		
			10	PBLS2023D		
			22	PBLS2024D		
40	0.5	350	2.2		PBLS4001Y	
			4.7		PBLS4002Y	
			10		PBLS4003Y	
			22		PBLS4004Y	
			47		PBLS4005Y	
	1	170	2.2		PBLS4001D	
			4.7		PBLS4002D	
			10		PBLS4003D	
			22		PBLS4004D	
			47		PBLS4005D	
60	1	180	2.2		PBLS6001D	
			4.7		PBLS6002D	
			10		PBLS6003D	
			22		PBLS6004D	
			47		PBLS6005D	
	1.5	100	2.2	PBLS6021D		
			4.7	PBLS6022D		
			10	PBLS6023D		
			22	PBLS6024D		

¹⁾ Device mounted on a ceramic PCB, Al₂O₃, standard footprint

²⁾ Device mounted on an FR4 PCB, single-sided copper, tin-plated, and standard footprint

Low V_{CEsat} (BISS) high voltage transistors

Types in **bold** represent new products

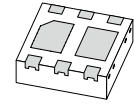
Package				SOT223 (SC-73)	SOT89 (SC-62)	SOT1215	SOT23
Size (mm)				6.5 x 3.5 x 1.65	4.5 x 2.5 x 1.5	1.1 x 1.0 x 0.37	2.9 x 1.3 x 1.0
P _{tot} (mW)				1700	1300	750	250
Polarity	V _{CEO} [max] (V)	I _c (A)	hFE [min]				
NPN	150	0.5	100			PBHV8515QA	
			70				PBHV8115TLH
		1	100			PBHV8115X	PBHV8115T
				PBHV8115Z			
	180	1	100	PBHV8215Z			
	400	0.5	100	PBHV8540Z	PBHV8540X		PBHV8540T
				PBHV8140Z			
	500	0.15	50				PMBTA45
	600	0.5	70	PBHV8560Z			
PNP	140	4	100	PBHV9414Z			
	150	0.5	100			PBHV9515QA	
							PBHV9115TLH
		1	100			PBHV9115X	PBHV9115T
				PBHV9115Z			
	400	0.25	100	PBHV9215Z			PBHV9040T
						PBHV9040X	
	500	0.5	100	PBHV9040Z	PBHV9540X		
				PBHV9540Z			
	600	0.15	100				PBHV9050T
				PBHV9050Z			
				PBHV3160Z			
600	0.5	70	PBHV9560Z				

Low V_{CEsat} (BISS) RETs

Package					SOT23	
Size (mm)					2.9 x 1.3 x 1.0	
P _{tot} (mW)					250	
V _{CEO} (V)	I _c (mA)		R1 (kΩ)	R2 (kΩ)	NPN	PNP
40	600	R1 = R2	1	1	PBRN113ET	PBRP113ET
			2.2	2.2	PBRN123ET	PBRP123ET
		R1 ≠ R2	1	10	PBRN113ZT	PBRP113ZT
			2.2	10	PBRN123YT	PBRP123YT

Low V_{CEsat} (BISS) transistors PNP - N-channel MOSFET combination

Package											DFN2020-6 (SOT1118)
Size (mm)											2.0 x 2.0 x 0.62
P_{tot} (mW)											1300
V_{CE0} (V)	I_C (A)	h_{FE} min	h_{FE} max	@ I_C (mA)	@ V_{CE} (V)	R_{CEsat} typ (m Ω)	V_{DS} (V)	V_{GS} (V)	I_D (A)	R_{Dson} typ (m Ω)	
40	2	300	800	100	5	240	30	0.7	0.66	390	PBSM5240PF
		100	-	100	5	240	30	0.7	0.66	390	PBSM5240PFH



Low V_{CEsat} (BISS) power transistors single

Package						LFAK56 (SOT669)
Size (mm)						5 x 6 x 1.1
P_{tot} (mW)						1250
V_{CE0} (V)	I_C (A)	h_{FE} min/typ	@ I_C (A)	@ V_{CE} (V)	Polarity	
40	6	200 / 400	0.5	2	NPN	PHPT60406NY
			0.5	2	PNP	PHPT60406PY
	10	200 / 400	0.5	2	NPN	PHPT60410NY
			0.5	2	PNP	PHPT60410PY
	15	200 / 400	0.5	2	NPN	PHPT60415NY
			0.5	2	PNP	PHPT60415PY
60	3	200 / 400	0.5	2	NPN	PHPT60603NY
			0.5	2	PNP	PHPT60603PY
	6	200 / 400	0.5	2	NPN	PHPT60606NY
			0.5	2	PNP	PHPT60606PY
	10	200 / 400	0.5	2	NPN	PHPT60610NY
			0.5	2	PNP	PHPT60610PY
100	3	150 / 250	0.5	10	NPN	PHPT61003NY
			0.5	10	PNP	PHPT61003PY
	6	150 / 250	0.5	10	NPN	PHPT61006NY
			0.5	10	PNP	PHPT61006PY
	10	150 / 250	0.5	10	NPN	PHPT61010NY
			0.5	10	PNP	PHPT61010PY





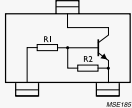
Low V_{CEsat} (BISS) power transistors double

Package											LFAK56D (SOT1205)	
Size (mm)											5 x 6 x 1.1	
P_{tot} (mW)											1250	
V_{CE0} (V)	I_C (A)	I_{CM} (A)	h_{FE} typ	@ I_C (A)	@ V_{CE} (V)	V_{CEsat} typ (mV); $I_C = 0.5$ A; $I_B = 0.05$ A	V_{CEsat} max (mV)	@ I_C (A)	@ I_B (A)	Polarity	h_{FE1}/h_{FE2}	
100	3	6	150	0.5	10	50	300	3	0.2	2XNPN	-	PHPT610030NK
						70	400	3	0.2	2XPNP	-	PHPT610030PK
						50 / 70	300 / 400	3	0.2	NPN/PNP	-	PHPT610030NPK
						50	300	3	0.2	2XNPN	0.95	PHPT610035NK
						70	400	3	0.2	2XPNP	0.9	PHPT610035PK



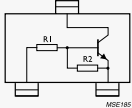


Resistor equipped transistors (RETs)

RETs 100 mA single - part 1




Package					SOT23		SOT323 (SC-70)	
								
Size (mm)					2.9 x 1.3 x 1.0		2.0 x 1.25 x 0.95	
P _{tot} (mW)					250		200	
V _{CE0} (V)	I _c (mA)	Configuration	R1 (kΩ)	R2 (kΩ)	NPN	PNP	NPN	PNP
50	100		1	1		PDTA113ET		PDTA113EU
			2.2	2.2	PDTC123ET	PDTA123ET	PDTC123EU	PDTA123EU
			4.7	4.7	PDTC143ET	PDTA143ET	PDTC143EU	PDTA143EU
			10	10	PDTC114ET	PDTA114ET	PDTC114EU	PDTA114EU
			22	22	PDTC124ET	PDTA124ET	PDTC124EU	PDTA124EU
			47	47	PDTC144ET	PDTA144ET	PDTC144EU	PDTA144EU
			100	100	PDTC115ET	PDTA115ET	PDTC115EU	PDTA115EU
			1	10		PDTA113ZT		PDTA113ZU
			2.2	10	PDTC123YT	PDTA123YT	PDTC123YU	PDTA123YU
			2.2	47	PDTC123JT	PDTA123JT	PDTC123JU	PDTA123JU
			4.7	10	PDTC143XT	PDTA143XT	PDTC143XU	PDTA143XU
			4.7	47	PDTC143ZT	PDTA143ZT	PDTC143ZU	PDTA143ZU
			10	47	PDTC114YT	PDTA114YT	PDTC114YU	PDTA114YU
			22	47	PDTC124XT	PDTA124XT	PDTC124XU	PDTA124XU
		47	10	PDTC144VT	PDTA144VT	PDTC144VU	PDTA144VU	
		47	22	PDTC144WT	PDTA144WT	PDTC144WU	PDTA144WU	
		2.2	-	PDTC123TT	PDTA123TT	PDTC123TU	PDTA123TU	
		4.7	-	PDTC143TT	PDTA143TT	PDTC143TU	PDTA143TU	
		10	-	PDTC114TT	PDTA114TT	PDTC114TU	PDTA114TU	
		22	-	PDTC124TT	PDTA124TT	PDTC124TU	PDTA124TU	
		47	-	PDTC144TT	PDTA144TT	PDTC144TU	PDTA144TU	
		100	-	PDTC115TT	PDTA115TT	PDTC115TU	PDTA115TU	

RETs 100 mA single - part 2





Package					DFN1006-3 (SOT883)		DFN1006B-3 (SOT883B)		SOT1215				
													
Size (mm)					1.0 x 0.6 x 0.48		1.0 x 0.6 x 0.37		1.1 x 1.0 x 0.37				
P _{tot} (mW)					250		250		750				
V _{CE0} (V)	I _c (mA)	Configuration	R1 (kΩ)	R2 (kΩ)	NPN	PNP	NPN	PNP	NPN	PNP			
50	100		1	1			PDTA113EM			PDTA113EMB			
			2.2	2.2	PDTC123EM		PDTA123EM		PDTC123EMB		PDTA123EMB		
			4.7	4.7	PDTC143EM		PDTA143EM		PDTC143EMB		PDTA143EMB	PDTC143EQA	PDTA143EQA
			10	10	PDTC114EM		PDTA114EM		PDTC114EMB		PDTA114EMB	PDTC114EQA	PDTA114EQA
			22	22	PDTC124EM		PDTA124EM		PDTC124EMB		PDTA124EMB	PDTC124EQA	PDTA124EQA
			47	47	PDTC144EM		PDTA144EM		PDTC144EMB		PDTA144EMB	PDTC144EQA	PDTA144EQA
			100	100	PDTC115EM		PDTA115EM		PDTC115EMB		PDTA115EMB		
			1	10			PDTA113ZM				PDTA113ZMB		
			2.2	10	PDTC123YM		PDTA123YM		PDTC123YMB		PDTA123YMB		
			2.2	47	PDTC123JM		PDTA123JM		PDTC123JMB		PDTA123JMB	PDTC123JQA	PDTA123JQA
			4.7	10	PDTC143XM		PDTA143XM		PDTC143XMB		PDTA143XMB	PDTC143XQA	PDTA143XQA
			4.7	47	PDTC143ZM		PDTA143ZM		PDTC143ZMB		PDTA143ZMB	PDTC143ZQA	PDTA143ZQA
			10	47	PDTC114YM		PDTA114YM		PDTC114YMB		PDTA114YMB	PDTC114YQA	PDTA114YQA
			22	47	PDTC124XM		PDTA124XM		PDTC124XMB		PDTA124XMB		
		47	10	PDTC144VM		PDTA144VM		PDTC144VMB		PDTA144VMB			
		47	22	PDTC144WM		PDTA144WM		PDTC144WMB		PDTA144WMB			
		2.2	-	PDTC123TM		PDTA123TM		PDTC123TMB		PDTA123TMB			
		4.7	-	PDTC143TM		PDTA143TM		PDTC143TMB		PDTA143TMB			
		10	-	PDTC114TM		PDTA114TM		PDTC114TMB		PDTA114TMB			
		22	-	PDTC124TM		PDTA124TM		PDTC124TMB		PDTA124TMB			
		47	-	PDTC144TM		PDTA144TM		PDTC144TMB		PDTA144TMB			
		100	-	PDTC115TM		PDTA115TM		PDTC115TMB		PDTA115TMB			

Resistor equipped transistors (RETs)

RETs 100 mA double






Package					DFN1010B-6 (SOT1216)			DFN1412-6 (SOT1268)			SOT363 (SC-88)					
																
Size (mm)					1.1 x 1.0 x 0.37			1.4 X 1.2 X 0.5			2.0 x 1.25 x 0.95					
P _{tot} (mW)					350			480			300					
V _{CEO} (V)	I _C (mA)	Configuration	R1 (kΩ)	R2 (kΩ)	NPN / NPN	NPN / PNP	PNP / PNP	NPN / NPN	NPN / PNP	PNP / PNP	NPN / NPN	NPN / PNP	PNP / PNP			
50	100	R1 = R2	2.2	2.2								PUMH20	PUMD20	PUMB20		
			4.7	4.7									PUMH15	PUMD15	PUMB15	
			10	10	PQMH11	PQMD3	PQMB11	PRMH11	PRMD3	PRMB11	PUMH11	PUMD3	PUMB11			
			22	22		PQMD2			PRMD2		PUMH1	PUMD2	PUMB1			
			47	47	PQMH2	PQMD12		PRMH2	PRMD12		PUMH2	PUMD12	PUMB2			
			100	100							PUMH24	PUMD24	PUMB24			
		R1 ≠ R2	2.2	47	PQMH10	PQMD10			PRMH10	PRMD10			PUMH10	PUMD10	PUMB10	
			4.7	10									PUMH18	PUMD18	PUMB18	
			4.7	47	PQMH13	PQMD13			PRMH13	PRMD13			PUMH13	PUMD13	PUMB13	
			10	47	PQMH9				PRMH9				PUMH9	PUMD9	PUMB9	
			22	47		PQMD16				PRMD16			PUMH16	PUMD16	PUMB16	
			47	22									PUMH17	PUMD17	PUMB17	
		Only R1	47 / 2.2	47 / 47										PUMD48		
			2.2	-									PUMH30	PUMD30	PUMB30	
			4.7	-									PUMH7	PUMD6	PUMB3	
			10	-									PUMH4	PUMD4	PUMB4	
			22	-									PUMH19	PUMD19	PUMB19	
		47	-									PUMH14	PUMD14	PUMB14		

RETs 500 mA single / double

Package					SOT457 (SC-74)		SOT23		SOT323 (SC-70)		SOT1215	
												
Size (mm)					2.9 x 1.5 x 1.0		2.9 x 1.3 x 1.0		2.0 x 1.25 x 0.95		1.1 x 1.0 x 0.37	
P _{tot} (mW)					750		250		200		750	
V _{CEO} (V)	I _C (mA)	Configuration	R1 (kΩ)	R2 (kΩ)	NPN / NPN	NPN / PNP	NPN	PNP	NPN	PNP	NPN	PNP
50	500	R1 = R2	1	1			PDTD113ET	PDTB113ET	PDTD113EU	PDTB113EU	PDTD113EQA	PDTB113EQA
			2.2	2.2			PDTD123ET	PDTB123ET	PDTD123EU	PDTB123EU	PDTD123EQA	PDTB123EQA
			4.7	4.7			PDTD143ET	PDTB143ET	PDTD143EU	PDTB143EU	PDTD143EQA	PDTB143EQA
			10	10			PDTD114ET	PDTB114ET	PDTD114EU	PDTB114EU	PDTD114EQA	PDTB114EQA
		R1 ≠ R2	1	10	PIMN31	PIMC31	PDTD113ZT	PDTB113ZT	PDTD113ZU	PDTB113ZU	PDTD113ZQA	PDTB113ZQA
			2.2	10			PDTD123YT	PDTB123YT	PDTD123YU	PDTB123YU	PDTD123YQA	PDTB123YQA
			4.7	10			PDTD143XT	PDTB143XT	PDTD143XU	PDTB143XU	PDTD143XQA	PDTB143XQA
		Only R1	2.2	-					PDTD123TT	PDTB123TT		

3-terminal adjustable shunt regulators

Types in **bold** new products

Type name	Pinning configuration	Tamb(C°)	Vref	Package	Size(mm)	Ptot(mW)	VKA(V)	IK(mA)					
TLVH431NCDBZR	Normal pinning	0 to 70	1.5%	SOT23 	2.9 x 1.3 x 1.0	480	20	80					
TLVH431NIDBZR	Normal pinning	-40 to 85											
TLVH431NQDBZR	Normal pinning	-40 to 125											
TLVH431NMQDBZR	Mirrored pinning												
TLVH431NACDBZR	Normal pinning	0 to 70	1%						SOT23 	2.9 x 1.3 x 1.0	580	36	100
TLVH431NAIDBZR	Normal pinning	-40 to 85											
TLVH431NAQDBZR	Normal pinning	-40 to 125											
TLVH431NAMQDBZR	Mirrored pinning												
TL431CDBZR	Normal pinning	0 to 70	2%	SOT23 	2.9 x 1.3 x 1.0	580	36	100					
TL431IDBZR	Normal pinning	-40 to 85											
TL431QDBZR	Normal pinning	-40 to 125											
TL431FDT	Normal pinning												
TL431MFD	Mirrored pinning												
TL431ACDBZR	Normal pinning	0 to 70	1%						SOT23 	2.9 x 1.3 x 1.0	580	36	100
TL431AIDBZR	Normal pinning	-40 to 85											
TL431AQDBZR	Normal pinning	-40 to 125											
TL431AFDT	Normal pinning												
TL431AMFDT	Mirrored pinning												
TL431BCDBZR	Normal pinning	0 to 70	0.5%	SOT23 	2.9 x 1.3 x 1.0	580	36	100					
TL431BIDBZR	Normal pinning	-40 to 85											
TL431BQDBZR	Normal pinning	-40 to 125											
TL431BFDT	Normal pinning												
TL431BMFDT	Mirrored pinning												



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General purpose Zener diodes

Types in **bold** represent new products

I_F max (mA)	P_{ZSM} (W)	V_Z nom (V)	V_Z tolerance	Note	Configuration		Series	Package		Size (mm)	P_{tot} (mW)
400	40	2.4~75	C	Europe	Single		BZV90 series	SOT223 (SC-73)		6.5 x 3.5 x 1.65	1500
250	40	2.4~75	C	Europe	Single		BZV49 series	SOT89 (SC-62)		4.5 x 2.5 x 1.5	1000
200	40	2.4~75	B, C	Europe	Dual c.a.		BZB84 series	SOT23		2.9 x 1.3 x 1.0	250
			A, B, C		Single		BZX84 series				
250	30	5~6.8	0.2 V	Ave	Single		PLVA600A series				
250	40	2.4~75	B, C	Europe	Single		BZT52 series	SOD123		2.7 x 1.6 x 1.2	550
200		2.4~36	B	Japan			PDZ-GW series				
250	-	3.0~30	About 2.5%	Special	Single		NZH series	SOD123F		2.6 x 1.6 x 1.1	830
	40	2.4~75	B, C	Europe			BZT52H series				
200	40	10	B2	Japan	Dual isolated		PZU10DB2 series	SOT353 (SC-88A)		2.0 x 1.25 x 0.95	300
200	40	2.4~15	C	Europe	Dual c.a.		BZB784 series	SOT323 (SC-70)		2.0 x 1.25 x 0.95	350
200	40	2.4~75	B, C	Europe	Single		BZX84W series				
200	30	100	C	Europe	Back-to-back		BZB100A	SOD323 (SC-76)		1.7 x 1.25 x 0.95	300
	40	2.4~36	B2	Japan	Single		PDZ-B series				
250	40	2.4~75	B, C	Europe			BZX384 series				
200	40	2.4~36	B, B1, B2, B3	Japan			PZUxBA series				
200	60	100	C	Europe	Single		BZX100A	SOD323F (SC-90)		1.7 x 1.25 x 0.7	550
200	40	2.4~36	B, B1, B2, B3	Japan			PZUxB series				
250	40	2.4~75	B, C	Europe			BZX84J series				
200	40	2.4~75	B, C	Europe	Single		BZX585 series	SOD523 (SC-79)		1.2 x 0.8 x 0.6	300
200	40	2.4~75	B, C	Europe	Single		BZX884 series	DFN1006-2 (SOD882)		1.0 x 0.6 x 0.48	250
		2.4~36	B, B2	Japan			PZUxBL series				
250	40	2.4~30	B	Europe	Single		TDZxJ series	SOD323F		1.7 x 1.25 x 0.7	500

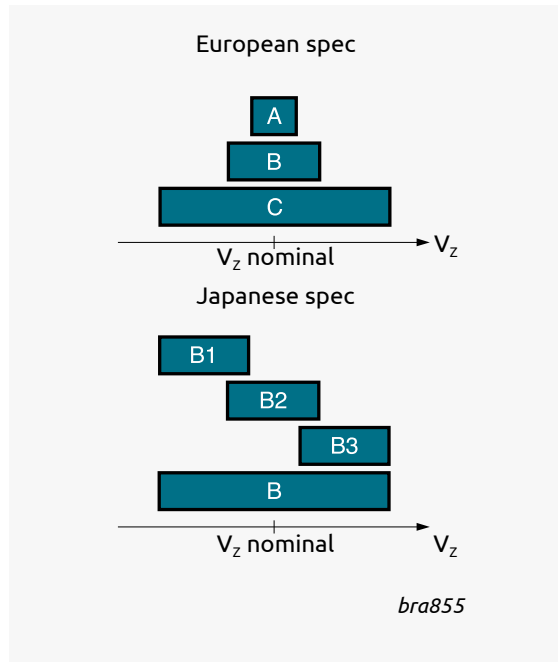
Notes:

Japan: B selection: app. 5% V_Z tolerance, B1, B2, B3 selections: app. 2% V_Z tolerance in sequential intervals
 Europe: A selection: app. 1% V_Z tolerance, B selection: app. 2% V_Z tolerance, C selection: app. 5% V_Z tolerance;
 the selections are in overlapping intervals

Ave: low-voltage avalanche regulator diodes
 Dual c.a.: dual common anode

Zener diodes specifications

Differences in Zener specifications



Japanese spec (PZU, PDZ)

y =	B-series	B1-series	B2-series	B3-series
	± 5%	± 2%	± 2%	± 2%
	V_z (V)	V_z (V)	V_z (V)	V_z (V)
PZU2.4y	2.3 - 2.6	-	-	-
PZU2.7y	2.5 - 2.9	2.5 - 2.75	2.65 - 2.9	-
PZU3.0y	2.8 - 3.2	2.8 - 3.05	2.95 - 3.2	-
PZU3.3y	3.1 - 3.5	3.1 - 3.35	3.25 - 3.5	-
PZU3.6y	3.4 - 3.8	3.4 - 3.65	3.55 - 3.8	-
PZU3.9y	3.7 - 4.1	3.7 - 3.97	3.87 - 4.1	-
PZU4.3y	4.01 - 4.48	4.01 - 4.21	4.15 - 4.34	4.28 - 4.48
PZU4.7y	4.42 - 4.9	4.42 - 4.61	4.55 - 4.75	4.69 - 4.9
PZU5.1y	4.84 - 5.37	4.84 - 5.04	4.98 - 5.2	5.14 - 5.37
PZU5.6y	5.31 - 5.92	5.31 - 5.55	5.49 - 5.73	5.67 - 5.92
PZU6.2y	5.86 - 6.53	5.86 - 6.12	6.06 - 6.33	6.26 - 6.53
PZU6.8y	6.47 - 7.14	6.47 - 6.73	6.65 - 6.93	6.86 - 7.14
PZU7.5y	7.06 - 7.84	7.06 - 7.36	7.28 - 7.6	7.52 - 7.84
PZU8.2y	7.76 - 8.64	7.76 - 8.1	8.02 - 8.36	8.28 - 8.64
PZU9.1y	8.56 - 9.55	8.56 - 8.93	8.85 - 9.23	9.15 - 9.55
PZU10y	9.45 - 10.55	9.45 - 9.87	9.77 - 10.21	10.11 - 10.55
PZU11y	10.44 - 11.56	10.44 - 10.88	10.76 - 11.22	11.1 - 11.56
PZU12y	11.42 - 12.6	11.42 - 11.9	11.74 - 12.24	12.08 - 12.6
PZU13y	12.47 - 13.96	12.47 - 13.03	12.91 - 13.49	13.37 - 13.96
PZU14y	-	-	13.7 - 14.3	-
PZU15y	13.84 - 15.52	13.84 - 14.46	14.34 - 14.98	14.85 - 15.52
PZU16y	15.37 - 17.09	15.37 - 16.01	15.85 - 16.51	16.35 - 17.09
PZU18y	16.94 - 19.03	16.94 - 17.7	17.56 - 18.35	18.21 - 19.03
PZU20y	18.86 - 21.08	18.86 - 19.7	19.52 - 20.39	20.21 - 21.08
PZU22y	20.88 - 23.17	20.88 - 21.77	21.54 - 22.47	22.23 - 23.17
PZU24y	22.93 - 25.57	22.93 - 23.96	23.72 - 24.78	24.54 - 25.57
PZU27y	25.1 - 28.9	-	-	-
PZU30y	28 - 32	-	-	-
PZU33y	31 - 35	-	-	-
PZU36y	34 - 38	-	-	-

Diodes

European spec (BZV, BZX, BZB, 1N47)


















y =	C-series	B-series	A-series
	±5%	±2%	±1%
	V_z (V)	V_z (V)	V_z (V)
BZX84-y2V4	2.2 - 2.6	2.35 - 2.45	2.37 - 2.43
BZX84-y2V7	2.5 - 2.9	2.65 - 2.75	2.67 - 2.73
BZX84-y3V0	2.8 - 3.2	2.94 - 3.06	2.97 - 3.03
BZX84-y3V3	3.1 - 3.5	3.23 - 3.37	3.26 - 3.34
BZX84-y3V6	3.4 - 3.8	3.53 - 3.67	3.56 - 3.64
BZX84-y3V9	3.7 - 4.1	3.82 - 3.98	3.86 - 3.94
BZX84-y4V3	4 - 4.6	4.21 - 4.39	4.25 - 4.35
BZX84-y4V7	4.4 - 5	4.61 - 4.79	4.65 - 4.75
BZX84-y5V1	4.8 - 5.4	5 - 5.2	5.04 - 5.16
BZX84-y5V6	5.2 - 6	5.49 - 5.71	5.54 - 5.66
BZX84-y6V2	5.8 - 6.6	6.08 - 6.32	6.13 - 6.27
BZX84-y6V8	6.4 - 7.2	6.66 - 6.94	6.73 - 6.87
BZX84-y7V5	7 - 7.9	7.35 - 7.65	7.42 - 7.58
BZX84-y8V2	7.7 - 8.7	8.04 - 8.36	8.11 - 8.29
BZX84-y9V1	8.5 - 9.6	8.92 - 9.28	9 - 9.2
BZX84-y10	9.4 - 10.6	9.8 - 10.2	9.9 - 10.1
BZX84-y11	10.4 - 11.6	10.8 - 11.2	10.8 - 11.11
BZX84-y12	11.4 - 12.7	11.8 - 12.2	11.88 - 12.12
BZX84-y13	12.4 - 14.1	12.7 - 13.3	12.87 - 13.13
BZX84-y15	13.8 - 15.6	14.7 - 15.3	14.85 - 15.15
BZX84-y16	15.3 - 17.1	15.7 - 16.3	15.84 - 16.16
BZX84-y18	16.8 - 19.1	17.6 - 18.4	17.82 - 18.18
BZX84-y20	18.8 - 21.2	19.6 - 20.4	19.8 - 20.2
BZX84-y22	20.8 - 23.3	21.6 - 22.4	21.78 - 22.22
BZX84-y24	22.8 - 25.6	23.5 - 24.5	23.76 - 24.24
BZX84-y27	25.1 - 28.9	26.5 - 27.5	26.73 - 27.27
BZX84-y30	28 - 32	29.4 - 30.6	29.70 - 30.30
BZX84-y33	31 - 35	32.3 - 33.7	32.67 - 33.33
BZX84-y36	34 - 38	35.3 - 36.7	35.64 - 36.36
BZX84-y39	37 - 41	38.2 - 39.8	38.61 - 39.39
BZX84-y43	40 - 46	42.1 - 43.9	42.57 - 43.43
BZX84-y47	44 - 50	46.1 - 47.9	-
BZX84-y51	48 - 54	50 - 52	50.49 - 51.51
BZX84-y56	52 - 60	54.9 - 57.1	-
BZX84-y62	58 - 66	60.8 - 63.2	-
BZX84-y68	64 - 72	66.6 - 69.4	-
BZX84-y75	70 - 79	73.5 - 76.5	74.25 - 75.75

NZX-series in SOD27





















	V_z (V)		V_z (V)		V_z (V)
NZX2V1B	2.0 - 2.2	NZX6V2D	6.1 - 6.4	NZX14C	13.8 - 14.3
NZX2V4A	2.3 - 2.5	NZX6V2E	6.3 - 6.6	NZX15A	14.1 - 14.7
NZX2V4B	2.4 - 2.6	NZX6V8A	6.4 - 6.7	NZX15B	14.5 - 15.1
NZX2V7A	2.5 - 2.7	NZX6V8B	6.6 - 6.9	NZX15C	14.9 - 15.5
NZX2V7B	2.6 - 2.8	NZX6V8C	6.7 - 7	NZX15X	14.35 - 15.09
NZX2V7C	2.7 - 2.9	NZX6V8D	6.9 - 7.2	NZX16A	15.3 - 15.9
NZX3V0A	2.8 - 3	NZX7V5A	7 - 7.3	NZX16B	15.7 - 16.5
NZX3V0B	2.9 - 3.1	NZX7V5B	7.2 - 7.6	NZX16C	16.3 - 17.1
NZX3V0C	3 - 3.2	NZX7V5C	7.3 - 7.7	NZX18A	16.9 - 17.7
NZX3V3A	3.1 - 3.3	NZX7V5D	7.5 - 7.9	NZX18B	17.5 - 18.3
NZX3V3B	3.2 - 3.4	NZX7V5X	7.07 - 7.45	NZX18C	18.1 - 19
NZX3V3C	3.3 - 3.5	NZX8V2A	7.7 - 8.1	NZX20A	18.8 - 19.7
NZX3V6A	3.4 - 3.6	NZX8V2B	7.9 - 8.3	NZX20B	19.5 - 20.4
NZX3V6B	3.5 - 3.7	NZX8V2C	8.1 - 8.5	NZX20C	20.2 - 21.2
NZX3V6C	3.6 - 3.8	NZX8V2D	8.3 - 8.7	NZX22A	20.9 - 21.9
NZX3V9A	3.7 - 3.9	NZX9V1A	8.5 - 8.9	NZX22B	21.6 - 22.6
NZX3V9B	3.8 - 4	NZX9V1B	8.7 - 9.1	NZX22C	22.3 - 23.3
NZX3V9C	3.9 - 4.1	NZX9V1C	8.9 - 9.3	NZX24A	22.9 - 24
NZX4V3A	4 - 4.2	NZX9V1D	9.1 - 9.5	NZX24B	23.6 - 24.7
NZX4V3B	4.1 - 4.3	NZX9V1E	9.3 - 9.7	NZX24C	24.3 - 25.5
NZX4V3C	4.2 - 4.4	NZX10A	9.5 - 9.9	NZX24X	22.61 - 23.77
NZX4V3D	4.3 - 4.5	NZX10B	9.7 - 10.1	NZX27A	25.2 - 26.6
NZX4V7A	4.4 - 4.6	NZX10C	9.9 - 10.3	NZX27B	26.2 - 27.6
NZX4V7B	4.5 - 4.7	NZX10D	10.2 - 10.6	NZX27C	27.2 - 28.6
NZX4V7C	4.6 - 4.8	NZX11A	10.4 - 10.8	NZX27X	26.99 - 28.39
NZX4V7D	4.7 - 4.9	NZX11B	10.7 - 11.1	NZX30A	28.2 - 29.6
NZX5V1A	4.8 - 5	NZX11C	10.9 - 11.3	NZX30B	29.2 - 30.6
NZX5V1B	4.9 - 5.1	NZX11D	11.1 - 11.6	NZX30C	30.2 - 31.6
NZX5V1C	5 - 5.2	NZX12A	11.4 - 11.9	NZX30X	29.02 - 30.51
NZX5V1D	5.1 - 5.3	NZX12B	11.6 - 12.1	NZX33A	31.2 - 32.6
NZX5V6A	5.2 - 5.5	NZX12C	11.9 - 12.4	NZX33B	32.2 - 33.6
NZX5V6B	5.3 - 5.6	NZX12D	12.2 - 12.7	NZX33C	33.2 - 34.5
NZX5V6C	5.4 - 5.7	NZX12X	11.44 - 12.03	NZX36A	34.2 - 35.7
NZX5V6D	5.5 - 5.8	NZX13A	12.4 - 12.9	NZX36B	35.3 - 36.8
NZX5V6E	5.6 - 5.9	NZX13B	12.6 - 13.1	NZX36C	36.4 - 38
NZX6V2A	5.7 - 6	NZX13C	12.9 - 13.4	NZX36X	35.36 - 37.19
NZX6V2B	5.8 - 6.1	NZX14A	13.2 - 13.7		
NZX6V2C	6 - 6.3	NZX14B	13.5 - 14		

Switching diodes

General purpose, high speed switching diodes <= 90V



V_R max (V)	V_F max (V)	I_F (mA)	I_R max (mA)	t_{tr} max (ns)	Package	SOT23	SOT143B	SOT323 (SC-70)	SOT363 (SC-88)	DFN1412-6 (SOT1268)	DFN1010D-3 (SOT1215)	DFN1006-3 (SOT883)	
													
						Size (mm)	2.9 x 1.3 x 1.0	2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.4 x 1.2 x 0.5	1.1 x 1.0 x 0.37	1.0 x 0.6 x 0.48
						P_{tot} (mW)	250	250	200	350	480	325	250
50	1	50	100	50	4		BAL74						
							BAV74						
70	1	50	1000	70	4		BAL99						
75	1	50	1000	75	4			BAS28					
80	1	50	500	80	4				1PS300				
									1PS301				
									1PS302				
90	1	50	500	80	4		BAW56		BAW56W		BAW56QA	BAW56M	
									BAW56S	BAW56SRA			
									BAV756S				

General purpose, high speed switching diodes 100V

V_R max (V)	V_F max (V)	I_F (mA)	I_R max (mA)	t_{tr} max (ns)	Package	SOT23	SOD123	SOD123F	SOT323 (SC-70)	SOT363 (SC-88)	SOD323 (SC-76)	SOD323F (SC-90)	DFN1412-6 (SOT1268)	SOD523 (SC-79)	DFN1010D-3 (SOT1215)	DFN1006-2 (SOD882)	DFN1006-3 (SOT883)	DFN1006D-2 (SOD882D)	
																			
						Size (mm)	2.9 x 1.3 x 1.0	2.7 x 1.6 x 1.2	2.6 x 1.6 x 1.1	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.7 x 1.25 x 0.95	1.7 x 1.25 x 0.7	1.4 x 1.2 x 0.5	1.2 x 0.8 x 0.6	1.1 x 1.0 x 0.37	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37
						P_{tot} (mW)	250	380	375	200	300	300	300	480	250	325	250	250	250
100	1	50	500	80	4		BAS16GW	BAS16H			BAS316	BAS16J		BAS516		BAS16L		BAS16LD	
							BAS16		BAS16W					BAS16QA					
									BAS16VY										
							BAV70		BAV70W					BAV70QA		BAV70M			
									BAV70S			BAV70SRA							
							BAV99		BAV99W					BAV99QA					
									BAV99S										






























High performance switching diodes (175°C capable & superior power dissipation)

Types in **bold** represent new products

V _R max (V)	V _F max (V)	I _F (mA)	I _R max (nA)	t _{rr} max (ns)	Package		
					SOT23		
							
					Size (mm)	2.9 X 1.3 X 1.0	
					P _{tot} (mW)	300	
100	1	50	500	80	4		BAS16TH
200	1	100	100	200	50		BAS21TH







General purpose, switching diodes >= 100V

Types in **bold** represent new products
















V _R max (V)	V _F max (V)	I _F (mA)	I _R max (nA)	t _{rr} max (ns)	Package													
					SOT457 (SC-74)	SOT23	SOT143B	SOD123	SOD123F	SOT323 (SC-70)	SOT353 (SC-88A)	SOT363 (SC-88)	SOD323 (SC-76)	SOD323F (SC-90)	SOD523 (SC-79)	DFN1006D-2 (SOD882(D))	DFN1010D-3 (SOT1215)	
																		
					Size (mm)	2.9 x 1.5 x 1.0	2.9 x 1.3 x 1.0	2.9 x 1.3 x 1.0	2.7 x 1.6 x 1.2	2.6 x 1.6 x 1.1	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.7 x 1.25 x 0.95	1.7 x 1.25 x 0.7	1.2 x 0.8 x 0.6	1.0 x 0.6 x 0.48 (1.0 x 0.6 x 0.37)	1.1 x 1.0 x 0.37
					P _{tot} (mW)	250	250	250	380	375	200	255	300	300	300	250	250	325
100	1	100	100	100	50		BAS19											
150	1	100	100	150	50		BAS20											
≥ 200	1	100	100	200	50				BAS21GW	BAS21H			BAS321	BAS321J	BAS521B	BAS21LL (LD)	BAV21QA	
							BAS21			BAS21W								
								BAV23										
										BAS21PG								
							BAV23A			BAS21AW								
							BAV23C								BAV23QA			
							BAV23S			BAS21SW								
							BAS21AVD											
							BAS21VD											
						300	1.1	100	150	250	50							
	BAS101																	
	BAS101S																	
		BAW101																
												BAS101S						

Switching diodes

Controlled avalanche switching diodes

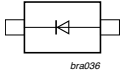


V_R max (V)	V_F max (V)	@ I_F (mA)	I_R max (nA) @ V_R max	I_{FBM} max (A)	I_{FRM} max (mA)	C_j max (pF)	t_{rr} max (ns)	Package	SOT23	SOT143B
										
								Size (mm)	2.9 x 1.3 x 1.0	2.9 x 1.3 x 1.0
P_{tot} (mW)	250	250								
60	1	200	100	9	600	2.5	6			BAS56
90	1	200	100	10	600	35	50		BAS29	
									BAS31	
									BAS35	

Low leakage current switching diodes

V_R max (V)	V_F max (V)	@ I_F (mA)	I_R max (nA) @ V_R max	t_{rr} max (μ s)	Package	SOT23	SOD123	SOD123F	SOT323 (SC-70)	SOD323 (SC-76)	SOD523 (SC-79)	DFN1010D-3 (SOT1215)	DFN1006-3 (SOT883)	DFN1006-2 (SOD882)
														
					Size (mm)	2.9 x 1.3 x 1.0	2.7 x 1.6 x 1.2	2.6 x 1.6 x 1.1	2.0 x 1.25 x 0.95	1.7 x 1.25 x 0.95	1.2 x 0.8 x 0.6	1.1 x 1.0 x 0.37	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.48
P_{tot} (mW)	250	380	375	250	250	250	305	250	250					
75	1	10	5	3			BAS116GW	BAS116H		BAS416	BAS716			BAS116L
						BAS116					BAS116QA			
						BAV199		BAV199W						
						BAW156								
						BAV170					BAV170QA	BAV170M		
125	1	100	1	1.5 typ										

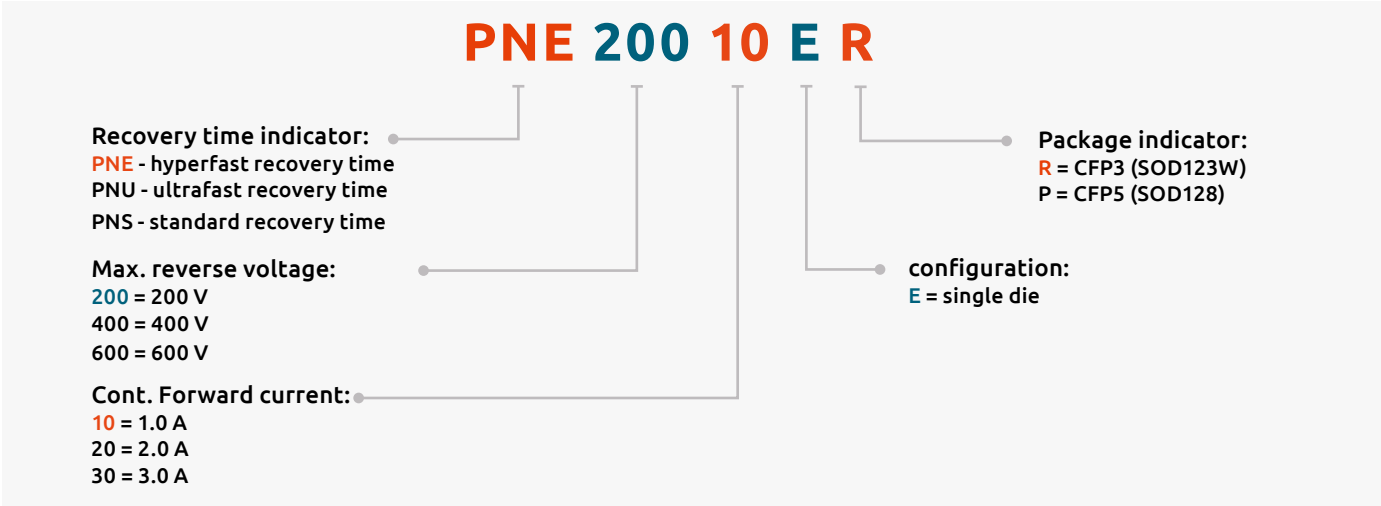
Recovery rectifiers - Automotive qualified

Types in **bold** represent new products




V _r max (V)	V _f max (V)	I _F (A)	I _r max (µA)	V _r (V)	t _{rr} max (ns)	Package  <small>bra036</small>	CFP5 (SOD128)	CFP3 (SOD123W)
								
							Size (mm)	
							P _{tot} (mW) @ 1cm ²	
200	0.93	1	0.2	200	25		PNE20010ER	
	0.98	2	0.2	200	25		PNE20020ER	
	0.95	2	0.2	200	25	PNE20020EP		
	0.98	3	0.2	200	30	PNE20030EP		
400	1.1	1	1	400	1800		PNS40010ER	

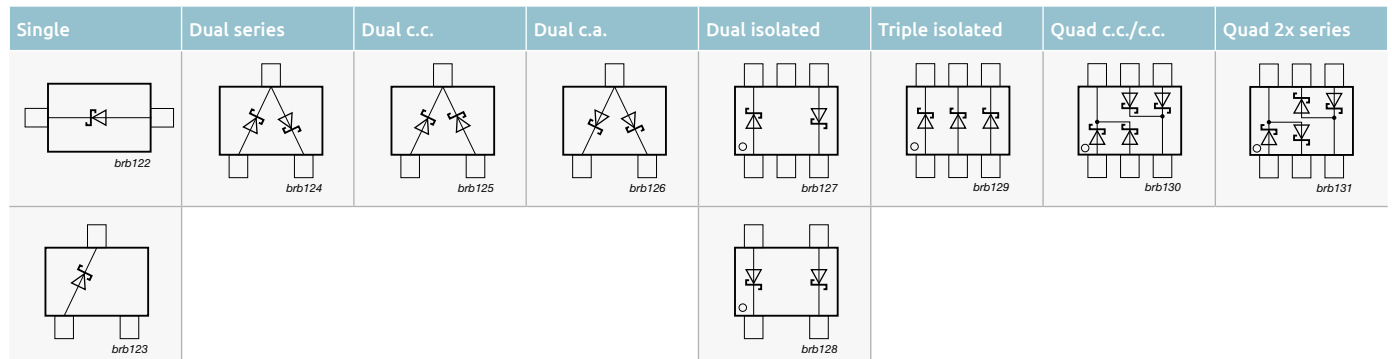
Diodes








Nomenclature recovery rectifiers automotive grade types









General purpose Schottky diodes <= 250 mA

IF max (mA)	VR max (V)	VF max (mV)	@ IF (mA)	IR max (µA)	@ VR (V)	Package	SOT23	SOT143B	SOD123	
										
							Size (mm)	2.9 x 1.3 x 1.0	2.9 x 1.3 x 1.0	2.7 x 1.6 x 1.2
							P _{tot} (mW)	250	250	357
70	70	750	10	0.1	50	Single	BAS70			
						Dual series	BAS70-04			
						Dual c.c.	BAS70-05			
						Dual c.a.	BAS70-06			
						Dual isolated		BAS70-07		
						Triple isolated				
120	40	370	1	0.5	30	Single				
						Single	BAS40			
						Dual series	BAS40-04			
						Dual c.c.	BAS40-05			
						Dual c.a.	BAS40-06			
						Dual isolated		BAS40-07		
200	30	300	10	30	10	Single				
						Single	BAT754			
						Dual series	BAT754S			
						Dual c.c.	BAT754C			
						Dual c.a.	BAT754A			
						Triple isolated				
	40	400	10	2	25	25	Single	BAT54		BAT54GW
							Dual series	BAT54S		
							Dual c.c.	BAT54C		
							Dual c.a.	BAT54A		
							Dual isolated		BAT74	
							Triple isolated			
	50	100	450	10	5	40	Single			
							Single			
							Single	BAT721		
							Dual series	BAT721S		
							Dual c.c.	BAT721C		
							Dual c.a.	BAT721A		
250	100	850	250	4	75	Single			BAT46GW	
						Single				
						Single				
						Single				
						Dual series				
						Dual c.c.				





SOD123F	SOT323 (SC-70)	SOT363 (SC-88)	SOD323F (SC-90)	SOD323 (SC-76)	SOD523 (SC-79)	DFN1006-2 (SOD882)/ DFN1006-3 (SOT883)
						
2.6 x 1.6 x 1.1	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.7 x 1.25 x 0.7	1.7 x 1.25 x 0.95	1.2 x 0.8 x 0.6	1.0 x 0.6 x 0.48
375	250	300	385	400	275	250
BAS70H	BAS70W BAS70-04W BAS70-05W BAS70-06W	BAS70-07S BAS70XY		1PS76SB70	1PS79SB70	BAS70L
BAS40H	BAS40W BAS40-04W BAS40-05W BAS40-06W			RB751V40 1PS76SB40	RB751S40 1PS79SB40	RB751CS40 BAS40L
		1PS88SB48 BAS40XY			1PS79SB31	
BAT54H	BAT54W BAT54SW BAT54CW BAT54AW	BAT754L BAT74S BAT54XY	BAT54J	1PS76SB10	1PS79SB10	BAT54L BAT54CM
					RB521S30 RB520S30	RB521CS30L RB520CS30L
				1PS76SB21		
					1PS79SB30	
	BAT854W BAT854SW BAT854CW BAT854AW					
BAT46WH			BAT46WJ			

Low capacitance Schottky diodes





I _F max (mA)	V _r max (V)	V _F max (mV) @ I _F (mA)	C _j max (pF) @ V _r = 0 V	Package	SOT23	SOT323 (SC-70)	SOT363 (SC-88)	SOD323 (SC-76)	SOD523 (SC-79)	DFN1006-2 (SOD882)	
											
30	4	450	1	Size (mm)	2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.7 x 1.25 x 0.95	1.2 x 0.8 x 0.6	1.0 x 0.6 x 0.48	
				P _{tot} (mW)	250	250	300	400	500	250	
				Single	BAT17			1PS76SB17	1PS79SB17		
				Triple isolated							
	15	340	1	1	Dual series	PMBD353 PMBD354 ¹⁾					
					Single		1PS70SB82				1PS10SB82
					Triple isolated			1PS88SB82			
					Dual series		1PS70SB84				
				Dual c.c.	1PS70SB85						
				Dual c.a.	1PS70SB86						

¹⁾Diodes have matched capacitance

Medium power low VF Schottky rectifiers single ≥ 200 mA - leadless DFN packages




I_F max (A)	V_R max (V)	V_F max (mV) @ I_F max	I_R max (mA) @ V_R max	Package	DFN2020-3 (SOT1061)	DFN2020D-3 (SOT1061D)	
							
					2.0 x 2.0 x 0.62	2.0 x 2.0 x 0.62	
					960	960	
					Optimization		
0.1	30	840	0.0008	Low I_R			
0.2	20	420	0.045	Low V_F			
		490	0.0035	Low I_R			
	30	470	0.08	Low V_F			
		480	0.05	low V_F			
		520	0.015	Low I_R			
		535	0.009	Low I_R			
	40	525	0.08	Low V_F			
		600	0.0065	Low I_R			
		600	0.01	low I_R			
		60	600	0.1	low V_F		
0.5	20	390	0.2	low V_F			
		410	0.3	low V_F			
		440	1.5	low V_F			
		500	0.03	low I_R			
		550	0.045	Low V_F			
		620	0.0035	Low I_R			
	30	500	0.5	low V_F			
		630	0.08	Low V_F			
		670	0.015	Low I_R			
		720	0.009	Low I_R			
	40	590	0.01	low I_R			
		820	0.08	Low V_F			
		880	0.0065	Low I_R			
		1	20	375	1.9	low V_F	PMEG2010EPA
415	0.6			low V_F			
490	0.2			low V_F			
30	480		1.25	Low V_F			
	565		0.045	Low I_R			
40	505		0.115	Low V_F			
	600		0.02	low I_R			
	610		0.04	Low I_R			
60	625	0.65	Low V_F				
	730	0.03	Low I_R				
1.5	20	420	0.9	low V_F			
	40	610	0.03	low I_R			
2	20	420	1.9	low V_F	PMEG2020EPA	PMEG2020EPAS	
		450	0.9	low V_F			
	30	470	2.5	low V_F	PMEG3020EPA	PMEG3020EPAS	
	40	535	0.1	low V_F	PMEG4020EPA	PMEG4020EPAS	
	60	530	0.2	low V_F			
		575	0.25	low V_F	PMEG6020EPA	PMEG6020EPAS	

Types in **bold** represent new products

DFN1608D-2 (SOD1608)	DFN1006-2 (SOD882)	DFN1006D-2 (SOD882D)	DFN0603-2 (SOD972E)
			
1.6 x 0.8 x 0.37	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37	0.63 x 0.33 x 0.25
780	565	660	570
			PMEG3001EEF
	PMEG3002AEL	PMEG3002AELD	PMEG3002EEF
	PMEG4002EL	PMEG4002ELD	
	PMEG6002EL	PMEG6002ELD PMEG2005BELD	
PMEG2005EPK	PMEG2005AEL PMEG2005EL	PMEG2005AELD PMEG2005ELD	
	PMEG3005EL	PMEG3005ELD	PMEG3005EEF
PMEG4005EPK			
PMEG2010EPK		PMEG2010BELD	
PMEG4010EPK			
PMEG2015EPK PMEG4015EPK			
PMEG2020EPK			
PMEG4020EPK			




Medium power low VF Schottky rectifiers single ≥ 200 mA

Types in **bold** represent new products

I_F max (A)	V_F^R max (V)	V_F max (mV) @ I_F max	I_R max (mA) @ V_F^R max	Package	CFP15 (SOT1289)	CFP5 (SOD128)	CFP3 (SOD123W)	
								
				Size (mm)	5.8 x 4.3 x 0.78	3.8 x 2.5 x 1.0	2.6 x 1.7 x 1.0	
				P_{tot} (mW) @ 1 cm ²	2150	1050	950	
				Optimization				
1	20	340	1	Low V_F			PMEG2010ER	
		450	0.05	Low I_R			PMEG2010BER	
	30	360	1.5	Low V_F		PMEG3010EP	PMEG3010ER	
		450	0.05	Low I_R		PMEG3010BEP	PMEG3010BER	
	40	490	0.05	Low V_F		PMEG4010EP	PMEG4010ER	
				Low V_F		PMEG4010ETP	PMEG4010ETR	
		460	0.022	Low V_F /Low I_R			PMEG40T10ER ¹⁾	
	60		530	0.06	Low V_F		PMEG6010EP	PMEG6010ER
				590	0.0008	Low V_F /Low I_R		PMEG6010ETR
			600	0.00065	Low V_F /Low I_R		PMEG60T10ELP¹⁾	
		660	0.0003	Low I_R			PMEG60T10ELR¹⁾	
		770	0.00015	Low I_R			PMEG6010ELR	
2	30	360	3	Low V_F		PMEG3020EP		
		420	1.5	Low V_F		PMEG3020CEP	PMEG3020ER	
		450	0.1	Low I_R		PMEG3020BEP		
		520	0.05	Low I_R		PMEG3020DEP	PMEG3020BER	
	40	490	0.1	Low V_F		PMEG4020EP	PMEG4020ER	
				Low V_F		PMEG4020ETP	PMEG4020ETR	
	60	515	0.022	Low V_F /Low I_R		PMEG40T20EP ¹⁾	PMEG40T20ER ¹⁾	
		530	0.2	Low V_F		PMEG6020EP	PMEG6020ER	
				Low V_F		PMEG6020ETP	PMEG6020ETR	
		620	0.0012	Low V_F /Low I_R		PMEG60T20ELP¹⁾	PMEG60T20ELR ¹⁾	
		680	0.0007	Low I_R		PMEG6020AELP	PMEG6020AELR	
	100	760	0.0003	Low I_R			PMEG6020ELR	
		770	0.0003	Low I_R		PMEG10020AELP	PMEG10020AELR	
		830	0.00015	Low I_R			PMEG10020ELR	
3	30	360	5	Low V_F		PMEG3030EP		
		450	0.15	Low I_R	PMEG030V030EPD	PMEG3030BEP		
	40	490	0.12	Low V_F	PMEG040V030EPD			
				Low V_F		PMEG4030EP		
				Low V_F		PMEG4030ETP		
		525	0.028	Low V_F /Low I_R		PMEG40T30EP ¹⁾	PMEG40T30ER ¹⁾	
		540	0.1	Low I_R			PMEG4030ER	
	45	480	0.044	Low V_F /Low I_R	PMEG045T030EPD ¹⁾			
	50	530	0.1	Low V_F	PMEG050V030EPD			
	60	475	0.4	Low V_F		PMEG6030EVP		
		530	0.2	Low V_F	PMEG060V030EPD	PMEG6030EP		
				Low V_F		PMEG6030ETP		
620		0.0018	Low V_F /Low I_R		PMEG60T30ELP¹⁾	PMEG60T30ELR¹⁾		
690		0.001	Low I_R		PMEG6030ELP			
100	770	0.00045	Low I_R		PMEG10030ELP			
4.5	60	530	0.4	Low V_F		PMEG6045ETP		
5	30	360	8	Low V_F		PMEG3050EP		
		450	0.25	Low I_R		PMEG3050BEP		
		500	0.15	Low V_F	PMEG030V050EPD			
	40	490	0.3	Low V_F		PMEG4050EP		
				Low V_F		PMEG4050ETP		
		520	0.12	Low V_F	PMEG040V050EPD			
	45	525	0.041	Low V_F /Low I_R			PMEG40T50EP ¹⁾	
		490	0.3	Low V_F	PMEG045V050EPD			
		525	0.044	Low V_F /Low I_R	PMEG045T050EPD ¹⁾			
		560	0.4	Low V_F	PMEG060V050EPD			
60	690	0.0018	Low V_F /Low I_R		PMEG60T50ELP¹⁾			
6	100	840	0.00045	Low I_R		PMEG100V060ELPD		
8	100	850	0.0005	Low I_R		PMEG100V080ELPD		









¹⁾ Trench process

Medium power low VF Schottky rectifiers single ≥ 200 mA

I_F max (A)	V_R max (V)	V_F max (mV) @ I_F max	I_R max (mA) @ V_R max	Package	CFP15 (SOT1289)	CFP5 (SOD128)	CFP3 (SOD123W)
							
				Size (mm)	5.8 x 4.3 x 0.78	3.8 x 2.5 x 1.0	2.6 x 1.7 x 1.0
				P_{tot} (mW) @ 1 cm ²	2150	1050	950
				Optimization			
10	45	490	0.6	Low V_F	PMEG045V100EPD		
		540	0.5	Low V_F	PMEG45A10EPD		
		545	0.08	Low V_F /Low I_R	PMEG045T100EPD ¹⁾		
	60	0.7	Low V_F	PMEG060V100EPD			
	100	850	0.0008	Low I_R	PMEG100V100ELPD		
15	45	490	1	Low V_F	PMEG045V150EPD		
		550	0.1	Low V_F /Low I_R	PMEG045T150EPD ¹⁾		
		580		Low V_F /Low I_R	PMEG45T15EPD ¹⁾		
		570	0.098	Low V_F /Low I_R	PMEG045T150EIPD ¹⁾		
	50	500	1	Low V_F	PMEG050V150EPD		
		550	0.1	Low I_R	PMEG050T150EPD ¹⁾		
















¹⁾ Trench process

Medium power low VF Schottky rectifiers single ≥ 200 mA - leaded packages

I_F max (A)	V_R max (V)	V_F max (mV) @ I_F max	I_R max (mA) @ V_R max	Package	SOT457 (SC-74)	SOT23	SOD123	SOD123F	SOT323 (SC-70)	SOD323F (SC-90)	SOD323 (SC-76)	SOD523 (SC-79)
												
				Size (mm)	2.9 x 1.5 x 1.0	2.9 x 1.3 x 1.0	2.7 x 1.6 x 1.2	2.6 x 1.6 x 1.1	2.0 x 1.25 x 0.95	1.7 x 1.25 x 0.7	1.7 x 1.25 x 0.95	1.2 x 0.8 x 0.6
				P_{tot} (mW) @ 1 cm ²	540	420	660	830	400	830	570	500
				Optimization								
0.2	30	480	0.05	Low V_F						PMEG3002EJ		PMEG3002AEB
	40	600	0.01	Low I_r						PMEG4002EJ		PMEG4002EB
	60	600	0.1	Low V_F						PMEG6002EJ		PMEG6002EB
0.5	20	390	0.2	Low V_F		PMEG2005ET	PMEG2005EGW	PMEG2005EH		PMEG2005EJ	PMEG2005AEA	
		480	0.03	Low I_r								PMEG2005EB
	30	430	0.15	Low V_F		PMEG3005ET	PMEG3005EGW	PMEG3005EH		PMEG3005EJ	PMEG3005AEA	
		500	0.5	Low V_F								PMEG3005EB
	40	470	0.1	Low V_F		PMEG4005ET	PMEG4005EGW	PMEG4005EH		PMEG4005EJ	PMEG4005AEA	
		550	1.1	Low V_F		BAT720			1PS70SB20			
640	0.008	Low I_r						PMEG4005CEJ	PMEG4005CEA			
0.75	40	740	0.008	Low I_r							BAT165A	
1	20	430	0.2	Low V_F		PMEG2010AET		PMEG2010AEH				
		500	0.2	Low V_F		PMEG2010ET		PMEG2010EH		PMEG2010EJ	PMEG2010BEA	
		550	0.07	Low I_r						PMEG2010AEJ	PMEG2010EA BAT760	
		620	1.5	Low V_F								PMEG2010AEB
	30	450	1	Low V_F	1PS745B23							
		520	0.1	Low I_r				PMEG3010CEH		PMEG3010CEJ		
		560	0.15	Low V_F		PMEG3010ET	PMEG3010EGW	PMEG3010EH		PMEG3010EJ	PMEG3010BEA	
		680	0.5	Low V_F								PMEG3010EB
	40	570	0.05	Low I_r			PMEG4010CEGW	PMEG4010CEH		PMEG4010CEJ		
		640	0.05	Low V_F		PMEG4010ET	PMEG4010EGW	PMEG4010EH		PMEG4010EJ	PMEG4010BEA	
		840	0.008	Low I_r							PMEG4010CEA	
		60	660	0.05	Low I_r			PMEG6010CEGW	PMEG6010CEH		PMEG6010CEJ	
1.5	20	600	0.2	Low I_r				PMEG2015EH		PMEG2015EJ	PMEG2015EA	
	30	500	1	Low V_F				PMEG3015EH		PMEG3015EJ		
2	10	460	3	Low V_F				PMEG1020EH		PMEG1020EJ	PMEG1020EA	
	20	525	0.2	Low V_F				PMEG2020EH		PMEG2020EJ	PMEG2020AEA	
	30	620	1	Low V_F			PMEG3020EGW	PMEG3020EH		PMEG3020EJ		
3	10	530	3	Low V_F				PMEG1030EH		PMEG1030EJ		

Diodes

Medium power low VF Schottky rectifiers dual >= 200 mA

I_F max (A)	V_R max (V)	V_F max (mV) @ I_F max	I_R max (mA) @ V_R max	Optimization	Package	SOT223 (SC-73)	SOT23	DFN2020-3 (SOT1061)	DFN2020D-3 (SOT1061D)	
										
						Size (mm)	6.5 x 3.5 x 1.65	2.9 x 1.3 x 1.0	2.0 x 2.0 x 0.62	2.0 x 2.0 x 0.63
						P_{tot} (mW) @ 1 cm ²	1500	400	1000	1000
0.5	20	390	0.2	Low V_F			PMEG2005CT			
	30	430	0.15	Low V_F			PMEG3005CT			
	40	470	0.1	Low V_F			PMEG4005CT			
1.0	25	450	1.0	Low V_F		BAT120S				
				Low V_F		BAT120C				
				Low V_F		BAT120A				
	40	500	0.05	Low V_F				PMEG4010CPA	PMEG4010CPAS	
	60	540	0.06	Low V_F				PMEG6010CPA	PMEG6010CPAS	
				Low V_F		BAT160S				
		650	0.35	Low V_F		BAT160C				
				Low V_F		BAT160A				
	2.0	20	420	1.0	Low V_F				PMEG2020CPA	PMEG2020CPAS
30		440	2.0	Low V_F				PMEG3020CPA	PMEG3020CPAS	

Nomenclature of automotive grade Schottky rectifier in medium-power packages

PMEG 40 10 A E T P

NEXPERIA MEGA Schottky rectifier

Max. reverse voltage in V
e.g. 40 = 40 V

Cont. forward current in A
e.g. 10 = 1.0 A

Variant number (optional)

Package indicator:

A	SOD323
B	SOD523
D	SOT457
GW	SOD123
H	SOD123F
L	SOD882
LD	SOD882D
ML	SOD923
P	SOD128
PA	SOT1061
PD	SOT1289
PK	SOD1608
R	SOD123W
T	SOT23

Variant letter (optional):
T = high temperature

Internal configuration:

- A = CA
- B = CC
- E = single
- P = double, parallel
- R = tripple, antiparallel
- S = series
- V = tripple
- W = CA and CC
- X = 2 x series
- Y = 2 x CC
- Z = 2 x CA

Diodes

Nomenclature of automotive grade Schottky rectifier in CFP15 (SOT1289) power package

PMEG 100 V 080 E L PD

NEXPERIA MEGA Schottky rectifier

Max. reverse voltage in V
e.g. 100 = 100 V

Variant letter (design)
V = planar design
T = trench design

Cont. forward current in A
e.g. 080 = 8.0 A

Package indicator:
PD = SOT1289

Variant letter (optional):
L = low leakage current

Internal configuration:
E = single die



100 100

ESD protection, TVS, filtering and signal conditioning

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Low capacitance ESD protection for high-speed interfaces

Number of protected lines		V_{RWM} (V)	C_{line_typ} (pF)	C_{line_max} (pF)	ESD rating max (kV) ^[1]	Surge robustness 8/20 μ s (A)	Configuration	Type	Package	Size (mm)
Unidirectional	Bidirectional									
0	1	5	0.4	0.55	10			PESD5V0F1BLD PESD5V0F1BRLD	DFN1006D-2 (SOD882D) 	1.0 x 0.6 x 0.37
1	0	5	0.95	1.15	8		PESD5V0X1ULD	SOD523 (SC-79) 		
			1.55	1.75	15		PESD5V0X1UALD			
		5	0.95	1.15	8	PESD5V0X1UB	SOT23 	2.9 x 1.3 x 1.0		
			1.55	1.75	15	PESD5V0X1UAB				
		3.3	0.6	1.5	30	5	PESD3V3U1UT	SOT23 		
		5	0.6	1.5	30	5	PESD5V0U1UT			
		12	0.6	1.5	30	5	PESD12VU1UT			
		15	0.6	1.5	30	5	PESD15VU1UT			
	24	0.6	1.5	23	5	PESD24VU1UT				
	2	1	5	0.9	1.3	9		PESD5V0X1BQ	SOT663 	1.6 x 1.2 x 0.55
PESD5V0X1BT								SOT23 	2.9 x 1.3 x 1.0	
0		80	0.6	0.75	30		NUP1301U	SOT323 	2.0 x 1.25 x 0.95	
							NUP1301	SOT23 	2.9 x 1.3 x 1.0	
			2.3	2.75			NUP1301QA	SOT1215 	1.1 x 0.9 x 0.4	
3	0	5.5	1	1.5	8		PRTR5V0U2X	SOT143B 	2.9 x 1.3 x 1.0	
			1.8	-	12		PRTR5V0U2AX			
4	0	5.5	1	-	8		PRTR5V0U4D	SOT457 (SC-74) 	2.9 x 1.5 x 1.0	

^[1] according to IEC 61000-4-2 (contact discharge)

General purpose ESD protection protection devices

Types in **bold** represent new products

Number of protected lines		V _{RWM} (V)	C _{line typ} (pF)	C _{line max} (pF)	P _{PP max} (W) ^[1]	ESD rating max (kV) ^[2]	I _{R max} (µA) @ V _{RWM}	Configuration	Type	Package	Size (mm)		
Unidirectional	Bidirectional												
1	0	5	25	30	42	26	0.1		PESD5V0L1ULD	DFN1006D-2 (SOD882D) 	1.0 x 0.6 x 0.4		
			152	200	150	30	1		PESD5V0S1ULD				
		12	38	75	150	30	0.05		PESD12VS1ULD				
		15	32	70	150	30	0.05		PESD15VS1ULD				
		24	23	50	150	23	0.05		PESD24VS1ULD				
		2.5	229	300	260	30	6		PESD5Z2.5	SOD523 (SC-79) 	1.2 x 0.8 x 0.6		
		3.3	2.6	3.1	-	9	0.1 (@ 3 V)		PESD3V3U1UB				
			34	40	45	30	0.3		PESD3V3L1UB				
			172	200	260	30	0.05		PESD5Z3.3				
			207	300	330	30	2		PESD3V3S1UB				
		5	2	2.6	-	9	0.1		PESD5V0U1UB				
			25	30	42	26	0.1		PESD5V0L1UB				
			89	150	180	30	0.05		PESD5Z5.0				
			152	200	260	30	1		PESD5V0S1UB				
		6	78	150	180	30	0.01		PESD5Z6.0				
		7	69	150	180	30	0.01		PESD5Z7.0				
		12	35	75	200	30	0.01		PESD5Z12				
			38	75	180	30	0.05		PESD12VS1UB				
		15	32	70	160	30	0.05		PESD15VS1UB				
		24	23	50	160	23	0.05		PESD24VS1UB				
		3.3	2.6	3.1	-	9	0.1 (@ 3 V)		PESD3V3U1UA	SOD323 (SC-76) 	1.7 x 1.25 x 0.95		
		5	2	2.6	-	9	0.1		PESD5V0U1UA				
			25	30	42	26	0.1		PESD5V0L1UA				
			480	530	890	30	4		PESD5V0S1UA				
		12	160	180	600	30	0.1		PESD12VS1UA				
		24	23	50	160	23	0.05		PESD24VS1UA				
		5	480	530	890	30	4		PESD5V0S1UJ	SOD323F (SC-90) 	1.7 x 1.25 x 0.7		
		12	160	180	600	30	0.1		PESD12VS1UJ				
		36	18	30	150	30	0.01		PESD36VS1UJ				
		0	1	3.3	101	-	500		30	2	PESD3V3L1BA	SOD323 (SC-76) 	1.7 x 1.25 x 0.95
				5	75	-	500		30	1	PESD5V0L1BA		
				12	19	-	200		30	0.05	PESD12VL1BA		
				15	16	-	200		30	0.05	PESD15VL1BA		
24	11			-	200	23	0.05	PESD24VL1BA					
4.5	6.6			78	-	30	0.05	PTVS4V5D1BL	DFN1006-2 (SOD882) 	1.0 x 0.6 x 0.48			
5.5	70			84	-	30	0.05	PTVS5V5D1BL					

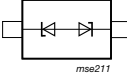






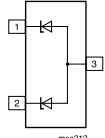
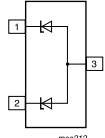
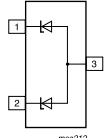
ESD protection, TVS, filtering and signal conditioning

^[1] 8 / 20 µs exponential decay waveform according to IEC 61000-4-5

^[2] according to IEC 61000-4-2 (contact discharge)

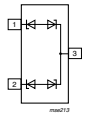

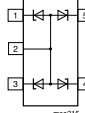





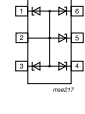





General purpose ESD protection devices

Types in **bold** represent new products

Number of protected lines		V _{RWM} (V)	C _{line typ} (pF)	C _{line max} (pF)	P _{pp} max (W) [1]	ESD rating max (kV) [2]	I _{rr} max (µA) @ V _{RWM}	Configuration	Type	Package	Size (mm)			
Unidirectional	Bidirectional													
0	1	3.3	20	25	-	30	0.05		PESD3V3T1BLD	DFN1006D-2 (SOD882D)	1.0 x 0.6 x 0.37			
		11	13	45	45	30	0.01		PESD5V0V1BLD		1.7 x 1.25 x 0.95			
		35	45	130	45	30	0.1		PESD5V0S1BLD					
		11	13	45	45	30	0.01		PESD5V0V1BB	SOD523 (SC-79)		1.2 x 0.8 x 0.6		
		35	45	130	45	30	0.1		PESD5V0S1BB					
		11	13	45	45	30	0.01		PESD5V0V1BA	SOD323 (SC-76)				
		35	45	130	45	30	0.1		PESD5V0S1BA					
		2.9	3.5	-	10	0.1			PESD5V0U1BLD	DFN1006D-2 (SOD882D)		1.7 x 1.25 x 0.95		
									PESD5V0U1BB	SOD523 (SC-79)				
									PESD5V0U1BA	SOD323 (SC-76)				
		2	1	3.3	200	275	150		30	3		PESD3V3S2UQ	SOT663	1.6 x 1.2 x 0.55
				5	150	215	150		30	0.3		PESD5V0S2UQ		
				12	38	100	150		30	0.03		PESD12VS2UQ		
				15	32	70	150		30	0.05		PESD15VS2UQ		
24	23			50	150	23	0.05	PESD24VS2UQ						
3.3	207			300	330	30	2		PESD3V3S2UT	SOT23		2.9 x 1.3 x 1		
5.2	152			200	260	30	1		PESD5V2S2UT					
12	38			75	180	30	1		PESD12VS2UT					
15	32			70	160	30	1		PESD15VS2UT					
24	23			50	160	23	1		PESD24VS2UT					
36	17			35	160	30	1 (@ 30 V)		PESD36VS2UT					
3.3	207			300	330	30	2				PESD3V3S2UAT		SOT323 (SC-70)	2 x 1.25 x 0.95
5	152			200	260	30	1				PESD5V0S2UAT			
15	32			70	160	30	0.05				PESD15VS2UAT			
24	23			50	160	23	0.05				PESD24VS2UAT			
5	38			46	70	30	0.09 (@ 4 V)				PESD5V0L2UU			
6	34			40	60	30	0.018 (@ 4.3 V)				PESD6V0L2UU			

[1] 8 / 20 µs exponential decay waveform according to IEC 61000-4-2 [2] according to IEC 61000-4-5 (contact discharge)

General purpose ESD protection devices

Number of protected lines		V_{RWM} (V)	C_{line} typ (pF)	C_{line} max (pF)	P_{PP} max (W) ^[1]	ESD rating max (kV) ^[2]	I_R max (μA) @ V_{RWM}	Configuration	Type	Package	Size (mm)
Unidirectional	Bidirectional										
0	2	3.3	101	-	350	30	2		PESD3V3L2BT		2.9 x 1.3 x 1
		5	75	-		30	1		PESD5V0L2BT		
		12	19	-		30	0.05		PESD12VL2BT		
		15	16	-	200	30	0.05		PESD15VL2BT		
		24	11	-		23	0.05		PESD24VL2BT		
		5	35	45	130	30	0.1		PESD5V0S2BT		
		5	2.9	3.5	-	10	0.1		PESD5V0U2BT		
4	3	3.3	22	28	30	20	0.3		PESD3V3L4UW		1.6 x 1.2 x 0.55
		5	16	19	30	20	0.025		PESD5V0L4UW		
		3.3	15	18	16	12	0.3		PESD3V3V4UW		
		5	12	15	16	12	0.025		PESD5V0V4UW		
		3	200	240	-	8	2		BZA856A		2 x 1.25 x 0.95
		3.3	22	28	30	20	0.3				
		5	16	19	30	20	0.025				
		3	200	240	-	8	2				
		3.3	215	300	200	30	0.8		BZA456A		2.9 x 1.5 x 1
		5	165	220	200	30	0.2				
		15	37	48	-	8	0.1				
		24	40	70	200	23	0.01				
0	4	5	45	75	-	15	0.1		BZA408B		1.6 x 1.2 x 0.55
		5	2.9	3.5	-	10	0.1		PESD5V0U4BW		
5	4	3.3	22	28	25	20	0.3		PESD3V3L5UV		1.6 x 1.2 x 0.55
		5	16	19	25	20	0.025		PESD5V0L5UV		
		3.3	22	28	25	20	0.3		PESD3V3LSUY		2 x 1.25 x 0.95
		5	16	19	25	20	0.025				
		3.3	215	300	200	30	0.8		PESD3V3SSUD		2.9 x 1.5 x 1.0
		5	165	220	200	30	0.2				
		24	45	70	200	23	0.015				
0	5	5	2.9	3.5	-	10	0.1		PESD5V0U5BV		1.6 x 1.2 x 0.55








ESD protection, TVS, filtering and signal conditioning

^[1] 8 / 20 μs exponential decay waveform according to IEC 61000-4-5

^[2] according to IEC 61000-4-2 (contact discharge)



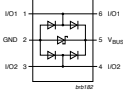


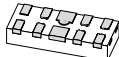

Audio interface protection

Types in **bold** represent new products

Lines	V_{RWM} (V)	$V_{BR\ min}$ (V)	$V_{BR\ max}$ (V)	$C_D\ typ$ (pF)	$C_D\ max$ (pF)	$I_{ppM}\ 8/20\mu s$ (A)	$V_{CL}\ 8/20\mu s @ I_{ppM}$ (V)	V_{Esp} (hV)	Configuration	Type	Package
1	4.5	4.7		65	78	34	13.2	30		PTVS4V5D1BL	DFN1006-2 (SOD882) 
	5.5	5.6	7.6	70	84	35	12.2	30		PTVS5V5D1BL	
	5	5.5	9.5	70	90	28	11.5	30		PESD5V0S2BQA	DFN1010D-3 (SOT1215) 
				35	45	12	14	30		PESD5V0S1BLD	DFN1006D-2 (SOD882D) 
		5.8	7.8	11	13	4.8	12.5	30		PESD5V0V1BLD	

Automotive high-speed network protection

Types in **bold** represent new products

Number of protected lines	V_{RWM} (V)	$C_{line\ typ}$ (pF)	$I_{RWM\ max}$ (μA)	ESD rating max (kV) ⁽¹⁾	Configuration	Type	Package	Size (mm)
2	5	1	0.1	8		PESD2ETH-X	SOT143B 	2.9 x 1.3 x 1.0
		1.8	0.1	12		PESD2ETH-AX		
2	5	1.3	0.1	8		PESD2ETH-D	SOT457 	2.9 x 1.5 x 1.0
		2	0.1	12		PESD2ETH-AD		
4	5.5	0.6	1 @ 3 V	8		PESD1LVDS	DFN2510-10 (SOT1165) 	2.5 x 1.0 x 0.48
		0.6	1 @ 3 V	8		PRTR5V0U4D	SOT457 	2.9 x 1.5 x 1.0

⁽¹⁾ according to IEC 61000-4-2 (contact discharge)

Automotive in-vehicle network bus line protection

Number of protected lines bidirectional	V_{RWM} (V)	C_{line_typ} (pF)	C_{line_max} (pF)	I_{PPM} 8/20 μ s (A)	V_{CL} 8/20 μ s @ I_{PPM} (V)	ESD rating max (kV) [2]	I_r max [μ A] @ V_{RWM}	Configuration	Type	Package	Size (mm)
1	24	14	17	3.5	42	30	0.05		PESD1VN24-A	SOD323 (SC-76)	1.7 x 1.25 x 0.95
	27	14	17	3	45	30	0.05		PESD1VN27-A		
2	24	14	17	3.5	42	30	0.05		PESD2IVN24-T	SOT23	2.0 x 1.25 x 0.95
	27	14	17	3	45	30	0.05		PESD2IVN27-T		
1	27	14	17	3	45	30	0.05		PESD1VN27-U	SOT323	2.0 x 1.25 x 0.95
2	24	14	17	3.5	42	30	0.05		PESD2IVN24-U		
	27	14	17	3	45	30	0.05		PESD2IVN27-U		
1	15 (diode 1) 24 (diode 2)	13	17	3 (diode 1) 5 (diode 2)	70 (diode 1) 44 (diode 2)	23	0.05		PESD1LIN	SOD323 (SC-76)	1.7 x 1.25 x 0.95
2	24	11	17	3	70	23	0.05		PESD1CAN	SOT23	2.9 x 1.3 x 1.0
		25	30	5	41	30	0.01		PESD2CAN		
		11	17	3	70	23	0.05		PESD1FLEX	SOT323	2.0 x 1.25 x 0.95
		9.3	12	3	50	23	0.05		PESD1CAN-U		
1	26.5	8.5	11	3	53	23	0.05		PESD1VN-U	SOT323	2.0 x 1.25 x 0.95
								PESD2IVN-U			

[1] 8 / 20 μ s surge pulse according to IEC 61000-4-5

[2] according to IEC 61000-4-2 (contact discharge)

ESD protection, TVS, filtering and signal conditioning

Charger port protection

Types in **bold** represent new products

Number of protected lines	V_{RWM} (V)	C_{line} (pF)	I_{PPM} 8/20 μ s (A)	Type	Package	Size (mm)
1 x bi	4.5	65	34	PTVS4V5D1BL	DFN1006-2	1.0 x 0.6 x 0.48
1 x bi	5.5	70	35	PTVS5V5D1BL	DFN1006-2	1.0 x 0.6 x 0.48
1 x uni	12	160	22.5	PESD12VS1UJ	SOD323F (SC-90)	1.7 x 1.25 x 0.7
	5	480	22.5	PESD5V0S1UJ		
	12	160	47	PESD12VS1UA	SOD323 (SC-76)	1.7 x 1.25 x 0.95
	5	480	47	PESD5V0S1UA		
2 x bi	5	35	15	PESD5V0S2BQA	DFN1010D-3 (SOT1215)	1.1 x 1.0 x 0.37

Antenna protection (NFC, WiFi,...)

Types in **bold** represent new products

Number of protected lines (bidirectional)	$V_{RWM} (V)$	$C_{line_typ} (pF)$	$C_{line_max} (pF)$	ESD rating ⁽¹⁾ max (kV)	Configuration	Type	Package	Size
1	18	0.35	0.5	10		PESD18VF1BL		1.0 x 0.6 x 0.48
	24	0.3	0.45	10		PESD30VF1BL		
1	30	0.27	-	10		PESD30VF1BL		



⁽¹⁾ according to IEC 61000-4-2 (contact discharge)

USB protection

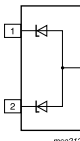

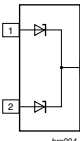

Interface	Number of protected lines	R_{line}	$C_{line} (pF)$	Remark	Type	Package	Size (mm)
USB2.0 (Plastic package)	2	-	1.0	ESD protection for up to 2 ultra high-speed datalines	PRTR5V0U2X		2.9 x 1.3 x 1.0
			1.8	ESD protection for up to 2 ultra high-speed datalines with 12 kV ESD robustness	PRTR5V0U2AX		
	4		0.8	Very low clamp ESD protection for USB2.0 high-speed with 12 kV IEC ESD protection	PUSB2X4Y		2.0 x 1.25 x 0.95
			1	Very low clamp ESD protection for USB2.0 high-speed with 12 kV IEC ESD protection	PUSB2X4D		2.9 x 1.5 x 1.0
				Dual ESD protection for USB2.0 high-speed, SD-card, SIM card	IP4220CZ6		
				Dual ESD protection for USB2.0 high-speed, SD-card, SIM card	PRTR5V0U4D		

TVS diodes, compact

Types in **bold** represent new products

P_{RPM} 10/1000µs	V_{RWM} (V)	V_{BR} min	V_{BR} max	I_{PPM} 8/20µs	V_{CL} 8/20µs	I_{PPM} 10/1000µs	V_{CL} 10/1000µs	Type	Package	Size
300	4.5	4.7	-	34	13.2	-	-	PTVS4V5D1BL	DFN1006-2 (SOD882) 	1.0 x 0.6 x 0.48
	5.5	5.6	7.6	35	12.2	-	-	PTVS5V5D1BL		
	7.5	8.33	9.21	178	19.7	23.3	12.9	PTVS7V5U1UPA	DFN2020-3 (SOT1061) 	2.0 x 2.0 x 0.62
	10	11.1	12.3	148	23	17.6	17	PTVS10VU1UPA		
	12	13.3	14.7	131	25.2	15.1	19.9	PTVS12VU1UPA		
	15	16.7	18.5	111	28.8	12.3	24.4	PTVS15VU1UPA		
	18	20	22.1	97	32	10.3	29.2	PTVS18VU1UPA		
	20	22.2	24.5	98.5	38.7	9.2	32.5	PTVS20VU1UPA		
	22	24.4	26.9	88.5	41	8.4	35.5	PTVS22VU1UPA		
	24	26.7	29.5	79	44.2	7.7	38.8	PTVS24VU1UPA		
26	28.9	31.9	69	43.5	7	43	PTVS26VU1UPA			


TVS diodes, 24 W/40 W

Power (W) (10 / 1000 µs waveform) [1]	V_{RWM} (V)	V_{BR} min (V) @ I_R	V_{BR} typ (V) @ I_R	V_{BR} max (V) @ I_R	I_R (mA)	ESD rating max (kV) [1]	C_{line} typ (pF)	V_{CL} max (V) @ I_{PP} [1]	I_{PP} (A) [1]	I_{RM} max (µA) @ V_{RWM}	Configuration	Type	Package	Size (mm)			
24	3	5.32	5.6	5.88	20	30	210	8	3	5	 mmz12	MMBZ5V6AL	SOT23 	2.9 x 1.3 x 1.0			
		5.89	6.2	6.51	1	30	175	8.7	2.76	0.2		MMBZ6V2AL					
	4.5	6.48	6.8	7.14	1	30	150	9.6	2.5	0.3		MMBZ6V8AL					
	6	8.65	9.1	9.56	1	30	155	14	1.7	0.1		MMBZ9V1AL					
	6.5	9.5	10	10.5	1	30	130	14.2	1.7	0.02		MMBZ10VAL					
40	8.5	11.4	12	12.6	1	30	110	17	2.35	0.005		 mmz04			MMBZ12VAL	SOT23 	2.9 x 1.3 x 1.0
	12	14.25	15	15.75	1	30	85	21	1.9	0.005					MMBZ15VAL		
	13	15.2	16	16.8	1	30	76	23	1.9	0.005					MMBZ16VAL		
	13	15.68	16	16.32	1	30	76	23	1.9	0.005					MMBZ16VTAL		
	14.5	17.1	18	18.9	1	30	70	25	1.6	0.005					MMBZ18VAL		
	17	19	20	21	1	30	65	28	1.4	0.005					MMBZ20VAL		
	22	25.65	27	28.35	1	30	48	40	1	0.005	MMBZ27VAL						
	26	31.35	33	34.65	1	30	45	46	0.87	0.005	MMBZ33VAL						
	8.5	11.4	12	12.6	1	30	110	17	2.35	0.005	MMBZ12VDL						
	12.8	14.3	15	15.8	1	30	85	21.2	1.9	0.005	MMBZ15VDL						
	14.5	17.1	18	18.9	1	30	70	25	1.6	0.005	MMBZ18VCL						
	17	19	20	21	1	30	65	28	1.4	0.005	MMBZ20VCL						
	22	25.65	27	28.35	1	30	48	38	1	0.005	MMBZ27VCL						
	26	31.35	33	34.65	1	30	45	46	0.87	0.005	MMBZ33VCL						

ESD protection, TVS, filtering and signal conditioning

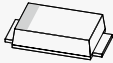
Transient voltage surge suppressor (TVS)

TVS diodes, 400 W

Power (W) (10/1000 µs waveform) ^[1]	V _{RWM} (V)	V _{BR} min (V) @ I _R	V _{BR} typ (V) @ I _R	V _{BR} max (V) @ I _R	I _R (mA)	V _{CL} max (V) @ I _{PP} ^[1]	I _{PP} (A) ^[1]	I _{RM} typ (µA) @ V _{RWM}	I _{RM} max (µA) @ V _{RWM}	Type (T _J max = 150 °C)	Type (T _J max = 185 °C)	Package	Size (mm)
350	3.5	5.20	5.60	6.00	10	8.0	43.8	5	600	PTVS3V3S1UR	PTVS3V3S1UTR		
400	5.0	6.40	6.70	7.00	10	9.2	43.5	5	400	PTVS5V0S1UR	PTVS5V0S1UTR		
	6.0	6.67	7.02	7.37	10	10.3	38.8	5	400	PTVS6V0S1UR	PTVS6V0S1UTR		
	6.5	7.22	7.60	7.98	10	11.2	35.7	5	250	PTVS6V5S1UR	PTVS6V5S1UTR		
	7.0	7.78	8.20	8.60	10	12.0	33.3	3	100	PTVS7V0S1UR	PTVS7V0S1UTR		
	7.5	8.33	8.77	9.21	1	12.9	31.0	0.2	50	PTVS7V5S1UR	PTVS7V5S1UTR		
	8.0	8.89	9.36	9.83	1	13.6	29.4	0.03	25	PTVS8V0S1UR	PTVS8V0S1UTR		
	8.5	9.44	9.92	10.40	1	14.4	27.8	0.01	10	PTVS8V5S1UR	PTVS8V5S1UTR		
	9.0	10.00	10.55	11.10	1	15.4	26.0	0.005	5	PTVS9V0S1UR	PTVS9V0S1UTR		
	10	11.10	11.70	12.30	1	17.0	23.5	0.005	2.5	PTVS10VS1UR	PTVS10VS1UTR		
	11	12.20	12.85	13.50	1	18.2	22.0	0.005	2.5	PTVS11VS1UR	PTVS11VS1UTR		
	12	13.30	14.00	14.70	1	19.9	20.1	0.005	2.5	PTVS12VS1UR	PTVS12VS1UTR		
	13	14.40	15.15	15.90	1	21.5	18.6	0.001	0.1	PTVS13VS1UR	PTVS13VS1UTR		
	14	15.60	16.40	17.20	1	23.2	17.2	0.001	0.1	PTVS14VS1UR	PTVS14VS1UTR		
	15	16.70	17.60	18.50	1	24.4	16.4	0.001	0.1	PTVS15VS1UR	PTVS15VS1UTR		
	16	17.80	18.75	19.70	1	26.0	15.4	0.001	0.1	PTVS16VS1UR	PTVS16VS1UTR		
	17	18.90	19.90	20.90	1	27.6	14.5	0.001	0.1	PTVS17VS1UR	PTVS17VS1UTR		
	18	20.00	21.00	22.10	1	29.2	13.7	0.001	0.1	PTVS18VS1UR	PTVS18VS1UTR	SOD123W	2.6 x 1.7 x 1.0
	20	22.20	23.35	24.50	1	32.4	12.3	0.001	0.1	PTVS20VS1UR	PTVS20VS1UTR		
	22	24.40	25.60	26.90	1	35.5	11.3	0.001	0.1	PTVS22VS1UR	PTVS22VS1UTR		
	24	26.70	28.10	29.50	1	38.9	10.3	0.001	0.1	PTVS24VS1UR	PTVS24VS1UTR		
	26	28.90	30.40	31.90	1	42.1	9.5	0.001	0.1	PTVS26VS1UR	PTVS26VS1UTR		
	28	31.10	32.80	34.40	1	45.4	8.8	0.001	0.1	PTVS28VS1UR	PTVS28VS1UTR		
	30	33.30	35.10	36.80	1	48.4	8.3	0.001	0.1	PTVS30VS1UR	PTVS30VS1UTR		
33	36.70	38.70	40.60	1	53.3	7.5	0.001	0.1	PTVS33VS1UR	PTVS33VS1UTR			
36	40.00	42.10	44.20	1	58.1	6.9	0.001	0.1	PTVS36VS1UR	PTVS36VS1UTR			
40	44.40	46.80	49.10	1	64.5	6.2	0.001	0.1	PTVS40VS1UR	PTVS40VS1UTR			
43	47.80	50.30	52.80	1	69.4	5.8	0.001	0.1	PTVS43VS1UR	PTVS43VS1UTR			
45	50.00	52.65	55.30	1	72.7	5.5	0.001	0.1	PTVS45VS1UR	PTVS45VS1UTR			
48	53.30	56.10	58.90	1	77.4	5.2	0.001	0.1	PTVS48VS1UR	PTVS48VS1UTR			
51	56.70	59.70	62.70	1	82.4	4.9	0.001	0.1	PTVS51VS1UR	PTVS51VS1UTR			
54	60.00	63.15	66.30	1	87.1	4.6	0.001	0.1	PTVS54VS1UR	PTVS54VS1UTR			
58	64.40	67.80	71.20	1	93.6	4.3	0.001	0.1	PTVS58VS1UR	PTVS58VS1UTR			
60	66.70	70.20	73.70	1	96.8	4.1	0.001	0.1	PTVS60VS1UR	PTVS60VS1UTR			
64	71.10	74.85	78.60	1	103.0	3.9	0.001	0.1	PTVS64VS1UR	PTVS64VS1UTR			

^[1] 10 / 1000 µs according to IEC 61643-321

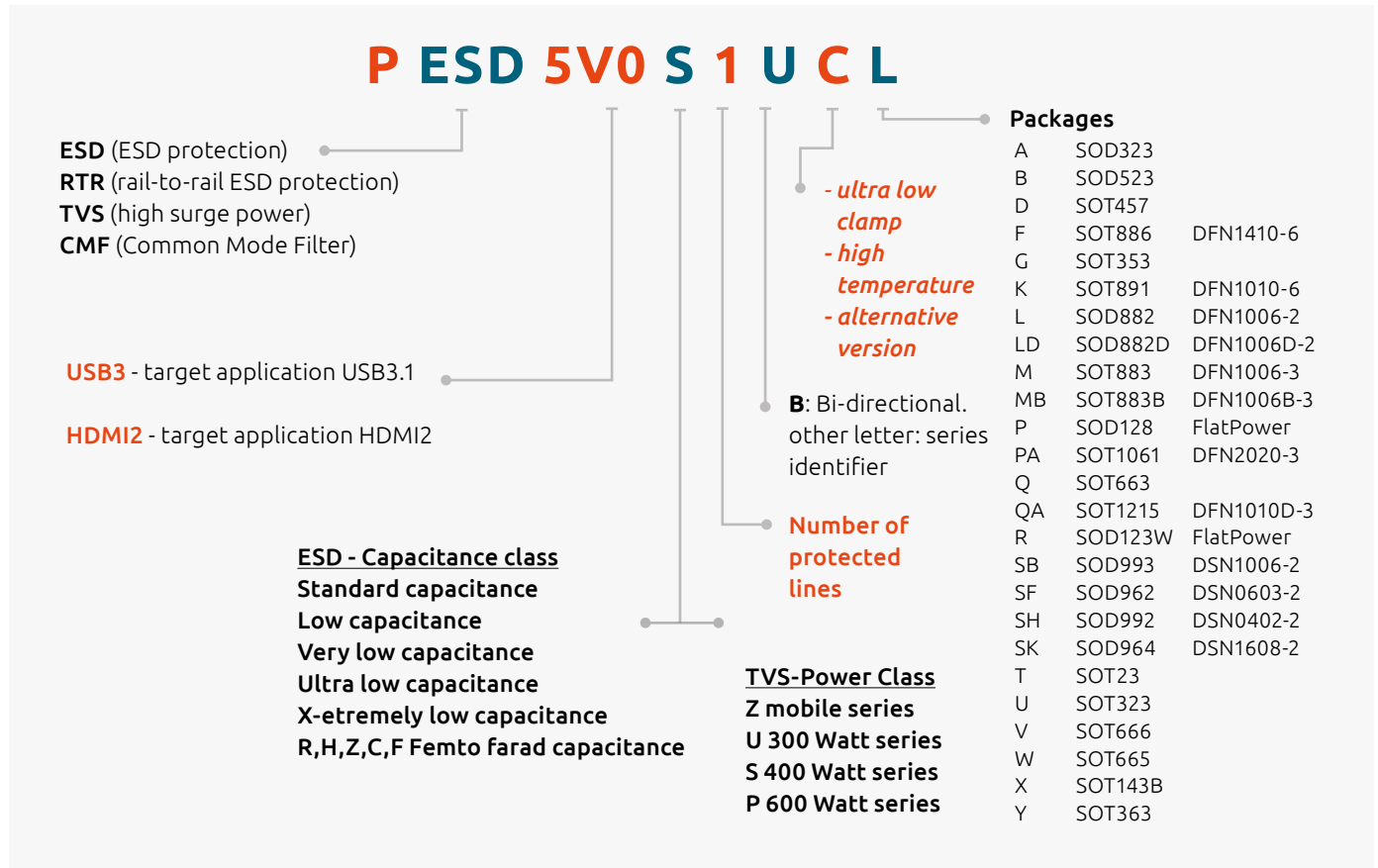
TVS diodes, 600 W

Power (W) (10 / 1000 µs waveform) ⁽¹⁾	V _{RWM} (V)	V _{BR} min (V) @ I _R	V _{BR} typ (V) @ I _R	V _{BR} max (V) @ I _R	I _R (mA)	V _{CL} max (V) @ I _{PP} ⁽¹⁾	I _{PP} (A) ⁽¹⁾	I _{RM} typ (µA) @ V _{RWM}	I _{RM} max (µA) @ V _{RWM}	Type (T _J max = 150 °C)	Type (T _J max = 185 °C)	Package	Size (mm)
600	3.5	5.20	5.60	6.00	10	8	75	5	600	PTVS3V3P1UP	PTVS3V3P1UTP	SOD128 	3.8 x 2.6 x 1.0
	5	6.40	6.70	7.00	10	9.2	65.2	5	400	PTVS5V0P1UP	PTVS5V0P1UTP		
	6	6.67	7.02	7.37	10	10.3	58.3	5	400	PTVS6V0P1UP	PTVS6V0P1UTP		
	6.5	7.22	7.60	7.98	10	11.2	53.6	5	250	PTVS6V5P1UP	PTVS6V5P1UTP		
	7	7.78	8.20	8.60	10	12	50	3	100	PTVS7V0P1UP	PTVS7V0P1UTP		
	7.5	8.33	8.77	9.21	1	12.9	46.5	0.2	50	PTVS7V5P1UP	PTVS7V5P1UTP		
	8	8.89	9.36	9.83	1	13.6	44.1	0.03	25	PTVS8V0P1UP	PTVS8V0P1UTP		
	8.5	9.44	9.92	10.40	1	14.4	41.7	0.01	10	PTVS8V5P1UP	PTVS8V5P1UTP		
	9	10.00	10.55	11.10	1	15.4	39	0.005	5	PTVS9V0P1UP	PTVS9V0P1UTP		
	10	11.10	11.70	12.30	1	17	35.3	0.005	2.5	PTVS10VP1UP	PTVS10VP1UTP		
	11	12.20	12.85	13.50	1	18.2	33	0.005	2.5	PTVS11VP1UP	PTVS11VP1UTP		
	12	13.30	14.00	14.70	1	19.9	30.2	0.005	2.5	PTVS12VP1UP	PTVS12VP1UTP		
	13	14.40	15.15	15.90	1	21.5	27.9	0.001	0.1	PTVS13VP1UP	PTVS13VP1UTP		
	14	15.60	16.40	17.20	1	23.2	25.9	0.001	0.1	PTVS14VP1UP	PTVS14VP1UTP		
	15	16.70	17.60	18.50	1	24.4	24.6	0.001	0.1	PTVS15VP1UP	PTVS15VP1UTP		
	16	17.80	18.75	19.70	1	26	23.1	0.001	0.1	PTVS16VP1UP	PTVS16VP1UTP		
	17	18.90	19.90	20.90	1	27.6	21.7	0.001	0.1	PTVS17VP1UP	PTVS17VP1UTP		
	18	20.00	21.00	22.10	1	29.2	20.5	0.001	0.1	PTVS18VP1UP	PTVS18VP1UTP		
	20	22.20	23.35	24.50	1	32.4	18.5	0.001	0.1	PTVS20VP1UP	PTVS20VP1UTP		
	22	24.40	25.60	26.90	1	35.5	16.9	0.001	0.1	PTVS22VP1UP	PTVS22VP1UTP		
	24	26.70	28.10	29.50	1	38.9	15.4	0.001	0.1	PTVS24VP1UP	PTVS24VP1UTP		
	26	28.90	30.40	31.90	1	42.1	14.2	0.001	0.1	PTVS26VP1UP	PTVS26VP1UTP		
	28	31.10	32.80	34.40	1	45.4	13.2	0.001	0.1	PTVS28VP1UP	PTVS28VP1UTP		
	30	33.30	35.10	36.80	1	48.4	12.4	0.001	0.1	PTVS30VP1UP	PTVS30VP1UTP		
	33	36.70	38.70	40.60	1	53.3	11.3	0.001	0.1	PTVS33VP1UP	PTVS33VP1UTP		
	36	40.00	42.10	44.20	1	58.1	10.3	0.001	0.1	PTVS36VP1UP	PTVS36VP1UTP		
40	44.40	46.80	49.10	1	64.5	9.3	0.001	0.1	PTVS40VP1UP	PTVS40VP1UTP			
43	47.80	50.30	52.80	1	69.4	8.6	0.001	0.1	PTVS43VP1UP	PTVS43VP1UTP			
45	50.00	52.65	55.30	1	72.7	8.3	0.001	0.1	PTVS45VP1UP	PTVS45VP1UTP			
48	53.30	56.10	58.90	1	77.4	7.8	0.001	0.1	PTVS48VP1UP	PTVS48VP1UTP			
51	56.70	59.70	62.70	1	82.4	7.3	0.001	0.1	PTVS51VP1UP	PTVS51VP1UTP			
54	60.00	63.15	66.30	1	87.1	6.9	0.001	0.1	PTVS54VP1UP	PTVS54VP1UTP			
58	64.40	67.80	71.20	1	93.6	6.4	0.001	0.1	PTVS58VP1UP	PTVS58VP1UTP			
60	66.70	70.20	73.70	1	96.8	6.2	0.001	0.1	PTVS60VP1UP	PTVS60VP1UTP			
64	71.10	74.85	78.60	1	103	5.8	0.001	0.1	PTVS64VP1UP	PTVS64VP1UTP			

ESD protection, TVS, filtering and signal conditioning

⁽¹⁾ 10 / 1000 µs according to IEC 61643-321

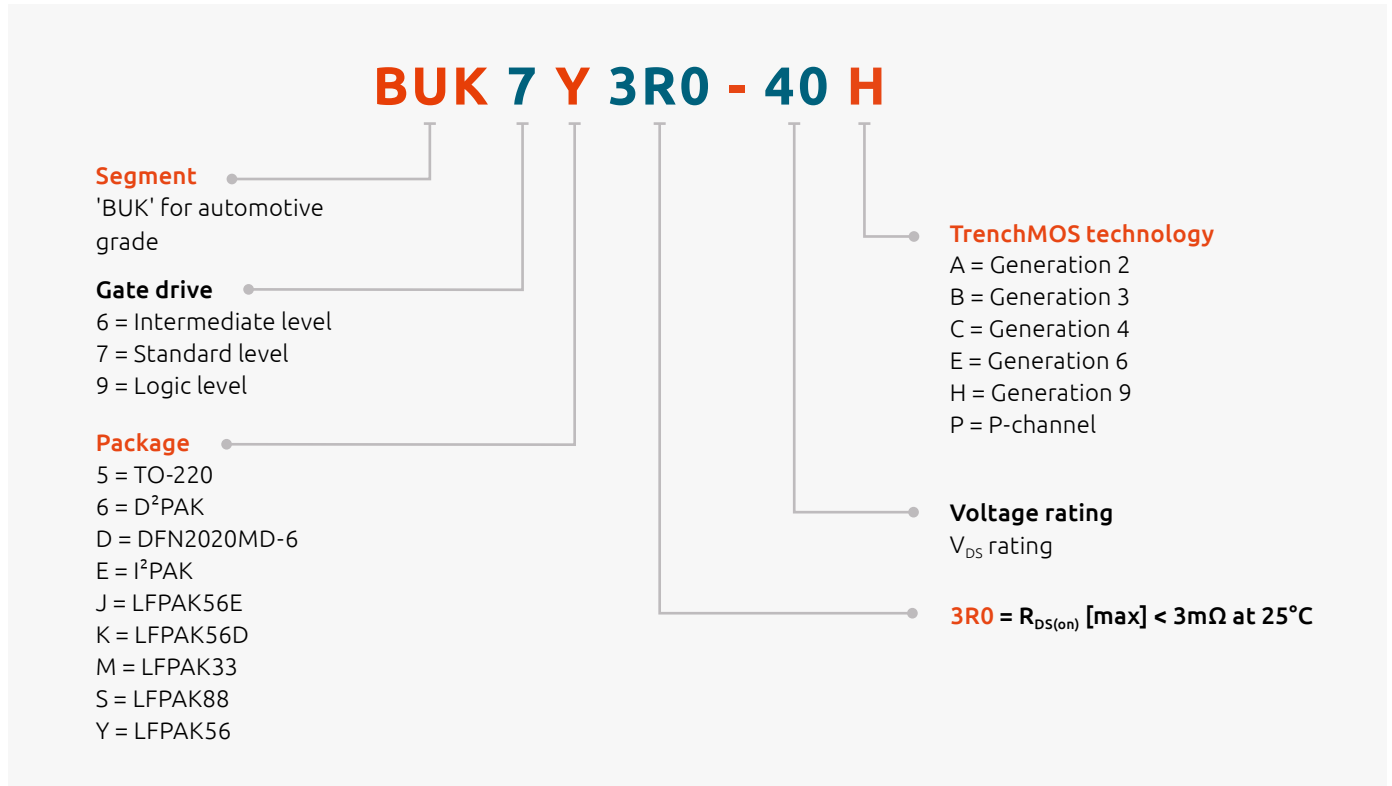
Nomenclature - protection devices





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Automotive grade MOSFETs nomenclature









N-channel 30V automotive power MOSFETs

Package name	Type number	V _{DS} [max] (V)	R _{DS(on)} [max] @ 10 V (mΩ)	R _{DS(on)} [max] @ 5 V (mΩ)	I _D [max] @ 25 °C (A)	R _{th(j-mb)} [max] (K/W)
D ² PAK (SOT404)	BUK762R7-30B	30	2.7		75	0.5
	BUK763R4-30B	30	3.4		75	0.59
LFPAK56; Power-SO8 (SOT669)	BUK9Y07-30B	30	6	7	75	1.42
	BUK7Y07-30B	30	7		75	1.42
	BUK9Y11-30B	30	9	11	59	2
	BUK7Y10-30B	30	10		67	1.76
	BUK9Y22-30B	30	19	22	38	2.53
	BUK7Y20-30B	30	20		40	2.53
LFPAK56D (SOT1205)	BUK9K5R1-30E	30	4.4	5.3	40	2.21
	BUK9K5R6-30E	30	4.7	5.8	40	2.36
	BUK7K5R1-30E	30	5.1		40	2.21
	BUK7K5R6-30E	30	5.6		40	2.36
LFPAK33 (SOT1210)	BUK9M5R2-30E	30	4.1	5.2	70	1.89
	BUK9M6R6-30E	30	5.3	6.6	70	2
	BUK9M10-30E	30	7.8	10	54	2.75
	BUK9M17-30E	30	14	17	37	3.4

N-channel 40V automotive power MOSFETs

Types in **bold red** are in development, types in **bold** represent new products




Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (m Ω)	$R_{DS(on)}$ [max] @ 5 V (m Ω)	I_b [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)	
TO-220AB (SOT78)		BUK751R8-40E	40	1.8		120	0.43
		BUK752R3-40E	40	2.3		120	0.51
		BUK753R1-40E	40	3.1		100	0.64
		BUK758R3-40E	40	7.4		75	1.56
LFPAK88 (SOT1235)		BUK7S0R7-40H	40	0.7		425	0.29
		BUK7S0R9-40H	40	0.9		375	0.31
		BUK7S1R0-40H	40	1		325	0.39
D ² PAK (SOT404)		BUK961R6-40E	40	1.4	1.6	120	0.43
		BUK761R6-40E	40	1.6		120	0.43
		BUK761R7-40E	40	1.6		120	0.46
		BUK762R0-40E	40	2		120	0.51
		BUK962R6-40E	40	2.4	2.8	100	0.57
		BUK762R6-40E	40	2.6		100	0.57
		BUK963R1-40E	40	2.7	3.1	100	0.64
		BUK762R9-40E	40	2.9		100	0.64
		BUK964R1-40E	40	3.5	4.1	75	0.82
		BUK764R0-40E	40	4		75	0.82
		BUK965R4-40E	40	4.4	5.4	75	1.09
		BUK765R3-40E	40	4.9		75	1.09
		BUK768R1-40E	40	7.2		75	1.56
		I ² PAK (SOT226)		BUK7E1R8-40E	40	1.8	
BUK7E1R9-40E	40			1.9		120	0.46
BUK7E2R3-40E	40			2.3		120	0.51
BUK7E3R1-40E	40			3.1		100	0.64
BUK7E8R3-40E	40			7.4		75	1.56
LFPAK56E (SOT1023)		BUK9J0R9-40H	40	0.9	1.2	220	0.3
		BUK7J1R0-40H	40	1		220	0.3
		BUK7J1R4-40H	40	1.4		120	0.38
LFPAK56; Power-SO8 (SOT669)		BUK9Y1R3-40H	40	1.3	1.8	120	0.38
		BUK7Y1R4-40H	40	1.4		190	0.38
		BUK9Y1R6-40H	40	1.6	2.2	120	0.51
		BUK7Y1R7-40H	40	1.7		120	0.51
		BUK9Y1R9-40H	40	1.9	2.6	120	0.69
		BUK7Y2R0-40H	40	2		120	0.69
		BUK9Y2R4-40H	40	2.4	3.2	120	0.79
		BUK9Y3R0-40E	40	2.5	3	100	0.77
		BUK7Y2R5-40H	40	2.5		120	0.79
		BUK9Y2R8-40H	40	2.8	3.9	120	0.87
		BUK7Y3R0-40H	40	3		120	0.87
		BUK7Y3R5-40H	40	3.5		120	1.3
		BUK7Y3R5-40E	40	3.5		100	0.9
		BUK9Y3R5-40E	40	3.6	3.8	100	0.9
		BUK9Y4R4-40E	40	3.7	4.4	100	1.02
		BUK7Y4R4-40E	40	4.4		100	1.02
		BUK9Y7R6-40E	40	6	7.6	79	1.58
		BUK7Y7R6-40E	40	7.6		79	1.58
		BUK9Y12-40E	40	10	12	52	2.31
		BUK7Y12-40E	40	12		52	2.31
BUK9Y21-40E	40	17	21	33	3.33		
BUK7Y21-40E	40	21		33	3.33		
BUK9Y29-40E	40	25	29	25	4.03		
BUK7Y29-40E	40	29		26	4.03		

N-channel 40V automotive power MOSFETs

Types in **bold red** are in development, types in **bold** represent new products

Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (m Ω)	$R_{DS(on)}$ [max] @ 5 V (m Ω)	I_D [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)
LFPAK56D (SOT1205)	BUK7K6R2-40E	40	5.8		40	2.21
	BUK9K6R2-40E	40	6	6.2	40	2.21
	BUK9K6R8-40E	40	6.1	7.2	40	2.36
	BUK7K6R8-40E	40	6.8			2.36
	BUK9K8R7-40E	40	8	9.4	30	2.84
	BUK7K8R7-40E	40	8.5			2.84
	BUK9K18-40E	40	16	20	30	3.96
	BUK7K18-40E	40	19		24	3.96
	BUK9K25-40E	40	24	29	18	4.68
	BUK7K25-40E	40	25			4.68
LFPAK33 (SOT1210)	BUK7M3R3-40H	40	3.3			
	BUK9M3R3-40H	40		3.3		
	BUK7M4R3-40H	40	4.3			
	BUK9M4R3-40H	40		4.3		
	BUK7M5R0-40H	40	5			
	BUK9M5R0-40H	40		5		
	BUK7M6R0-40H	40	6			
	BUK9M6R0-40H	40		6		
	BUK7M6R3-40E	40	6.3		70	1.89
	BUK7M6R7-40H	40	6.7			
	BUK9M6R7-40H	40		6.7		
	BUK7M8R0-40E	40	8		69	2
	BUK7M8R5-40H	40	8			
	BUK9M8R5-40H	40		8		
	BUK7M10-40E	40	10		56	2.43
	BUK7M12-40E	40	12		48	2.75
	BUK7M9R5-40H	40	9.5			
	BUK9M9R5-40H	40		9.5		
	BUK7M21-40E	40	21		33	3.4
	BUK7M11-40H	40	11			
	BUK9M11-40H	40		11		
	BUK7M45-40E	40	45		19	4.8
	BUK9M14-40E	40	11	14	44	2.75
	BUK9M24-40E	40	20	24	30	3.4
	BUK7M15-40H	40	15			
	BUK9M15-40H	40		15		
	BUK7M20-40H	40	20			
	BUK9M20-40H	40		20		
	BUK9M52-40E	40	40	52	18	4.8
	BUK9M7R2-40E	40	5.8	7.2	70	1.89
BUK9M9R1-40E	40	7.3	9.1	64	2	
BUK9M11-40E	40	9	11	53	2.43	

N-channel 55V-60V automotive power MOSFETs

Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (m Ω)	$R_{DS(on)}$ [max] @ 5 V (m Ω)	I_D [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)	
TO-220AB (SOT78)		BUK953R5-60E	60	3.4	3.7	120	0.51
		BUK954R8-60E	60	4.5	4.9	100	0.64
D ² PAK (SOT404)		BUK7610-55AL	55	10		75	0.5
		BUK9620-55A	55	18	20	54	1.2
		BUK7620-55A	55	20		54	1.2
		BUK9624-55A	55	22	24	46	1.4
		BUK9628-55A	55	25	28	42	1.5
		BUK9635-55A	55	32	35	34	1.8
		BUK7635-55A	55	35		35	1.7
		BUK9675-55A	55	68	75	20	2.4
		BUK7675-55A	55	75		20	2.4
		BUK962R5-60E	60	2.3	2.5	120	0.43
		BUK762R4-60E	60	2.4		120	0.43
		BUK962R8-60E	60	2.5	2.8	120	0.46
		BUK762R6-60E	60	2.6		120	0.46
		BUK963R3-60E	60	3	3.3	120	0.51
		BUK763R1-60E	60	3.1		120	0.51
		BUK964R2-60E	60	3.9	4.2	100	0.57
		BUK763R9-60E	60	3.9		100	0.57
		BUK964R8-60E	60	4.4	4.8	100	0.64
		BUK764R4-60E	60	4.5		100	0.64
		BUK966R5-60E	60	5.9	6.5	75	0.82
		BUK766R0-60E	60	6		75	0.82
		BUK969R0-60E	60	8	9	75	1.09
		BUK768R3-60E	60	8.3		75	1.09
BUK9614-60E	60	13	14	56	1.56		
BUK7613-60E	60	13		58	1.56		
I ² PAK (SOT226)		BUK7E2R6-60E	60	2.6		120	0.43
		BUK7E3R5-60E	60	3.5		120	0.51
		BUK7E4R6-60E	60	4.6		100	0.64
		BUK7E13-60E	60	13		58	1.56





N-channel 55V-60V automotive power MOSFETs

Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (m Ω)	$R_{DS(on)}$ [max] @ 5 V (m Ω)	I_D [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)
LFPAK56; Power-SO8 (SOT669)	BUK9Y4R8-60E	60	4.1	4.8	100	0.63
	BUK7Y4R8-60E	60	4.8		100	0.63
	BUK9Y6R0-60E	60	5.2	6	100	0.77
	BUK9Y7R2-60E	60	5.6	7.2	100	0.9
	BUK7Y6R0-60E	60	6		100	0.77
	BUK7Y7R2-60E	60	7.2		100	0.9
	BUK9Y8R7-60E	60	7.5	8.7	86	1.02
	BUK7Y8R7-60E	60	8.7		87	1.02
	BUK9Y15-60E	60	13	15	53	1.58
	BUK7Y15-60E	60	15		53	1.59
	BUK9Y25-60E	60	22	25	34	2.31
	BUK7Y25-60E	60	25		34	2.31
	BUK9Y43-60E	60	38	43	22	3.33
	BUK7Y43-60E	60	43		22	3.33
	BUK9Y59-60E	60	52	59	17	4.03
	BUK7Y59-60E	60	59		17	4.03
LFPAK56D (SOT1205)	BUK7K12-60E	60	9.3			2.21
	BUK7K13-60E	60	10		40	2.36
	BUK9K12-60E	60	11	12	35	2.21
	BUK9K13-60E	60	12	13	40	2.36
	BUK7K17-60E	60	14		30	2.84
	BUK9K17-60E	60	16	17	26	2.84
	BUK7K35-60E	60	30		21	3.96
	BUK9K35-60E	60	32	35	22	3.96
	BUK7K52-60E	60	45		15	4.68
BUK9K52-60E	60	49	55	16	4.68	
LFPAK33 (SOT1210)	BUK7M9R9-60E	60	9.9		60	1.89
	BUK9M12-60E	60	11	12	54	1.89
	BUK7M12-60E	60	12		53	2
	BUK9M15-60E	60	13	15	47	2
	BUK7M15-60E	60	15		43	2.43
	BUK9M19-60E	60	17	19	38	2.43
	BUK7M19-60E	60	19		36	2.75
	BUK9M24-60E	60	21	24	32	2.75
	BUK7M33-60E	60	33			3.4
	BUK9M42-60E	60	37	42	22	3.4
	BUK7M42-60E	60	42		20	4.17
	BUK9M53-60E	60	46	53	17	4.17
	BUK7M67-60E	60	67		14	4.8
BUK9M85-60E	60	73	85	13	4.8	
SOT223	BUK9832-55A/CU	55	29	32		
	BUK9880-55A/CU	55	73	80		
	BUK7880-55A/CU	55	80			
	BUK98150-55A/CU	55	137	150		
	BUK78150-55A/CU	55	150			

N-channel 75V-80V automotive power MOSFETs

Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (m Ω)	$R_{DS(on)}$ [max] @ 5 V (m Ω)	I_b [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)
TO-220AB (SOT78)	BUK753R8-80E	80	4		120	0.43
D ² PAK (SOT404)	BUK7613-75B	75	13		75	0.95
	BUK9616-75B	75	14	16	67	0.95
	BUK7623-75A	75	23		53	1.1
	BUK763R8-80E	80	3.8		120	0.43
	BUK964R2-80E	80	4	4.2	120	0.43
	BUK764R2-80E	80	4.2		120	0.46
	BUK964R7-80E	80	4.5	4.7	120	0.46
	BUK769R6-80E	80	9.6		75	0.82
	BUK9611-80E	80	10	11	75	0.82
LFPAK56; Power-SO8 (SOT669)	BUK7Y7R8-80E	80	7.8		100	0.63
	BUK9Y8R5-80E	80	8	8.5	100	0.63
	BUK7Y9R9-80E	80	9.9		89	0.77
	BUK9Y11-80E	80	10	11	84	0.77
	BUK9Y14-80E	80	14	15	62	1.02
	BUK7Y14-80E	80	14		65	1.02
	BUK9Y25-80E	80	25	27	37	1.58
	BUK7Y25-80E	80	25		39	1.58
	BUK9Y41-80E	80	41	45	24	2.33
	BUK7Y41-80E	80	41		25	2.31
	BUK9Y72-80E	80	72	78	15	3.33
	BUK7Y72-80E	80	72		16	3.33
	BUK9Y107-80E	80	98	107	12	4.03
	BUK7Y98-80E	80	98		12	4.03
LFPAK56D (SOT1205)	BUK7K15-80E	80	15		23	2.21
	BUK7K17-80E	80	17		21	2.36
	BUK7K23-80E	80	23		17	2.21
	BUK9K20-80E	80	17	19	23	2.84
	BUK9K22-80E	80	19	22	21	2.36
	BUK9K30-80E	80	26	30	17	2.84
LFPAK33 (SOT1210)	BUK7M17-80E	80	17		43	1.89
	BUK9M23-80E	80	20	23	37	1.89
	BUK7M22-80E	80	22		37	2
	BUK7M27-80E	80	27		30	2.43
	BUK9M28-80E	80	28	28	33	2
BUK9M35-80E	80	35	35	26	2.43	

N-channel 100V automotive power MOSFETs

Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (m Ω)	$R_{DS(on)}$ [max] @ 5 V (m Ω)	I_D [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)			
TO-220AB (SOT78)		BUK755R4-100E	100	5.2		120	0.43		
		BUK765R0-100E	100	5		120	0.43		
D ² PAK (SOT404)		BUK965R8-100E	100	5.6	5.8	120	0.43		
		BUK768R1-100E	100	8.1		100	0.57		
		BUK969R3-100E	100	8.9	9.3	100	0.57		
		BUK7613-100E	100	13		72	0.82		
		BUK9615-100E	100	14	15	66	0.82		
		BUK7631-100E	100	31		34	1.56		
		BUK9637-100E	100	36	37	31	1.56		
		BUK9660-100A	100	58	60	26	1.4		
		BUK7660-100A	100	60		26	1.4		
		BUK9675-100A	100	72	75	23	1.5		
		BUK7675-100A	100	75		23	1.5		
		BUK96180-100A	100	173	180	11	2.8		
		IPAK (SOT226)		BUK7E5R2-100E	100	5.2		120	0.43
				BUK9Y12-100E	100	12	12	85	0.63
LFPAK56; Power-SO8 (SOT669)		BUK7Y12-100E	100	12		85	0.63		
		BUK9Y15-100E	100	15	15	69	0.77		
		BUK7Y15-100E	100	15		68	0.77		
		BUK9Y19-100E	100	18	19	56	0.9		
		BUK7Y19-100E	100	19		56	0.9		
		BUK9Y22-100E	100	22	22	49	1.02		
		BUK7Y22-100E	100	22		49	1.02		
		BUK9Y38-100E	100	38	38	30	1.58		
		BUK7Y38-100E	100	38		30	1.58		
		BUK9Y65-100E	100	64	65	19	2.31		
		BUK7Y65-100E	100	65		19	2.31		
		BUK9Y113-100E	100	110	113	12	3.33		
		BUK7Y113-100E	100	113		12	3.33		
		BUK9Y153-100E	100	146	153	9.4	4.03		
		BUK7Y153-100E	100	153		9.4	4.03		

N-channel 100V automotive power MOSFETs

Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (m Ω)	$R_{DS(on)}$ [max] @ 5 V (m Ω)	I_D [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)
LFPAK56D (SOT1205)	BUK7K29-100E	100	25		29.5	2.21
	BUK9K29-100E	100	27	29	30	2.21
	BUK7K32-100E	100	28		29	2.36
	BUK9K32-100E	100	31	33	26	2.36
	BUK7K45-100E	100	38		21	2.84
	BUK9K45-100E	100	42	45	21	2.84
	BUK7K89-100E	100	83		13	3.96
	BUK9K89-100E	100	85	89	13	3.96
	BUK7K134-100E	100	121		9.8	4.68
	BUK9K134-100E	100	154	159	8.5	4.68
LFPAK33 (SOT1210)	BUK9M34-100E	100	34	34	29	1.89
	BUK9M43-100E	100	43	44	26	1.88
	BUK9M120-100E	100	119	120	12	3.4
	BUK9M156-100E	100	150	156	9.3	4.17
SOT223	BUK98180-100A/CU	100	173	180	4.6	
	BUK9875-100A/CU	101	72	75	7	

P-channel 30V-60V automotive power MOSFETs


Types in **bold red** are in development

Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (m Ω)	I_D [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)
LFPAK56	BUK6Y12-30P	30	12	67	1.4
	BUK6Y20-30P	30	20	41	2.3
	BUK6Y15-40P	40	15	63	1.4
	BUK6Y25-40P	40	25	40	2.3
	BUK6Y32-60P	60	32	39	1.4
	BUK6Y57-60P	60	57	23	2.3

Small-signal automotive MOSFETs – Low $R_{DS(on)}$

Package												
Size (mm)												
P _{tot} (mW)												
Polarity	V _{DS} (V)	V _{GS} (V)	I _D (A)	V _{GS(th)} min (V)	V _{GS(th)} max (V)	ESD protection (kV)	R _{DS(on)} typ (mΩ) @ V _{GS} =					
							10 V	4.5 V	2.5 V	1.8 V		
N-channel	20	8	4.7	0.45	1	2	-	24	29	40		
			12.9	0.4	0.9	2	-	10	12	16		
		12	11.4	0.4	0.9	2	-	12	15	20		
			6.3	0.75	1.25	2	-	16	24	-		
	30	12	11.3	0.4	0.9	2	-	13	14	17		
			5	0.4	0.9	2	-	28	32	37		
			4	0.75	1.25	2	-	55	72	-		
		20	5.5	1	2.5	2	17	22	-	-		
			3.9	1	2.5	2	30	39	-	-		
			3.7	1	2.5	2	54	70	-	-		
	40	15	19	1.4	2.1	-	18	22	-	-		
			19	1.3	2.7	-	17	22	-	-		
		20	19	2.4	4	-	18	-	-	-		
			2.7	1	2.5	1	64	79	-	-		
	60	20	2.5	1	2.5	1	95	120	-	-		
			13	1.3	2.7	-	32	38	-	-		
			4	1.3	2.7	2	42	49	-	-		
			3.1	1.3	2.7	2	46	52	-	-		
			3	1.3	2.7	2	72	85	-	-		
			9	1.3	2.7	2	96	108	-	-		
			1.5	1.3	2.7	2	176	196	-	-		
			0.8	1.3	2.7	2	300	332	-	-		
	100	20	2.8	1.3	2.7	2	80	92	-	-		
			1.9	1.3	2.7	2	175	195	-	-		
			1.1	1.3	2.7	2	345	390	-	-		
	P-channel	12	12	11.8	0.47	0.9	-	-	15	17	21	
				5.6	0.45	0.95	2	-	27	38	50	
		20	8	2	0.5	1.1	-	-	100	155	210	
2.3				0.45	0.95	-	-	120	150	200		
12				10.3	0.47	0.9	2	-	19	22	28	
				5	0.47	0.9	2.3	-	28	31	36	
			5.3	0.75	1.25	2	-	28	42	-		
			5	0.47	0.9	2	-	39	45	56		
30			20	5.7	0.75	1.25	2	-	41	56	-	
				3.5	0.75	1.25	-	-	48	71	-	
		3.3		0.75	1.25	2	-	67	99	-		
		2.4		1	2.5	2	-	97	147	-		
40		20	8.8	1	2.5	-	24	32	-	-		
			4.2	1	3	2	35	47	-	-		
60		20	1.5	1	2.5	1	180	220	-	-		
			14	1.4	2.7	-	30	45	-	-		
60	20	8	1.9	3.2	-	95	125	-	-			

Types in **bold** represent new products

SOT223	SOT457 (SC-74)	SOT23	DFN2020MD-6 (SOT1220)	DFN2020D-6 (SOT1118D)	DFN1010D-3 (SOT1215)
					
6.5 x 3.5 x 1.65	2.9 x 1.5 x 1.0	2.9 x 1.3 x 1.0	2.0 x 2.0 x 0.65	2.0 x 2.0 x 0.65	1.1 x 1.0 x 0.37
1700	600	250	1250	1250	1000
		PMV28UNEA			
			PMPB10XNEA		
			PMPB12UNEA		
		PMV20XNEA	PMPB20XNEA		
			PMPB13XNEA		
			PMPB29XNEA		
				PMDPB56XNEA	
		PMV25ENEA			
		PMV50ENEA			
		PMV100ENEA			
			BUK9D23-40E		
			BUK6D23-40E		
			BUK7D25-40E		
		PMV65ENEA			
		PMV130ENEA			
			BUK6D43-60E		
			PMPB55ENEA		
		PMV55ENEA			
			PMPB85ENEA		
		PMV120ENEA			
		PMV230ENEA			
		PMV450ENEA			
			PMPB95ENEA		
			PMPB215ENEA		
					PMXB360ENEA
PMT280ENEA		PMV280ENEA			
PMT560ENEA					
			PMPB15XPA		
		PMV27UPEA			
		NX2301P			
		BSH205G2			
			PMPB20XPEA		
			PMPB29XPEA		
		PMV30XPEA			
			PMPB43XPEA		
	PMN42XPEA				
		PMV48XPA			
		PMV65XPEA			
		PMV100XPEA			
			PMPB27EPA		
		PMV50EPEA	PMPB50EPEA		
		PMV250EPEA			
			BUK6D43-40P		
			BUK6D120-60P		

Automotive MOSFETs


Small-signal automotive MOSFETs – High $R_{DS(on)}$





Package											
Size (mm)											
P_{tot} (mW)											
Polarity	V_{DS} (V)	V_{GS} (V)	I_D (A)	$V_{GS(th)}$ min (V)	$V_{GS(th)}$ max (V)	ESD protection (kV)	$R_{DS(on)}$ typ (m Ω) @ V_{GS} =				
							10 V	4.5 V	2.5 V	1.8 V	
N	30	8	0.4	0.6	1.1	2	-	1000	1400	2000	
			0.36	0.9	1.5	-	900	1000	-	-	
	60	20	0.36	0.48	1.6	1.5	1000	1100	1400	-	
			0.3	1	2.5	2	1000	1300	-	-	
			0.3	1	2.5	3	1100	1300	-	-	
			0.2	0.8	1.5	yes	2700	3000	4000	-	
P	30	8	0.23	0.6	1.1	2	-	2800	5300	-	
	50	20	0.2	1.1	2.1	1	5300	6000	-	-	



Small-signal automotive MOSFETs – Dual

Package											
Size (mm)											
P_{tot} (mW)											
Polarity	V_{DS} (V)	V_{GS} (V)	I_D (A)	$V_{GS(th)}$ min (V)	$V_{GS(th)}$ max (V)	ESD protection (kV)	$R_{DS(on)}$ typ (m Ω) @ V_{GS} =				
							10 V	4.5 V	2.5 V	1.8 V	
N	30	12	4	0.75	1.25	2	-	55	72	-	
N	20	8	0.73	0.5	0.95	2	-	290	420	600	
P			0.5	0.5	1.3	2	-	670	1200	1800	

Small-signal MOSFETs complementary

Package	Type	Polarity	V_{DS} (V)	V_{GS} (V)	I_D (A)	V_{GSth} min (V)	V_{GSth} max (V)	
SOT363 (SC-88) (2.0 x 1.25 x 0.95) 	NX3008CBKS	N	30	8	0.35	0.6	1.1	
		P	30	8	0.2	0.6	1.1	

SOT23	SOT363 (SC-88)	SOT323 (SC-70)	DFN1006 (SOT883)
			
2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.0 x 0.6 x 0.5
250	300	200	250
NX3008NBK	NX3008NBKS	NX3008NBKW	
BSS138P	BSS138PS	BSS138PW	
BSS138BK	BSS138BKS	BSS138BKW	
2N7002BK	2N7002BKS	2N7002BKW	2N7002BKM
2N7002CK			
BSS138AKA			
NX3008PBK	NX3008PBKS	NX3008PBKW	
BSS84AK	BSS84AKS	BSS84AKW	BSS84AKM

SOT363 (SC-88)	DFN2020D-6 (SOT1118D)
	
2.0 x 1.25 x 0.95	2.0 x 2.0 x 0.65
300	1250
	PMDPB56XNEA
PMGD290UCEA	

t _{on} typ (ns)	t _{off} typ (ns)	QG typ (nC)	ESD protection (kV)	R _{DS(on)} typ (mΩ) @ V _{GS} =					
				10 V	4.5 V	2.5 V	1.8 V	1.5 V	1.2 V
26	88	0.52	2	-	1000	1400	2000	-	-
49	103	0.55	2	-	2800	5300	-	-	-

AIRBAG

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Q100 Standard logic functions and packages

Analog switches

Type number	Description	Features					Package (suffix)								
		Configuration	V _{cc} (V)	R _{ON} (Ω)	R _{ON} (FLAT) (Ω)	T _{amb} (°C)	SOT108-1 (D)	SOT402-1 (PW)	SOT762-1 (BQ)	SOT109-1 (D)	SOT403-1 (PW)	SOT763-1 (BQ)	SOT137-1 (D)	SOT355-1 (PW)	SOT1815-1 (BQ)
74HC4051-Q100	Single-pole, octal-throw analog switch	SP8T-Z	2.0 - 10.0	200	20	-40~125				•	•	•			
74HCT4051-Q100	Single-pole, octal-throw analog switch; TTL-enabled	SP8T-Z	4.5 - 5.5	225	20	-40~125				•	•	•			
74HC4052-Q100	Dual single-pole, quad-throw analog switch	SP4T-Z	2.0 - 10.0	200	20	-40~125				•	•	•			
74HCT4052-Q100	Dual single-pole, quad-throw analog switch; TTL-enabled	SP4T-Z	4.5 - 5.5	200	20	-40~125				•	•	•			
74HC4053-Q100	Triple single-pole, double-throw analog switch	SP8T-Z	2.0 - 10.0	200	20	-40~125				•	•	•			
74HCT4053-Q100	Triple single-pole, double-throw analog switch; TTL-enabled	SP8T-Z	4.5 - 5.5	200	20	-40~125				•	•	•			
74HC4066-Q100	Quad single-pole, single-throw analog switch	SPST-NO	2.0 - 10.0	105	23	-40~125	•	•	•						
74HCT4066-Q100	Quad single-pole, single-throw analog switch; TTL-enabled	SPST-NO	4.5 - 5.5	118	23	-40~125	•	•	•						
74HC4067-Q100	Single-pole, 16-throw analog switch	SP16T-Z	2.0 - 10.0	200	25	-40~125							•	•	•
74HCT4067-Q100	Single-pole, 16-throw analog switch; TTL-enabled	SP16T-Z	4.5 - 5.5	225	25	-40~125							•	•	•
74HC4851-Q100	Single-pole, octal-throw analog switch	SP8T-Z	2.0 - 10.0	220	-	-40~125				•	•	•			
74HCT4851-Q100	Single-pole, octal-throw analog switch; TTL-enabled	SP8T-Z	4.5 - 5.5	240	-	-40~125				•	•	•			
74HC4852-Q100	Dual single-pole, quad-throw analog switch	SP4T-Z	2.0 - 10.0	220	-	-40~125				•	•	•			
74HCT4852-Q100	Dual single-pole, quad-throw analog switch; TTL-enabled	SP4T-Z	4.5 - 5.5	240	-	-40~125				•	•	•			
74LV4052-Q100	Dual single-pole, quad-throw analog switch	SP4T-Z	1.0 - 6.0	125	15	-40~125				•	•				
74LV4053-Q100	Triple single-pole, double-throw analog switch	SPDT-Z	1.0 - 6.0	150	30	-40~125				•	•	•			
74LVC4066-Q100	Quad single-pole, single-throw analog switch	SPST-NO	1.65 - 5.5	15	1.5	-40~125	•	•	•						
HEF4051B-Q100	Single-pole, octal-throw analog switch	SP8T-Z	3.0 - 15	175	30	-40~85				•	•				
HEF4052B-Q100	Dual single-pole, quad-throw analog switch	SP4T-Z	3.0 - 15	175	30	-40~85				•	•				
HEF4053B-Q100	Triple single-pole, double-throw analog switch	SPDT-Z	3.0 - 15	175	30	-40~85				•	•				
HEF4066B-Q100	Quad single-pole, single-throw analog switch	SPST-NO	3.0 - 15	175	20	-40~85	•								
HEF4067B-Q100	Single-pole, 16-throw analog switch	SP16T-Z	3.0 - 15	175	20	-40~85							•		

Buffers/Inverters

Type number	Description	Features				Package (suffix)								
		V _{cc} (V)	I _o (mA)	t _{pd} (ns)	T _{amb} (°C)	SOT108-1 (D)	SOT402-1 (PW)	SOT762-1 (BQ)	SOT109-1 (D)	SOT403-1 (PW)	SOT163-1 (D)	SOT360-1 (PW)	SOT764-1 (BQ)	SOT362-1 (DGG)
74AHC04-Q100	Hex inverter	2.0 - 5.5	± 8	3.0	-40~125	•	•	•						
74AHT04-Q100	Hex inverter; TTL-enabled	4.5 - 5.5	± 8	3.0	-40~125	•	•	•						
74AHC125-Q100	Quad buffer/line driver (3-state)	2.0 - 5.5	± 8	3.0	-40~125	•	•	•						
74AHT125-Q100	Quad buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 8	3.0	-40~125	•	•	•						
74AHC126-Q100	Quad buffer/line driver (3-state)	2.0 - 5.5	± 8	3.3	-40~125	•	•	•						
74AHT126-Q100	Quad buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 8	3.0	-40~125	•	•	•						
74AHC240-Q100	Octal inverter/line driver (3-state)	2.0 - 5.5	± 8	2.8	-40~125						•	•	•	
74AHT240-Q100	Octal inverter/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 8	3.0	-40~125						•	•	•	
74AHC244-Q100	Octal buffer/line driver (3-state)	2.0 - 5.5	± 8	3.5	-40~125						•	•	•	
74AHT244-Q100	Octal buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 8	3.5	-40~125						•	•	•	
74AHC541-Q100	Octal buffer/line driver (3-state)	2.0 - 5.5	± 8	3.5	-40~125						•	•	•	
74AHT541-Q100	Octal buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 8	3.5	-40~125						•	•	•	
74AHCU04-Q100	Hex inverter; unbuffered	2.0 - 5.5	± 8	2.4	-40~125	•	•	•						
74ALVC125-Q100	Quad buffer/line driver (3-state)	1.65 - 3.6	± 24	1.8	-40~85	•	•	•						
74ALVC541-Q100	Octal buffer/line driver (3-state)	1.65 - 3.6	± 24	2.3	-40~85						•	•	•	
74HC05-Q100	Hex inverter; open-drain	2.0 - 6.0	5.2	11	-40~125	•	•	•						
74HC04-Q100	Hex inverter	2.0 - 6.0	± 5.2	7.0	-40~125	•	•	•						
74HCT04-Q100	Hex inverter; TTL-enabled	4.5 - 5.5	± 4.0	8.0	-40~125	•	•	•						
74HC125-Q100	Quad buffer/line driver (3-state)	2.0 - 6.0	± 7.8	9.0	-40~125	•	•							
74HCT125-Q100	Quad buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 6	12	-40~125	•	•							
74HC126-Q100	Quad buffer/line driver (3-state)	2.0 - 6.0	± 7.8	9.0	-40~125	•	•							
74HCT126-Q100	Quad buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 6	11	-40~125	•	•							
74HC240-Q100	Octal inverter/line driver (3-state)	2.0 - 6.0	± 7.8	9.0	-40~125						•	•	•	
74HCT240-Q100	Octal inverter/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 6	9.0	-40~125						•	•	•	
74HC244-Q100	Octal buffer/line driver (3-state)	2.0 - 6.0	± 7.8	9.0	-40~125						•	•	•	
74HCT244-Q100	Octal buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 6	11	-40~125						•	•	•	
74HC365-Q100	Hex buffer/line driver (3-state)	2.0 - 6.0	± 7.8	9.0	-40~125				•	•				
74HCT365-Q100	Hex buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 6	11	-40~125				•	•				
74HC366-Q100	Hex inverter/line driver (3-state)	2.0 - 6.0	± 7.8	10	-40~125				•	•				
74HCT366-Q100	Hex inverter/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 6	11	-40~125				•	•				
74HC540-Q100	Octal inverter/line driver (3-state)	2.0 - 6.0	± 7.8	9.0	-40~125						•			
74HCT540-Q100	Octal inverter/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 6	11	-40~125						•			
74HC541-Q100	Octal buffer/line driver (3-state)	2.0 - 6.0	± 7.8	10	-40~125						•	•		

Buffers/Inverters

Type number	Description	Features				Package (suffix)								
		V_{CC} (V)	I_o (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT108-1 (D)	SOT402-1 (PW)	SOT762-1 (BQ)	SOT109-1 (D)	SOT403-1 (PW)	SOT163-1 (D)	SOT360-1 (PW)	SOT764-1 (BQ)	SOT362-1 (DGG)
74HCT541-Q100	Octal buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 6	12	-40~125						•	•		
74HCU04-Q100	Hex inverter; unbuffered	2.0 - 6.0	± 5.2	5.0	-40~125	•	•	•						
74LV244-Q100	Octal buffer/line driver (3-state)	1.0 - 5.5	± 16	8.0	-40~125						•	•		
74LVC04A-Q100	Hex inverter	1.65 - 5.5	± 24	2.0	-40~125	•	•	•						
74LVC06A-Q100	Hex inverter; open-drain	1.65 - 5.5	32	2.2	-40~125	•	•	•						
74LVC07A-Q100	Hex buffer; open-drain	1.65 - 5.5	32	2.2	-40~125	•	•	•						
74LVC125A-Q100	Quad buffer/line driver (3-state)	1.2 - 3.6	± 24	2.4	-40~125	•	•	•						
74LVC126A-Q100	Quad buffer/line driver (3-state)	1.2 - 3.6	± 24	2.4	-40~125	•	•	•						
74LVC541A-Q100	Octal buffer/line driver (3-state)	1.2 - 3.6	± 24	3.3	-40~125						•	•	•	
74LVC16240A-Q100	16-bit inverter/line driver (3-state)	1.2 - 3.6	± 24	2.7	-40~125									•
74LVC244A-Q100	Octal buffer/line driver (3-state)	1.2 - 3.6	± 24	2.8	-40~125						•	•	•	
74LVCH244A-Q100	Octal buffer/line driver with bus hold (3-state)	1.2 - 3.6	± 24	2.8	-40~125						•	•	•	
74LVC16244A-Q100	16-bit buffer/line driver (3-state)	1.2 - 3.6	± 24	3.0	-40~125									•
74LVCH16244A-Q100	16-bit buffer/line driver with bus hold (3-state)	1.2 - 3.6	± 24	3.0	-40~125									•
74LVCU04A-Q100	Hex inverter; unbuffered	1.2 - 3.6	± 24	2.0	-40~125	•	•							
74LVT04-Q100	Hex inverter	2.7 - 3.6	-20 / +32	2.6	-40~85	•	•							
74LVT244A-Q100	Octal buffer/line driver with bus hold (3-state)	2.7 - 3.6	-32 / +64	2.6	-40~85						•	•		
74LVTH244A-Q100	Octal buffer/line driver with bus hold (3-state)	2.7 - 3.6	-32 / +64	2.6	-40~85						•	•		
74VHC126-Q100	Quad buffer/line driver (3-state)	2.0 - 5.5	± 8	3.3	-40~125	•	•	•						
74VHCT126-Q100	Quad buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 8	3.0	-40~125	•	•	•						
74VHC541-Q100	Octal buffer/line driver (3-state)	2.0 - 5.5	± 8	3.5	-40~125						•	•	•	
74VHCT541-Q100	Octal buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 8	3.5	-40~125						•	•	•	
HEF4049B-Q100	Hex inverter/line driver	3.0 - 15.0	-3 / +20	20	-40~85				•					
HEF4050B-Q100	Hex buffer/line driver	3.0 - 15.0	-3 / +20	40	-40~85				•					
HEF4069UB-Q100	Hex inverter; unbuffered	3.0 - 15.0	± 3.4	15	-40~85	•	•							

Counters/Frequency dividers

Type number	Description	Features				Package (suffix)					
		V_{CC} (V)	I_o (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT108-1 (D)	SOT402-1 (PW)	SOT762-1 (BQ)	SOT109-1 (D)	SOT403-1 (PW)	SOT763-1 (BQ)
74HC161-Q100	Presetable synchronous 4-bit binary counter; asynchronous reset	2.0 - 6.0	± 5.2	19	-40~125				•	•	
74HC163-Q100	Presetable synchronous 4-bit binary counter; synchronous reset	2.0 - 6.0	± 5.2	17	-40~125				•	•	
74HCT163-Q100	Presetable synchronous 4-bit binary counter; synchronous reset; TTL-enabled	4.5 - 5.5	± 4.0	20	-40~125				•	•	
74HC193-Q100	Presetable synchronous 4-bit binary up/down counter	2.0 - 6.0	± 5.2	20	-40~125				•	•	
74HCT193-Q100	Presetable synchronous 4-bit binary up/down counter; TTL-enabled	4.5 - 5.5	± 4.0	20	-40~125				•	•	
74HC393-Q100	Dual 4-bit binary ripple counter	2.0 - 6.0	± 5.2	12	-40~125	•	•	•			
74HCT393-Q100	Dual 4-bit binary ripple counter; TTL-enabled	4.5 - 5.5	± 4.0	20	-40~125	•	•	•			
74HC4017-Q100	Johnson decade counter with 10 decoded outputs	2.0 - 6.0	± 5.2	18	-40~125				•	•	•
74HCT4017-Q100	Johnson decade counter with 10 decoded outputs; TTL-enabled	4.5 - 5.5	± 4.0	21	-40~125				•		•
74HC4020-Q100	14-stage binary ripple counter	2.0 - 6.0	± 5.2	11	-40~125				•	•	•
74HCT4020-Q100	14-stage binary ripple counter; TTL-enabled	4.5 - 5.5	± 4.0	15	-40~125				•	•	•
74HC4024-Q100	7-stage binary ripple counter	2.0 - 6.0	± 5.2	14	-40~125	•	•				
74HC4040-Q100	12-stage binary ripple counter	2.0 - 6.0	± 5.2	14	-40~125				•	•	•
74HCT4040-Q100	12-stage binary ripple counter; TTL-enabled	4.5 - 5.5	± 4.0	16	-40~125				•	•	•
74HC4060-Q100	14-stage binary ripple counter with oscillator	2.0 - 6.0	± 5.2	31	-40~125				•	•	•
74HCT4060-Q100	14-stage binary ripple counter with oscillator; TTL-enabled	4.5 - 5.5	± 4.0	31	-40~125				•		•
74HC4520-Q100	Dual 4-bit synchronous binary counter	2.0 - 6.0	± 5.2	24	-40~125				•		
74HCT4520-Q100	Dual 4-bit synchronous binary counter; TTL-enabled	4.5 - 5.5	± 4.0	24	-40~125				•		
74LV393-Q100	Dual 4-bit binary ripple counter	1.0 - 3.6	± 6	12	-40~125	•	•				
HEF4017B-Q100	5-stage Johnson decade counter	3.0 - 15	± 2.4	40	-40~85				•		
HEF4020B-Q100	14-stage binary ripple counter	3.0 - 15	± 2.4	30	-40~85				•		
HEF4040B-Q100	12-stage binary ripple counter	3.0 - 15	± 2.4	35	-40~85				•		
HEF4060B-Q100	14-stage binary ripple counter with oscillator	3.0 - 15	± 2.4	50	-40~85				•		
HEF4541B-Q100	Programmable timer	3.0 - 15	- 4/ + 2.7	38	-40~85	•					
HEF4520B-Q100	Dual 4-bit synchronous binary counter	3.0 - 15	± 2.4	15	-40~85				•		

Bus switches

Type number	Description	Features				Package (suffix)							
		V_{CC} (V)	V_{PASS} (V)	R_{ON} (Ω)	T_{amb} ($^{\circ}$ C)	SOT402-1 (PW)	SOT762-1 (BQ)	SOT109-1 (D)	SOT403-1 (PW)	SOT763-1 (BQ)	SOT163-1 (D)	SOT360-1 (PW)	SOT764-1 (BQ)
74CBTLV3125-Q100	Quad bus switch	2.3 - 3.6	3.3	7	-40~125	•							
74CBTLV3126-Q100	Quad bus switch	2.3 - 3.6	3.3	7	-40~125	•	•						
74CBTLV3253-Q100	Dual 4:1 mux/demux	2.3 - 3.6	3.3	7	-40~125			•	•	•			
74CBTLV3257-Q100	Quad 2:1 mux/demux	2.3 - 3.6	3.3	7	-40~125			•	•	•			
74CBTLV3245-Q100	Octal bus switch	2.3 - 3.6	3.3	7	-40~125							•	•
74CBTLVD3245-Q100	Octal bus switch level translator	3.0 - 3.6	1.8	7	-40~125							•	•
CBT3245A-Q100	Octal bus switch	4.5 - 5.5	3.9	7	-40~85						•	•	•

Digital decoders/Demultiplexers

Type number	Description	Features				Package (suffix)		
		V_{CC} (V)	I_o (mA)	t_{pd} (ns)	T_{amb} ($^{\circ}$ C)	SOT109-1 (D)	SOT403-1 (PW)	SOT763-1 (BQ)
74AHC138-Q100	3-to-8 line decoder/demultiplexer; inverting	2.0 - 5.5	± 8	4.4	-40~125	•	•	•
74AHCT138-Q100	3-to-8 line decoder/demultiplexer; inverting; TTL-enabled	4.5 - 5.5	± 8	4.4	-40~125	•	•	•
74AHC139-Q100	Dual 2-to-4 line decoder/demultiplexer	2.0 - 5.5	± 8	3.9	-40~125	•	•	
74AHCT139-Q100	Dual 2-to-4 line decoder/demultiplexer; TTL-enabled	4.5 - 5.5	± 8	3.6	-40~125	•	•	
74HC237-Q100	3-to-8 decoder/demultiplexer with address latches	2.0 - 6.0	± 5.2	18	-40~125	•		
74HC138-Q100	3-to-8 line decoder/demultiplexer; inverting	2.0 - 6.0	± 5.2	12	-40~125	•	•	•
74HCT138-Q100	3-to-8 line decoder/demultiplexer; inverting; TTL-enabled	4.5 - 5.5	± 4	19	-40~125	•	•	•
74HC139-Q100	Dual 2-to-4 line decoder/demultiplexer	2.0 - 6.0	± 5.2	14	-40~125	•	•	
74HCT139-Q100	Dual 2-to-4 line decoder/demultiplexer; TTL-enabled	4.5 - 5.5	± 4	16	-40~125	•	•	
74HC238-Q100	3-to-8 decoder/demultiplexer	2.0 - 6.0	± 5.2	14	-40~125	•	•	•
74HCT238-Q100	3-to-8 decoder/demultiplexer; TTL-enabled	4.5 - 5.5	± 4	18	-40~125	•	•	•
74LVC138A-Q100	3-to-8 line decoder/demultiplexer; inverting	1.2 - 3.6	± 24	2.7	-40~125	•	•	•
HEF4555B-Q100	Dual 1-to-4 line decoder/demultiplexer	3.0 - 15	± 2.4	30	-40~85	•		

Digital multiplexers

Type number	Description	Features				Package (suffix)		
		V_{CC} (V)	I_O (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT109-1 (D)	SOT403-1 (PW)	SOT763-1 (BQ)
74AHC157-Q100	Quad 2-input multiplexer	2.0 - 5.5	± 8	3.2	-40~125	•	•	•
74AHCT157-Q100	Quad 2-input multiplexer; TTL-enabled	4.5 - 5.5	± 8	3.2	-40~125	•	•	•
74AHC257-Q100	Quad 2-input multiplexer (3-State)	2.0 - 5.5	± 8	2.9	-40~125	•	•	
74AHCT257-Q100	Quad 2-input multiplexer; TTL-enabled (3-State)	4.5 - 5.5	± 8	3.7	-40~125	•	•	
74HC151-Q100	8-input multiplexer	2.0 - 6.0	± 5.2	17	-40~125	•	•	
74HCT151-Q100	8-input multiplexer; TTL-enabled	4.5 - 5.5	± 4	19	-40~125	•	•	
74HC153-Q100	Dual 4-input multiplexer	2.0 - 6.0	± 5.2	17	-40~125	•	•	
74HCT153-Q100	Dual 4-input multiplexer; TTL-enabled	4.5 - 5.5	± 4	19	-40~125	•	•	
74HC157-Q100	Quad 2-input multiplexer	2.0 - 6.0	± 5.2	11	-40~125	•	•	•
74HCT157-Q100	Quad 2-input multiplexer; TTL-enabled	4.5 - 5.5	± 4	13	-40~125	•	•	•
74HC251-Q100	8-input multiplexer (3-State)	2.0 - 6.0	± 5.2	18	-40~125	•	•	
74HCT251-Q100	8-input multiplexer; TTL-enabled (3-State)	4.5 - 5.5	± 4	22	-40~125	•	•	
74HC253-Q100	Dual 4-input multiplexer (3-State)	2.0 - 6.0	± 7.8	17	-40~125	•		
74HCT253-Q100	Dual 4-input multiplexer; TTL-enabled (3-State)	4.5 - 5.5	± 6	17	-40~125	•		
74HC257-Q100	Quad 2-input multiplexer (3-State)	2.0 - 6.0	± 7.8	11	-40~125	•	•	
74HCT257-Q100	Quad 2-input multiplexer; TTL-enabled (3-State)	4.5 - 5.5	± 6	13	-40~125	•	•	
74LVC157A-Q100	Quad 2-input multiplexer	1.2 - 3.6	± 24	2.5	-40~125	•	•	•

Flip-flops

Type number	Description	Features				Package (suffix)									
		V_{CC} (V)	I_O (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT108-1 (D)	SOT402-1 (PW)	SOT762-1 (BQ)	SOT109-1 (D)	SOT403-1 (PW)	SOT163-1 (D)	SOT360-1 (PW)	SOT764-1 (BQ)	SOT815-1 (BQ)	SOT362-1 (DGG)
74AHC74-Q100	Dual D-type flip-flop with set and reset; positive-edge trigger	2.0 - 5.5	± 8	3.7	-40~125	•	•	•							
74AHCT74-Q100	Dual D-type flip-flop with set and reset; positive-edge trigger; TTL-enabled	4.5 - 5.5	± 8	3.3	-40~125	•	•	•							
74AHC273-Q100	Octal D-type flip-flop with reset; positive-edge trigger	2.0 - 5.5	± 8	4.2	-40~125						•	•	•		
74AHCT273-Q100	Octal D-type flip-flop with reset; positive-edge trigger; TTL-enabled	4.5 - 5.5	± 8	4.0	-40~125						•	•	•		
74AHC374-Q100	Octal D-type flip-flop; positive-edge trigger	2.0 - 5.5	± 8	4.4	-40~125						•	•			
74AHCT374-Q100	Octal D-type flip-flop; positive-edge trigger (3-state); TTL-enabled (3-state)	4.5 - 5.5	± 8	4.3	-40~125						•	•			
74AHC377-Q100	Octal D-type flip-flop with data enable; positive-edge trigger	2.0 - 5.5	± 8	3.9	-40~125						•				
74AHCT377-Q100	Octal D-type flip-flop with data enable; positive-edge trigger; TTL-enabled	4.5 - 5.5	± 8	4.0	-40~125						•	•			
74AVC16374-Q100	16-bit D-type flip-flop; positive-edge trigger (3-state)	1.2 - 3.6	± 12	1.5	-40~85										•

Flip-flops

Type number	Description	Features				Package (suffix)									
		V _{cc} (V)	I _o (mA)	t _{pd} (ns)	T _{amb} (°C)	SOT108-1 (D)	SOT402-1 (PW)	SOT762-1 (BQ)	SOT109-1 (D)	SOT403-1 (PW)	SOT163-1 (D)	SOT360-1 (PW)	SOT764-1 (BQ)	SOT815-1 (BQ)	SOT362-1 (DGG)
74HC74-Q100	Dual D-type flip-flop with set and reset; positive-edge trigger	2.0 - 6.0	± 5.2	14	-40~125	•	•	•							
74HCT74-Q100	Dual D-type flip-flop with set and reset; positive-edge trigger; TTL-enabled	4.5 - 5.5	± 4	15	-40~125	•	•	•							
74HC107-Q100	Dual J-K flip-flop with reset; negative-edge trigger	2.0 - 6.0	± 5.2	16	-40~125	•	•								
74HCT107-Q100	Dual J-K flip-flop with reset; negative-edge trigger; TTL-enabled	4.5 - 5.5	± 4	16	-40~125	•									
74HC109-Q100	Dual J-K flip-flop with set and reset; positive-edge trigger	2.0 - 6.0	± 5.2	15	-40~125				•						
74HCT109-Q100	Dual J-K flip-flop with set and reset; positive-edge trigger; TTL-enabled	4.5 - 5.5	± 4	17	-40~125				•						
74HC174-Q100	Hex D-type flip-flop with reset; positive-edge trigger	2.0 - 6.0	± 5.2	17	-40~125				•	•					
74HCT174-Q100	Hex D-type flip-flop with reset; positive-edge trigger; TTL-enabled	4.5 - 5.5	± 4	18	-40~125				•	•					
74HC175-Q100	Quad D-type flip-flop with reset; positive-edge trigger	2.0 - 6.0	± 5.2	17	-40~125				•	•					
74HCT175-Q100	Quad D-type flip-flop with reset; positive-edge trigger; TTL-enabled	4.5 - 5.5	± 4	16	-40~125				•	•					
74HC273-Q100	Octal D-type flip-flop with reset; positive-edge trigger	2.0 - 6.0	± 5.2	15	-40~125						•	•	•		
74HCT273-Q100	Octal D-type flip-flop with reset; positive-edge trigger; TTL-enabled	4.5 - 5.5	± 4	15	-40~125						•	•	•		
74HC377-Q100	Octal D-type flip-flop with data enable; positive-edge trigger	2.0 - 6.0	± 7.8	13	-40~125						•	•			
74HCT377-Q100	Octal D-type flip-flop with data enable; positive-edge trigger; TTL-enabled	4.5 - 5.5	± 6	14	-40~125						•	•			
74HC574-Q100	Octal D-type flip-flop; positive-edge trigger (3-state)	2.0 - 6.0	± 7.8	14	-40~125						•	•			
74HCT574-Q100	Octal D-type flip-flop; positive-edge trigger; TTL-enabled (3-state)	4.5 - 5.5	± 6	15	-40~125						•	•			
74LV74-Q100	Dual D-type flip-flop with set and reset; positive-edge trigger	1.0 - 5.5	± 12	11	-40~125	•	•								
74LVC74A-Q100	Dual D-type flip-flop with set and reset; positive-edge trigger	1.2 - 3.6	± 24	2.5	-40~125	•	•	•							
74LVC273-Q100	Octal D-type flip-flop with reset; positive-edge trigger	1.2 - 3.6	± 24	6.0	-40~125						•	•	•		
74LVC374A-Q100	Octal D-type flip-flop; positive-edge trigger (3-state)	1.2 - 3.6	± 24	2.7	-40~125						•	•	•		

Flip-flops

Type number	Description	Features				Package (suffix)									
		V_{cc} (V)	I_o (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT108-1 (D)	SOT402-1 (PW)	SOT762-1 (BQ)	SOT109-1 (D)	SOT403-1 (PW)	SOT163-1 (D)	SOT360-1 (PW)	SOT764-1 (BQ)	SOT815-1 (BQ)	SOT362-1 (DGG)
74LVC573A-Q100	Octal D-type transparent latch (3-state)	1.2 - 3.6	± 24	3.4	-40~125						•	•	•		
74LVC823A-Q100	9-bit D-type flip-flop; positive-edge trigger (3-state)	1.2 - 3.6	± 24	5.4	-40~125									•	
74LVC16374A-Q100	16-bit D-type flip-flop; positive-edge trigger (3-state)	1.2 - 3.6	± 24	3.8	-40~125										•
74LVCH16374A-Q100	16-bit D-type flip-flop with bus hold; positive-edge trigger (3-state)	1.2 - 3.6	± 24	3.8	-40~125										•
HEF4013B-Q100	Dual D-type flip-flop with set and reset; positive-edge trigger	3.0 - 15	± 2.4	30	-40~85	•	•								
HEF4027B-Q100	Dual J-K flip-flop	3.0 - 15	± 2.4	30	-40~85				•						

Gates

Type number	Description	Features				Package (suffix)		
		V_{cc} (V)	I_o (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT108-1 (D)	SOT402-1 (PW)	SOT762-1 (BQ)
74AHC00-Q100	Quad 2-input NAND gate	2.0 - 5.5	± 8	3.2	-40~125	•	•	•
74AHCT00-Q100	Quad 2-input NAND gate; TTL-enabled	4.5 - 5.5	± 8	3.3	-40~125	•	•	•
74AHC02-Q100	Quad 2-input NOR gate	2.0 - 5.5	± 8	2.9	-40~125	•	•	•
74AHCT02-Q100	Quad 2-input NOR gate; TTL-enabled	4.5 - 5.5	± 8	3.8	-40~125	•	•	•
74AHC08-Q100	Quad 2-input AND gate	2.0 - 5.5	± 8	3.5	-40~125	•	•	•
74AHCT08-Q100	Quad 2-input AND gate; TTL-enabled	4.5 - 5.5	± 8	5.0	-40~125	•	•	•
74AHC30-Q100	8-input NAND gate	2.0 - 5.5	± 8	3.6	-40~125	•	•	•
74AHCT30-Q100	8-input NAND gate; TTL-enabled	4.5 - 5.5	± 8	3.3	-40~125	•	•	•
74AHC32-Q100	Quad 2-input OR gate	2.0 - 5.5	± 8	3.5	-40~125	•	•	•
74AHCT32-Q100	Quad 2-input OR gate; TTL-enabled	4.5 - 5.5	± 8	5.0	-40~125	•	•	•
74AHC86-Q100	Quad 2-input EXCLUSIVE-OR gate	2.0 - 5.5	± 8	3.4	-40~125	•	•	•
74AHCT86-Q100	Quad 2-input EXCLUSIVE-OR gate; TTL-enabled	4.5 - 5.5	± 8	3.4	-40~125	•	•	•
74ALVC00-Q100	Quad 2-input NAND gate	1.65 - 3.6	± 24	2.1	-40~85	•	•	•

Gates

Type number	Description	Features				Package (suffix)		
		V_{CC} (V)	I_o (mA)	t_{prop} (ns)	T_{amb} (°C)	SOT108-1 (D)	SOT402-1 (PW)	SOT762-1 (BQ)
74ALVC32-Q100	Quad 2-input OR gate	1.65 - 3.6	± 24	2.0	-40~125	•	•	•
74HC00-Q100	Quad 2-input NAND gate	2.0 - 6.0	± 5.2	7.0	-40~125	•	•	•
74HCT00-Q100	Quad 2-input NAND gate; TTL-enabled	4.5 - 5.5	± 4	10	-40~125	•	•	•
74HC02-Q100	Quad 2-input NOR gate	2.0 - 6.0	± 5.2	7.0	-40~125	•	•	•
74HCT02-Q100	Quad 2-input NOR gate; TTL-enabled	4.5 - 5.5	± 4	9.0	-40~125	•	•	•
74HC03-Q100	Quad 2-input NAND gate; open-drain	2.0 - 6.0	5.2	8.0	-40~125	•	•	
74HCT03-Q100	Quad 2-input NAND gate; open-drain; TTL-enabled	4.5 - 5.5	± 4	10	-40~125	•	•	
74HC08-Q100	Quad 2-input AND gate	2.0 - 6.0	± 5.2	7.0	-40~125	•	•	•
74HCT08-Q100	Quad 2-input AND gate; TTL-enabled	4.5 - 5.5	± 4	11	-40~125	•	•	•
74HC10-Q100	Triple 3-input NAND gate	2.0 - 6.0	± 5.2	9.0	-40~125	•	•	
74HCT10-Q100	Triple 3-input NAND gate; TTL-enabled	4.5 - 5.5	± 4	11	-40~125	•	•	
74HC11-Q100	Triple 3-input AND gate	2.0 - 6.0	± 5.2	10	-40~125	•	•	
74HCT11-Q100	Triple 3-input AND gate; TTL-enabled	4.5 - 5.5	± 4	11	-40~125	•	•	
74HC20-Q100	Dual 4-input NAND gate	2.0 - 6.0	± 5.2	8.0	-40~125	•	•	
74HCT20-Q100	Dual 4-input NAND gate; TTL-enabled	4.5 - 5.5	± 4	13	-40~125	•		•
74HC27-Q100	Triple 3-input NOR gate	2.0 - 6.0	± 5.2	8.0	-40~125	•	•	•
74HCT27-Q100	Triple 3-input NOR gate; TTL-enabled	4.5 - 5.5	± 4	10	-40~125	•	•	•
74HC30-Q100	8-input NAND gate	2.0 - 6.0	± 5.2	12	-40~125	•	•	
74HCT30-Q100	8-input NAND gate; TTL-enabled	4.5 - 5.5	± 4	12	-40~125	•	•	
74HC32-Q100	Quad 2-input OR gate	2.0 - 6.0	± 5.2	6.0	-40~125	•	•	•
74HCT32-Q100	Quad 2-input OR gate; TTL-enabled	4.5 - 5.5	± 4.0	9.0	-40~125	•	•	•
74HC86-Q100	Quad 2-input EXCLUSIVE-OR gate	2.0 - 6.0	± 5.2	11	-40~125	•	•	
74HCT86-Q100	Quad 2-input EXCLUSIVE-OR gate; TTL-enabled	4.5 - 5.5	± 4	14	-40~125	•	•	
74HC4002-Q100	Dual 4-input NOR gate	2.0 - 6.0	± 5.2	9.0	-40~125	•	•	
74HC4075-Q100	Triple 3-input OR gate	2.0 - 6.0	± 5.2	8.0	-40~125	•	•	
74HCT4075-Q100	Triple 3-input OR gate; TTL-enabled	4.5 - 5.5	± 4	10	-40~125	•	•	
74LV08-Q100	Quad 2-input AND gate	1.0 - 5.5	± 12	7.0	-40~125	•	•	
74LVC00A-Q100	Quad 2-input NAND gate	1.2 - 3.6	± 24	2.1	-40~125	•	•	•
74LVC02A-Q100	Quad 2-input NOR gate	1.2 - 3.6	± 24	2.1	-40~125	•	•	•
74LVC08A-Q100	Quad 2-input AND gate	1.2 - 3.6	± 24	2.1	-40~125	•	•	•
74LVC11-Q100	Triple 3-input AND gate	1.2 - 3.7	± 24	3.7	-40~125	•	•	
74LVC32A-Q100	Quad 2-input OR gate	1.2 - 3.6	± 24	2.1	-40~125	•	•	•
74VHC02-Q100	Quad 2-input NOR gate	2.0 - 5.5	± 8	2.9	-40~125	•	•	•
74VHCT02-Q100	Quad 2-input NOR gate; TTL-enabled	4.5 - 5.5	± 8	3.8	-40~125	•	•	•

Gates

Type number	Description	Features				Package (suffix)		
		V_{CC} (V)	I_o (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT108-1 (D)	SOT402-1 (PW)	SOT762-1 (BQ)
74VHCT08-Q100	Quad 2-input AND gate; TTL-enabled	4.5 - 5.5	± 8	5.0	-40~125	•	•	•
74VHC32-Q100	Quad 2-input OR gate	2.0 - 5.5	± 8	3.5	-40~125	•	•	
74VHCT32-Q100	Quad 2-input OR gate; TTL-enabled	4.5 - 5.5	± 8	5.0	-40~125	•	•	•
HEF4001B-Q100	Quad 2-input NOR gate	3.0 - 15	± 2.4	20	-40~85	•		
HEF4011B-Q100	Quad 2-input NAND gate	3.0 - 15	± 2.4	20	-40~85	•		
HEF4030B-Q100	Quad 2-input EXCLUSIVE-OR gate	3.0 - 15	± 2.4	30	-40~85	•		
HEF4070B-Q100	Quad 2-input EXCLUSIVE-OR gate	3.0 - 15	± 2.4	30	-40~85	•		
HEF4081B-Q100	Quad 2-input AND gate	3.0 - 15	± 2.4	20	-40~85	•		
HEF4082B-Q100	Dual 4-input AND gate	3.0 - 15	± 2.4	25	-40~85	•		

Latches/Registered drivers

Type number	Description	Features				Package (suffix)						
		V_{CC} (V)	I_o (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT109-1 (D)	SOT403-1 (PW)	SOT763-1 (BQ)	SOT163-1 (D)	SOT360-1 (PW)	SOT764-1 (BQ)	SOT362-1 (DGG)
74AHC573-Q100	Octal D-type transparent latch (3-state)	2.0 - 5.5	± 8	4.2	-40~125				•	•	•	
74AHCT573-Q100	Octal D-type transparent latch; TTL-enabled (3-state)	4.5 - 5.5	± 8	3.9	-40~125				•	•	•	
74HC259-Q100	8 bit addressable latch	2.0 - 6.0	± 5.2	18	-40~125	•	•	•				
74HCT259-Q100	8 bit addressable latch; TTL-enabled	4.5 - 5.5	± 4	20	-40~125	•	•	•				
74HC373-Q100	Octal D-type transparent latch (3-state)	2.0 - 6.0	± 7.8	12	-40~125				•	•	•	
74HCT373-Q100	Octal D-type transparent latch; TTL-enabled (3-state)	4.5 - 5.5	± 6	14	-40~125				•	•	•	
74HCS73-Q100	Octal D-type transparent latch (3-state)	2.0 - 6.0	± 7.8	14	-40~125				•	•	•	
74HCT573-Q100	Octal D-type transparent latch; TTL-enabled (3-state)	4.5 - 5.5	± 6	17	-40~125				•	•	•	
74LVC373A-Q100	Octal D-type transparent latch (3-state)	1.2 - 3.6	± 24	3.0	-40~125				•	•	•	
74LVC16373A-Q100	16-bit D-type transparent latch (3-state)	1.2 - 3.6	± 24	2.4	-40~125							•
74LVCH16373A-Q100	16-bit D-type transparent latch with bushold (3-state)	1.2 - 3.6	± 24	2.4	-40~125							•
HEF4043B-Q100	Quad R/S latch with set and reset (3-state)	3.0 - 15	± 2.4	25	-40~85	•						

Schmitt-triggers

Type number	Description	Features				Package (suffix)				
		V_{CC} (V)	I_o (mA)	t_{FHD} (ns)	T_{amb} (°C)	SOT108-1 (D)	SOT402-1 (PW)	SOT762-1 (BQ)	SOT163-1 (D)	SOT360-1 (PW)
74AHC14-Q100	Hex inverter Schmitt-trigger	2.0 - 5.5	± 8	3.2	-40~125	•	•	•		
74AHCT14-Q100	Hex inverter Schmitt-trigger; TTL-enabled	4.5 - 5.5	± 8	4.0	-40~125	•	•	•		
74AHC132-Q100	Quad 2-input NAND gate Schmitt-trigger	2.0 - 5.5	± 8	3.3	-40~125	•	•	•		
74AHCT132-Q100	Quad 2-input NAND gate Schmitt-trigger; TTL-enabled	4.5 - 5.5	± 8	3.5	-40~125	•	•	•		
74HC7014-Q100	Hex buffer precision Schmitt-trigger	2.0 - 6.0	± 5.2	27	-40~125	•				
74HC14-Q100	Hex inverter Schmitt-trigger	2.0 - 6.0	± 5.2	12	-40~125	•	•	•		
74HCT14-Q100	Hex inverter Schmitt-trigger; TTL-enabled	4.5 - 5.5	± 4	17	-40~125	•	•	•		
74HC132-Q100	Quad 2-input NAND gate Schmitt-trigger	2.0 - 6.0	± 5.2	11	-40~125	•	•	•		
74HCT132-Q100	Quad 2-input NAND gate Schmitt-trigger; TTL-enabled	4.5 - 5.5	± 4	17	-40~125	•	•	•		
74HC7541-Q100	Octal buffer/line driver Schmitt-trigger (3-State)	2.0 - 6.0	± 7.8	11	-40~125				•	•
74HCT7541-Q100	Octal buffer/line driver Schmitt-trigger; TTL-enabled (3-State)	4.5 - 5.5	± 6	16	-40~125				•	•
74LV132-Q100	Quad 2-input NAND gate Schmitt-trigger	1.0 - 5.5	± 12	10	-40~125	•	•	•		
74LVC14A-Q100	Hex inverter Schmitt-trigger	1.2 - 3.6	± 24	3.2	-40~125	•	•	•		
74LVC132A-Q100	Quad 2-input NAND gate Schmitt-trigger	1.2 - 3.6	± 24	3.4	-40~125	•	•	•		
HEF40106B-Q100	Hex inverter Schmitt-trigger	4.5 - 15.5	± 2.4	30	-40~85	•	•			

Shift registers

Type number	Description	Features				Package (suffix)							
		V _{CC} (V)	I _o (mA)	t _{psd} (ns)	T _{amb} (°C)	SOT108-1 (D)	SOT402-1 (PW)	SOT762-1 (BQ)	SOT109-1 (D)	SOT403-1 (PW)	SOT763-1 (BQ)	SOT163-1 (D)	SOT360-1 (PW)
74AHC164-Q100	8-bit serial-in/parallel-out shift register	2.0 - 5.5	± 8	4.5	-40~125	•	•	•					
74AHCT164-Q100	8-bit serial-in/parallel-out shift register; TTL-enabled	4.5 - 5.5	± 8	3.4	-40~125	•	•	•					
74AHC594-Q100	8-bit serial-in/parallel-out shift register with output register	2.0 - 5.5	± 8	4.1	-40~125				•	•	•		
74AHCT594-Q100	8-bit serial-in/parallel-out shift register with output register; TTL-enabled	4.5 - 5.5	± 8	3.8	-40~125				•	•	•		
74AHC595-Q100	8-bit serial-in/parallel-out shift register with output register (3-state)	2.0 - 5.5	± 8	4.0	-40~125				•	•	•		
74AHCT595-Q100	8-bit serial-in/parallel-out shift register with output storage; TTL-enabled (3-state)	4.5 - 5.5	± 8	3.8	-40~125				•	•	•		
74HC164-Q100	8-bit serial-in/parallel-out shift register	2.0 - 6.0	± 5.2	12	-40~125	•	•	•					
74HCT164-Q100	8-bit serial-in/parallel-out shift register; TTL-enabled	4.5 - 5.5	± 4	12	-40~125	•	•	•					
74HC165-Q100	8-bit parallel or serial-in/serial-out shift register	2.0 - 6.0	± 5.2	16	-40~125				•	•	•		
74HCT165-Q100	8-bit parallel or serial-in/serial-out shift register; TTL-enabled	4.5 - 5.5	± 4	14	-40~125				•	•	•		
74HC166-Q100	8-bit parallel or serial-in/serial-out shift register	2.0 - 6.0	± 5.2	15	-40~125				•	•			
74HCT166-Q100	8-bit parallel or serial-in/serial-out shift register; TTL-enabled	4.5 - 5.5	± 4	23	-40~125				•				
74HCS94-Q100	8-bit serial-in/parallel-out shift register with output storage register	2.0 - 6.0	± 7.8	14	-40~125			•					
74HCT594-Q100	8-bit serial-in/parallel-out shift register with output storage register; TTL-enabled	4.5 - 5.5	± 6	15	-40~125				•				
74HCS95-Q100	8-bit serial-in/parallel-out shift register with output storage register (3-state)	2.0 - 6.0	± 7.8	16	-40~125				•	•	•		
74HCT595-Q100	8-bit serial-in/parallel-out shift register with output storage register; TTL-enabled (3-state)	4.5 - 5.5	± 6	25	-40~125				•	•	•		
74HCS97-Q100	8-bit parallel or serial-in/parallel-out shift register with parallel input register	2.0 - 6.0	± 5.2	16	-40~125				•	•			
74HCT597-Q100	8-bit parallel or serial-in/parallel-out shift register with parallel input register; TTL-enabled	4.5 - 5.5	± 4	20	-40~125				•				
74HC4094-Q100	8-bit serial-in/serial or parallel-out shift register with output register (3-state)	2.0 - 6.0	± 5.2	15	-40~125				•	•			
74HCT4094-Q100	8-bit serial-in/serial or parallel-out shift register with output register; TTL-enabled (3-state)	4.5 - 5.5	± 4	19	-40~125				•				
74LV164-Q100	8-bit serial-in/parallel-out shift register	1.0 - 5.5	± 12	12	-40~125	•	•	•					
74LV165-Q100	8-bit parallel or serial-in/serial-out shift register	1.0 - 5.5	± 12	18	-40~125				•	•			
74LV165A-Q100	8-bit parallel or serial-in/serial-out shift register	1.0 - 5.5	± 12	7.5	-40~125				•	•			
74LV4060-Q100	14-stage binary ripple counter with oscillator	1.0 - 5.5	± 6	29	-40~125				•	•			
74LVC594A-Q100	8-bit serial-in/parallel-out shift register with output storage register	1.2 - 5.5	± 24	3.1	-40~125				•	•	•		

Shift registers

Type number	Description	Features				Package (suffix)							
		V _{cc} (V)	I _o (mA)	t _{pad} (ns)	T _{amb} (°C)	SOT108-1 (D)	SOT402-1 (PW)	SOT762-1 (BQ)	SOT109-1 (D)	SOT403-1 (PW)	SOT763-1 (BQ)	SOT163-1 (D)	SOT360-1 (PW)
74VHC595-Q100	8-bit serial-in/parallel-out shift register with output storage register (3-state)	2.0 - 5.5	± 8	4.0	-40~125				•	•	•		
74VHCT595-Q100	8-bit serial-in/parallel-out shift register with output storage register; TTL-enabled (3-state)	4.5 - 5.5	± 8	3.8	-40~125				•	•	•		
HEF4014B-Q100	8-bit shift register with synchronous parallel enable	3.0 - 15	± 2.4	40	-40~85				•				
HEF4021B-Q100	8-bit shift register with asynchronous parallel load	3.0 - 15	± 2.4	40	-40~85				•	•			
HEF4094B-Q100	8-bit serial-in/serial or parallel-out shift register with output register (3-state)	3.0 - 15	± 2.4	50	-40~85				•	•			
HEF4794B-Q100	8-bit serial-in/serial or parallel-out shift register with output register LED driver (3-state)	3.0 - 15	-20	45	-40~85				•				
HEF4894B-Q100	12-bit serial-in/serial or parallel-out shift register with output register LED driver (3-state)	3.0 - 15	-20	45	-40~85							•	•
NPIC6C595-Q100	8-bit serial-in/parallel-out shift register with output storage register (3-state)	4.5 - 5.5	-100	90	-40~125				•	•	•		
NPIC6C596-Q100	8-bit serial-in/serial or parallel-out shift register with output register LED driver (3-state)	4.5 - 5.5	-100	90	-40~125				•	•	•		
NPIC6C596A-Q100	8-bit serial-in/serial or parallel-out shift register with output register LED driver (3-state)	2.3 - 5.5	-100	90	-40~125				•	•	•		
NPIC6C4894-Q100	12-bit serial-in/serial or parallel-out shift register with output register LED driver (3-state)	3.5 - 15	-100	105	-40~125							•	•

Transceivers

Type number	Description	Features				Package (suffix)			
		V _{cc} (V)	I _o (mA)	t _{pad} (ns)	T _{amb} (°C)	SOT163-1 (D)	SOT360-1 (PW)	SOT764-1 (BQ)	SOT362-1 (DGG)
74AHC245-Q100	Octal transceiver (3-state)	2.0 - 5.5	± 8	3.5	-40~125	•	•	•	
74AHCT245-Q100	Octal transceiver; TTL-enabled (3-state)	4.5 - 5.5	± 8	5.0	-40~125	•	•	•	
74AVC16245-Q100	16-bit transceiver (3-state)	1.2 - 3.6	± 12	2.0	-40~85				•
74HC245-Q100	Octal transceiver (3-state)	2.0 - 6.0	± 7.8	7.0	-40~125	•	•	•	
74HCT245-Q100	Octal transceiver; TTL-enabled (3-state)	4.5 - 5.5	± 6	10	-40~125	•	•	•	
74LVC245A-Q100	Octal transceiver (3-state)	1.2 - 3.6	± 24	2.9	-40~125	•	•	•	
74LVCH245A-Q100	Octal transceiver with bus hold (3-state)	1.2 - 3.6	± 24	2.9	-40~125	•	•	•	
74LVC162245A-Q100	16-bit transceiver with 30 Ω termination resistors (3-state)	1.2 - 3.6	± 12	3.3	-40~125				•

Q100 mini logic functions and packages

Analog switches

Type number	Description	Features					Package (suffix)						
		Configuration	V _{CC} (V)	R _{ON} (Ω)	R _{ON} (FLAT) (Ω)	T _{amb} (°C)	SOT353-1 (GW)	SOT753 (GV)	SOT363 (GW)	SOT457 (GV)	SOT886 (GM)	SOT505-2 (DP)	SOT765-1 (DC)
74AHC1G66-Q100	Single-pole, single-throw analog switch	SPST-NO	2.0 - 5.5	40	5	-40~125	•	•					
74AHT1G66-Q100	Single-pole, single-throw analog switch; TTL-enabled	SPST-NO	4.5 - 5.5	40	5	-40~125	•	•					
74HC1G66-Q100	Single-pole, single-throw analog switch	SPST-NO	2.0 - 9.0	105	23	-40~125	•	•					
74HCT1G66-Q100	Single-pole, single-throw analog switch; TTL-enabled	SPST-NO	4.5 - 5.5	118	23	-40~125	•	•					
74HC2G66-Q100	Dual single-pole, single-throw analog switch	SPST-NO	2.0 - 9.0	105	23	-40~125						•	•
74HCT2G66-Q100	Dual single-pole, single-throw analog switch; TTL-enabled	SPST-NO	4.5 - 5.5	118	23	-40~125						•	•
74LVC1G53-Q100	Single-pole, double-throw analog switch	SPDT-Z	1.65 - 5.5	15	1.5	-40~125						•	•
74LVC1G66-Q100	Single-pole, single-throw analog switch	SPST-NO	1.65 - 5.5	15	1.5	-40~125	•	•					
74LVC1G384-Q100	Single-pole, single-throw analog switch	SPST-NC	1.65 - 5.5	15	1.5	-40~125	•	•					
74LVC1G3157-Q100	Single-pole, double-throw analog switch	SPDT	1.65 - 5.5	15	1.5	-40~125			•	•	•		
74LVC2G66-Q100	Dual single-pole, single-throw analog switch	SPST-NO	1.65 - 5.5	15	1.5	-40~125						•	•

Buffers/Inverters

Type number	Description	Features				Package (suffix)							
		V _{CC} (V)	I _O (mA)	t _{PLD} (ns)	T _{amb} (°C)	SOT353-1 (GW)	SOT753 (GV)	SOT363 (GM)	SOT457 (GV)	SOT886 (GM)	SOT1202 (GS)	SOT505-2 (DP)	SOT765-1 (DC)
74AHC1GU04-Q100	Single inverter; unbuffered	2.0 - 5.5	± 8	2.6	-40~125	•	•						
74AHC3GU04-Q100	Triple inverter; unbuffered	2.0 - 5.5	± 8	2.5	-40~125							•	•
74AHC1G04-Q100	Single inverter	2.0 - 5.5	± 8	3.1	-40~125	•	•						
74AHC1G04-Q100	Single inverter; TTL-enabled	4.5 - 5.5	± 8	3.4	-40~125	•	•						
74AHC1G07-Q100	Single buffer; open-drain	2.0 - 5.5	8	4.2	-40~125	•	•						
74AHC1G17-Q100	Single buffer with Schmitt-trigger inputs	2.0 - 5.5	± 8	3.2	-40~125	•							
74AHC1G17-Q100	Single buffer with Schmitt-trigger inputs; TTL-enabled	4.5 - 5.5	± 8	4.1	-40~125	•							
74AHC1G125-Q100	Single buffer/line driver (3-state)	2.0 - 5.5	± 8	3.4	-40~125	•	•						
74AHC1G125-Q100	Single buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 8	3.4	-40~125	•	•						
74AHC1G126-Q100	Single buffer/line driver (3-state)	2.0 - 5.5	± 8	3.4	-40~125	•	•						
74AHC1G126-Q100	Single buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 8	3.4	-40~125	•	•						
74AHC2G125-Q100	Dual buffer/line driver (3-state)	2.0 - 5.5	± 8	3.4	-40~125							•	•
74AHC2G125-Q100	Dual buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 8	3.4	-40~125							•	•
74AHC2G126-Q100	Dual buffer/line driver (3-state)	2.0 - 5.5	± 8	3.4	-40~125							•	•
74AHC2G126-Q100	Dual buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 8	3.4	-40~125							•	•
74AHC2G241-Q100	Dual buffer/line driver (3-state)	2.0 - 5.5	± 8	3.4	-40~125							•	•
74AHC2G241-Q100	Dual buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 8	3.4	-40~125							•	•
74AHC3G04-Q100	Triple inverter	2.0 - 5.5	± 8	3.1	-40~125							•	•
74AHC3G04-Q100	Triple inverter; TTL-enabled	4.5 - 5.5	± 8	3.0	-40~125							•	•
74AUP1G04-Q100	Single inverter	1.1 - 3.6	± 1.9	4.0	-40~125	•	•						
74AUP1G06-Q100	Single inverter; open-drain	1.1 - 3.6	1.9	4.5	-40~125	•							
74AUP1G34-Q100	Single buffer	1.1 - 3.6	± 1.9	3.9	-40~125	•							
74AUP1G125-Q100	Single buffer/line driver (3-state)	1.1 - 3.6	± 1.9	4.3	-40~125	•				•	•		
74AUP2G04-Q100	Dual inverter	1.1 - 3.6	± 1.9	4.0	-40~125			•					
74AUP2GU04-Q100	Dual inverter; unbuffered	1.1 - 3.6	± 1.9	2.3	-40~125			•		•			
74HC1GU04-Q100	Single inverter; unbuffered	2.0 - 6.0	± 2.6	5.0	-40~125	•	•						
74HC2GU04-Q100	Dual inverter; unbuffered	2.0 - 6.0	± 5.2	5.0	-40~125			•	•				
74HC3GU04-Q100	Triple inverter; unbuffered	2.0 - 6.0	± 5.2	6.0	-40~125							•	•
74HC1G04-Q100	Single inverter	2.0 - 6.0	± 2.6	7.0	-40~125	•	•						
74HCT1G04-Q100	Single inverter; TTL-enabled	4.5 - 5.5	± 2.0	8.0	-40~125	•	•						
74HC1G125-Q100	Single buffer/line driver (3-state)	2.0 - 6.0	± 2.6	9.0	-40~125	•	•						
74HCT1G125-Q100	Single buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 2.0	10	-40~125	•	•						

Buffers/Inverters

Type number	Description	Features				Package (suffix)							
		V _{cc} (V)	I _o (mA)	t _{pd} (ns)	T _{amb} (°C)	SOT353-1 (GW)	SOT753 (GV)	SOT363 (GW)	SOT457 (GV)	SOT886 (GM)	SOT1202 (GS)	SOT505-2 (DP)	SOT765-1 (DC)
74HC2G04-Q100	Dual inverter	2.0 - 6.0	± 5.2	8.0	-40~125			•	•				
74HCT2G04-Q100	Dual inverter; TTL-enabled	4.5 - 5.5	± 4.0	10	-40~125			•	•				
74HC2G34-Q100	Dual buffer	2.0 - 6.0	± 5.2	9.0	-40~125			•	•				
74HCT2G34-Q100	Dual buffer; TTL-enabled	4.5 - 5.5	± 4.0	10	-40~125			•	•				
74HC2G125-Q100	Dual buffer/line driver (3-state)	2.0 - 6.0	± 5.2	10	-40~125							•	•
74HCT2G125-Q100	Dual buffer/line driver; TTL-enabled (3-state)	4.5 - 5.5	± 4.0	12	-40~125							•	•
74HC3G04-Q100	Triple inverter	2.0 - 6.0	± 5.2	8.0	-40~125							•	•
74HCT3G04-Q100	Triple inverter; TTL-enabled	4.5 - 5.5	± 4.0	10	-40~125							•	•
74HC3G07-Q100	Triple buffer; open-drain	2.0 - 6.0	5.2	9.0	-40~125							•	•
74HCT3G07-Q100	Triple buffer; open-drain; TTL-enabled	4.5 - 5.5	4	9.0	-40~125							•	•
74HC3G34-Q100	Triple buffer	2.0 - 6.0	± 5.2	9.0	-40~125							•	•
74HCT3G34-Q100	Triple buffer; TTL-enabled	4.5 - 5.5	± 4.0	10	-40~125								•
74LVC1G04-Q100	Single inverter	1.65 - 5.5	± 32	2.0	-40~125	•	•						
74LVC1G06-Q100	Single inverter; open-drain	1.65 - 5.5	32	2.3	-40~125	•	•						
74LVC1G07-Q100	Single buffer; open-drain	1.65 - 5.5	32	2.2	-40~125	•	•				•		
74LVC1G34-Q100	Single buffer	1.65 - 5.5	± 32	2.0	-40~125	•	•						
74LVC1G125-Q100	Single buffer/line driver (3-state)	1.65 - 5.5	± 32	2.1	-40~125	•	•			•			
74LVC1G126-Q100	Single buffer/line driver (3-state)	1.65 - 5.5	± 32	2.0	-40~125	•	•						
74LVC1GU04-Q100	Single inverter; unbuffered	1.65 - 5.5	± 32	1.6	-40~125	•	•						
74LVC2G04-Q100	Dual inverter	1.65 - 5.5	± 32	2.7	-40~125			•	•		•		
74LVC2G06-Q100	Dual inverter; open-drain	1.65 - 5.5	32	2.3	-40~125			•	•				
74LVC2G07-Q100	Dual buffer; open-drain	1.65 - 5.5	32	2.6	-40~125			•	•				
74LVC2G125-Q100	Dual buffer/line driver (3-state)	1.65 - 5.5	± 32	2.3	-40~125							•	•
74LVC2G126-Q100	Dual buffer/line driver (3-state)	1.65 - 5.5	± 32	2.4	-40~125							•	•
74LVC2G240-Q100	Dual inverter/line driver (3-state)	1.65 - 5.5	± 32	2.5	-40~125							•	•
74LVC2G241-Q100	Dual buffer/line driver (3-state)	1.65 - 5.5	± 32	2.6	-40~125							•	•
74LVC2GU04-Q100	Dual inverter; unbuffered	1.65 - 5.5	± 32	2.3	-40~125			•	•	•			
74LVC3G04-Q100	Triple inverter	1.65 - 5.5	± 32	2.7	-40~125							•	•
74LVC3G07-Q100	Triple buffer; open-drain	1.65 - 5.5	32	2.1	-40~125							•	•
74LVC3G34-Q100	Triple buffer	1.65 - 5.5	± 32	2.2	-40~125							•	•

Digital decoders/Demultiplexers

Type number	Description	Features				Package (suffix)	
		V_{CC} (V)	I_o (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT363 (GW)	SOT457 (GV)
74LVC1G18-Q100	1-to-2 demultiplexer (3-state)	1.65 - 5.5	± 32	2.3	-40~125	•	•
74LVC1G19-Q100	1-to-2 demultiplexer	1.65 - 5.5	± 32	1.8	-40~125	•	

Digital multiplexers

Types in **bold** represent new products

Type number	Description	Features				Package (suffix)		
		V_{CC} (V)	I_o (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT363 (GW)	SOT457 (GV)	SOT886 (GM)
74AUP1G157-Q100	Low-power 2-input multiplexer	1.1 - 3.6	± 1.9	3.2	-40~125			•
74LVC1G157-Q100	Single 2-input multiplexer	1.65 - 5.5	± 32	2.2	-40~125	•	•	

Flip-flops

Type number	Description	Features				Package (suffix)						
		V_{CC} (V)	I_o (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT353-1 (GW)	SOT753 (GV)	SOT363 (GW)	SOT457 (GV)	SOT505-2 (DP)	SOT765-1 (DC)	SOT833-1 (GT)
74AHC1G79-Q100	Single D-type flip-flop; positive-edge trigger	2.0 - 5.5	± 8	3.5	-40~125	•	•					
74AHC1G79-Q100	Single D-type flip-flop; positive-edge trigger; TTL-enabled	4.5 - 5.5	± 8	3.5	-40~125	•	•					
74AUP1G74-Q100	Single D-type flip-flop with set and reset; positive-edge trigger	1.1 - 3.6	± 1.9	8.1	-40~125						•	
74AUP1G175-Q100	Single D flip-flop with reset; positive-edge trigger	1.1 - 3.6	± 1.9	7.4	-40~125			•				
74AUP1G374-Q100	Single D-type flip-flop; positive-edge trigger (3-state)	1.1 - 3.6	± 1.9	7.9	-40~125			•				
74AUP2G79-Q100	Dual D-type flip-flop; positive-edge trigger	1.1 - 3.6	± 1.9	8.5	-40~125						•	
74LVC1G74-Q100	Single D-type flip-flop with set and reset; positive-edge trigger	1.65 - 5.5	± 32	3.5	-40~125					•	•	•
74LVC1G79-Q100	Single D-type flip-flop; positive-edge trigger	1.65 - 5.5	± 32	2.2	-40~125	•	•					
74LVC1G80-Q100	Single D-type flip-flop; positive-edge trigger	1.65 - 5.5	± 32	2.4	-40~125	•	•					
74LVC1G175-Q100	Single D flip-flop with reset; positive-edge trigger	1.65 - 5.5	± 32	3.1	-40~125			•	•			
74LVC2G74-Q100	Single D-type flip-flop with set and reset; positive-edge trigger	1.65 - 5.5	± 32	3.5	-40~125					•	•	

Gates

Type number	Description	Features				Package (suffix)						
		V _{CC} (V)	I _O (mA)	t _{pd} (ns)	T _{amb} (°C)	SOT353-1 (GW)	SOT753 (GV)	SOT363 (GW)	SOT457 (GV)	SOT886 (GM)	SOT505-2 (DP)	SOT765-1 (DC)
74AHC1G09-Q100	Single 2-input AND gate; open-drain	2.0 - 5.5	± 8	3.2	-40~125	•	•					
74AHC1G00-Q100	Single 2-input NAND gate	2.0 - 5.5	± 8	3.5	-40~125	•	•					
74AHC1G00-Q100	Single 2-input NAND gate; TTL-enabled	4.5 - 5.5	± 8	3.6	-40~125	•	•					
74AHC1G02-Q100	Single 2-input NOR gate	2.0 - 5.5	± 8	3.2	-40~125	•	•					
74AHC1G02-Q100	Single 2-input NOR gate; TTL-enabled	4.5 - 5.5	± 8	3.5	-40~125	•	•					
74AHC1G08-Q100	Single 2-input AND gate	2.0 - 5.5	± 8	3.2	-40~125	•	•					
74AHC1G08-Q100	Single 2-input AND gate; TTL-enabled	4.5 - 5.5	± 8	3.6	-40~125	•	•					
74AHC1G32-Q100	Single 2-input OR gate	2.0 - 5.5	± 8	3.2	-40~125	•	•					
74AHC1G32-Q100	Single 2-input OR gate; TTL-enabled	4.5 - 5.5	± 8	3.3	-40~125	•	•					
74AHC1G86-Q100	2-input EXCLUSIVE-OR gate	2.0 - 5.5	± 8	3.4	-40~125	•	•					
74AHC1G86-Q100	2-input EXCLUSIVE-OR gate; TTL-enabled	4.5 - 5.5	± 8	3.5	-40~125	•	•					
74AHC2G00-Q100	Dual 2-input NAND gate	2.0 - 5.5	± 8	3.5	-40~125						•	•
74AHC2G00-Q100	Dual 2-input NAND gate; TTL-enabled	4.5 - 5.5	± 8	3.6	-40~125						•	•
74AHC2G08-Q100	Dual 2-input AND gate	2.0 - 5.5	± 8	3.2	-40~125						•	•
74AHC2G08-Q100	Dual 2-input AND gate; TTL-enabled	4.5 - 5.5	± 8	3.6	-40~125						•	•
74AHC2G32-Q100	Dual 2-input OR gate	2.0 - 5.5	± 8	3.2	-40~125						•	•
74AHC2G32-Q100	Dual 2-input OR gate; TTL-enabled	4.5 - 5.5	± 8	3.3	-40~125						•	•
74AUP1G02-Q100	Single 2-input NOR gate	1.1 - 3.6	± 1.9	8.2	-40~125	•						
74AUP1G08-Q100	Single 2-input AND gate	1.1 - 3.6	± 1.9	8.2	-40~125	•					•	
74AUP1G32-Q100	Single 2-input OR gate	1.1 - 3.6	± 1.9	7.9	-40~125	•					•	
74AUP1G86-Q100	Single 2-input EXCLUSIVE-OR gate	1.1 - 3.6	± 1.9	3.3	-40~125	•						
74AUP1T98-Q100	Configurable gate with voltage level translation	2.3 - 3.6 V	± 1.9	8.7	-40~125			•				
74HC1G86-Q100	Single 2-input EXCLUSIVE-OR gate	2.0 - 6.0	± 2.6	9.0	-40~125	•	•					
74HC1G00-Q100	Single 2-input NAND gate	2.0 - 6.0	± 2.6	7.0	-40~125	•						
74HCT1G00-Q100	Single 2-input NAND gate; TTL-enabled	4.5 - 5.5	± 2	10	-40~125	•	•					
74HC1G02-Q100	Single 2-input NOR gate	2.0 - 6.0	± 2.6	7.0	-40~125	•	•					
74HCT1G02-Q100	Single 2-input NOR gate; TTL-enabled	4.5 - 5.5	± 2.0	9.0	-40~125	•	•					
74HC1G08-Q100	Single 2-input AND gate	2.0 - 6.0	± 5.2	7.0	-40~125	•	•					
74HCT1G08-Q100	Single 2-input AND gate; TTL-enabled	4.5 - 5.5	± 2	11	-40~125	•	•					
74HC1G32-Q100	Single 2-input OR gate	2.0 - 6.0	± 2.6	8.0	-40~125	•	•					
74HCT1G32-Q100	Single 2-input OR gate; TTL-enabled	4.5 - 5.5	± 2.0	10	-40~125	•	•					
74HC2G00-Q100	Dual 2-input NAND gate	2.0 - 6.0	± 5.6	9.0	-40~125						•	•
74HCT2G00-Q100	Dual 2-input NAND gate; TTL-enabled	4.5 - 5.5	± 4	12	-40~125						•	•
74HC2G02-Q100	Dual 2-input NOR gate	2.0 - 6.0	± 5.2	9.0	-40~125						•	•
74HCT2G02-Q100	Dual 2-input NOR gate; TTL-enabled	4.5 - 5.5	± 4	12	-40~125						•	•
74HC2G08-Q100	Dual 2-input AND gate	2.0 - 6.0	± 5.2	9.0	-40~125						•	•

Gates

Type number	Description	Features				Package (suffix)							
		V_{CC} (V)	I_o (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT353-1 (GW)	SOT753 (GV)	SOT363 (GW)	SOT457 (GV)	SOT886 (GIM)	SOT505-2 (DP)	SOT765-1 (DC)	SOT1203 (GS)
74HCT2G08-Q100	Dual 2-Input AND gate; TTL-enabled	4.5 - 5.5	± 4	14	-40~125						•	•	
74HC2G32-Q100	Dual 2-input OR gate	2.0 - 6.0	± 5.2	9.0	-40~125						•	•	
74HCT2G32-Q100	Dual 2-input OR gate; TTL-enabled	4.5 - 5.5	± 4.0	13	-40~125						•	•	
74HC2G86-Q100	Dual 2-input EXCLUSIVE-OR gate	2.0 - 6.0	± 5.2	9.0	-40~125						•	•	
74HCT2G86-Q100	Dual 2-input EXCLUSIVE-OR gate; TTL-enabled	4.5 - 5.5	± 4.0	11	-40~125						•	•	
74HCT1G86-Q100	Single 2-input EXCLUSIVE-OR gate; TTL-enabled	4.5 - 5.5	± 2.0	10	-40~125	•	•						
74LVC1G00-Q100	Single 2-input NAND gate	1.65 - 5.5	± 32	2.2	-40~125	•	•						
74LVC1G02-Q100	Single 2-input NOR gate	1.65 - 5.5	± 32	2.1	-40~125	•	•						
74LVC1G08-Q100	Single 2-input AND gate	1.65 - 5.5	± 32	2.1	-40~125	•	•			•			
74LVC1G10-Q100	Single 3-input NAND gate	1.65 - 5.5	± 32	2.6	-40~125			•					
74LVC1G11-Q100	Single 3-input AND gate	1.65 - 5.5	± 32	2.6	-40~125			•	•				
74LVC1G32-Q100	Single 2-input OR gate	1.65 - 5.5	± 32	2.1	-40~125	•	•			•			
74LVC1G38-Q100	Single 2-input NAND gate; open-drain	1.65 - 5.5	32	2.3	-40~125	•	•						
74LVC1G57-Q100	Configurable gate; Schmitt-trigger	1.65 - 5.5	± 32	3.8	-40~125			•	•				
74LVC1G58-Q100	Configurable gate; Schmitt-trigger	1.65 - 5.5	± 32	3.8	-40~125			•	•				
74LVC1G86-Q100	Single 2-input EXCLUSIVE-OR gate	1.65 - 5.5	± 32	2.4	-40~125	•	•						
74LVC1G332-Q100	Single 3-input OR gate	1.65 - 5.5	± 32	2.6	-40~125			•	•				
74LVC1GX04-Q100	Crystal driver	1.65 - 5.5	± 24	2.8	-40~125			•	•				
74LVC2G00-Q100	Dual 2-input NAND gate	1.65 - 5.5	± 32	2.2	-40~125							•	
74LVC2G02-Q100	Dual 2-input NOR gate	1.65 - 5.5	± 32	2.4	-40~125						•	•	
74LVC2G08-Q100	Dual 2-input AND gate	1.65 - 5.5	± 24	2.1	-40~125						•	•	•
74LVC2G32-Q100	Dual 2-input OR gate	1.65 - 5.5	± 32	2.2	-40~125						•	•	
74LVC2G34-Q100	Dual buffer	1.65 - 5.5	± 32	2.2	-40~125			•	•	•			
74LVC2G86-Q100	Dual 2-input EXCLUSIVE-OR gate	1.65 - 5.5	± 32	2.3	-40~125						•	•	

Latches/Registered drivers

Type number	Description	Features				Package (suffix)
		V_{CC} (V)	I_o (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT363 (GW)
74AUP1G373-Q100	Single D-type transparent latch (3-state)	1.1 - 3.6	±1.9	8.5	-40~125	•

Multivibrators

Type number	Description	Features				Package (suffix)	
		V_{CC} (V)	I_o (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT505-2 (DP)	SOT765-1 (DC)
74LVC1G123-Q100	Single retriggerable monostable multivibrator	1.65 - 5.5	± 32	3.5	-40~125	•	•

Schmitt-triggers

Type number	Description	Features				Package (suffix)						
		V_{CC} (V)	I_o (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT353-1 (GW)	SOT753 (GV)	SOT363 (GW)	SOT457 (GV)	SOT886 (GM)	SOT505-2 (DP)	SOT765-1 (DC)
74AHC1G14-Q100	Single inverter Schmitt-trigger	2.0 - 5.5	± 8	3.2	-40~125	•	•					
74AHC1G14-Q100	Single inverter Schmitt-trigger; TTL-enabled	4.5 - 5.5	± 8	4.1	-40~125	•	•					
74AHC3G14-Q100	Triple inverter Schmitt-trigger	2.0 - 5.5	± 8	3.2	-40~125						•	•
74AHC3G14-Q100	Triple inverter Schmitt-trigger; TTL-enabled	4.5 - 5.5	± 8	4.1	-40~125						•	•
74HC1G14-Q100	Single inverter Schmitt-trigger	2.0 - 6.0	± 2.6	10	-40~125	•	•					
74HCT1G14-Q100	Single inverter Schmitt-trigger; TTL-enabled	4.5 - 5.5	± 2.0	15	-40~125	•	•					
74HC2G14-Q100	Dual inverter Schmitt-trigger	2.0 - 6.0	± 5.2	16	-40~125			•	•			
74HCT2G14-Q100	Dual inverter Schmitt-trigger; TTL-enabled	4.5 - 5.5	± 4.0	21	-40~125			•	•			
74HC2G17-Q100	Dual buffer Schmitt-trigger	2.0 - 6.0	± 5.2	12	-40~125			•	•			
74HCT2G17-Q100	Dual buffer Schmitt-trigger; TTL-enabled	4.5 - 5.5	± 4.0	21	-40~125			•	•			
74HC3G14-Q100	Triple inverter Schmitt-trigger	2.0 - 6.0	± 5.2	16	-40~125						•	•
74HCT3G14-Q100	Triple inverter Schmitt-trigger; TTL-enabled	4.5 - 5.5	± 4.0	21	-40~125						•	•
74LVC1G14-Q100	Single inverter Schmitt-trigger	1.65 - 5.5	± 32	3.0	-40~125	•	•			•		
74LVC1G17-Q100	Single buffer Schmitt-trigger	1.65 - 5.5	± 32	3.0	-40~125	•	•			•		
74LVC2G14-Q100	Dual inverter Schmitt-trigger	1.65 - 5.5	± 32	3.9	-40~125			•	•	•		
74LVC2G17-Q100	Dual buffer Schmitt-trigger	1.65 - 5.5	± 32	3.6	-40~125			•	•			
74LVC3G17-Q100	Triple buffer Schmitt-trigger	1.65 - 5.5	± 32	3.6	-40~125						•	•

Level shifters/Translators

Type number	Description	Features				Package (suffix)								
		V _{cc} (A) (V)	V _{cc} (B) (V)	I _o (mA)	T _{amb} (°C)	SOT353-1 (GW)	SOT363 (GW)	SOT886 (GM)	SOT1202 (GS)	SOT1505-2 (DP)	SOT765-1 (DC)	SOT1833-1 (GT)	SOT1203 (GS)	SOT552-1 (DP)
74AUP1T34-Q100	Single dual supply translating buffer	1.1 - 3.6	1.1 - 3.6	± 1.9	-40~125	•		•						
74AVC1T45-Q100	Single dual-supply voltage level translating transceiver (3-state)	0.8 - 3.6	0.8 - 3.6	± 12	-40~125		•		•					
74AVC2T45-Q100	Dual-bit dual-supply voltage level translating transceiver (3-state)	0.8 - 3.6	0.8 - 3.6	± 12	-40~125					•	•			
74AVCH1T45-Q100	Single dual-supply voltage translating transceiver with bus hold (3-state)	0.8 - 3.6	0.8 - 3.6	± 12	-40~125		•							
74AXP1T57-Q100	Dual-supply translating configurable multiple function gate, Schmitt-trigger inputs	0.7 - 2.75	1.2 - 5.5	± 12	-40~125						•			
74AXP2T08-Q100	Dual-supply 2-input AND gate	0.7 - 2.75	1.2 - 5.5	± 12	-40~125								•	
74LVC1T45-Q100	Single dual-supply voltage level translating transceiver (3-state)	1.2 - 5.5	1.2 - 5.5	± 24	-40~125		•							
74LVCH1T45-Q100	Single dual-supply voltage translating transceiver with bus hold (3-state)	1.2 - 5.5	1.2 - 5.5	± 24	-40~125		•							
74LVC2T45-Q100	Dual-bit dual-supply voltage level translating transceiver (3-state)	1.2 - 5.5	1.2 - 5.5	± 24	-40~125						•	•	•	
74LVCH2T45-Q100	Dual-bit dual-supply voltage level translating transceiver with bus hold (3-state)	1.2 - 5.5	1.2 - 5.5	± 24	-40~125						•			

Nomenclatures
standard logic functions

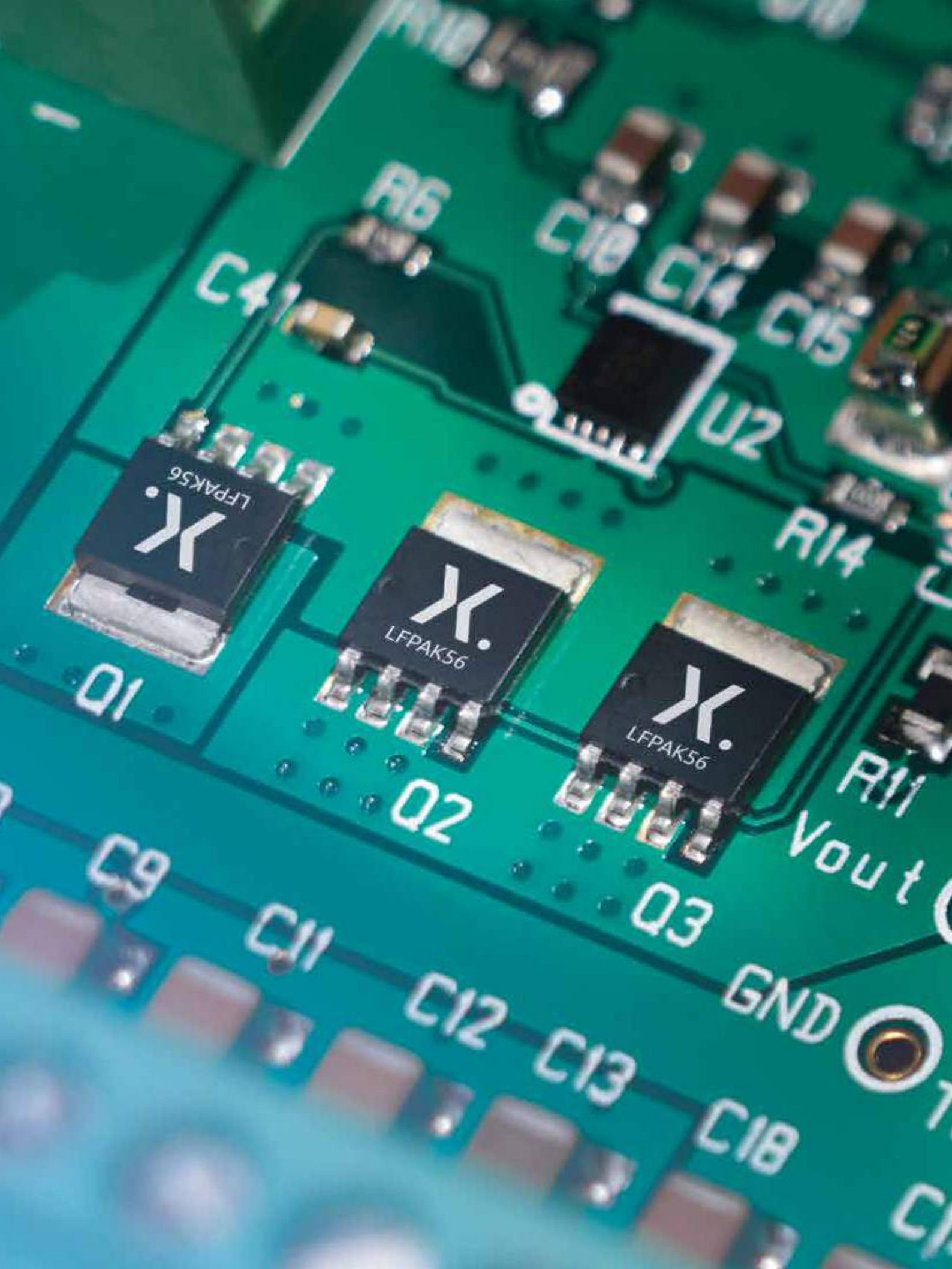
74 XXX XXX XXX

Logic family	Function number	Package type
AHC(T)	BQ	DQFN
ALVC	BX	DQFN
ALVT	D	SO
AUP	DB	SSOP
AVC(M)	DC	VSSOP
CBT(D)	DG	TSSOP
CBTLV(D)	DGG	TSSOP
HC(T)	DL	SSOP
HEF4000B	DP	TSSOP
LV	FC	BGA
LVC	EV	BGA
LVT	GU	DQFN
NPIC	P	TSSOP
VHC(T)	T	SO
XC7	TS	SSOP
	TT	TSSOP

Nomenclatures
mini logic functions

**74 XXX XG
XT XXX XXX**

Logic family	Gate format	Translator format	Function number	Package type
AHC(T)	1G Single-gate		DC	PicoGate
AUP	2G Dual-gate		DP	PicoGate
AVC(M)	3G Triple-gate		GD	MicroPak
AXP			GF	MicroPak
CBT(D)		Translator format	GM	MicroPak
CBTLV(D)			GN	MicroPak
HC(T)	1T Single-translator		GS	MicroPak
LVC	2T Dual-translator		GT	MicroPak
XC7	3T Triple-translator		GV	PicoGate
	4T Quad-translator		GW	PicoGate
			GX	MicroPak



K.
LFPAK56

K.
LFPAK56

K.
LFPAK56

Q1

Q2

Q3

Vout

GND

C4

R6

C10

C14

C15

U2

R14

R11

C9

C11

C12

C13

C18

C1

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Package cross reference list

Type	Competitor	Nexperia	Pins/Leads
μ8FL	ON Semi	LFPAK33 (SOT1210)	8
μQFN-10L	ST	DFN2510A-10 (SOT1176)	10
μQFN-2L	ST	DFN1006-2 (SOD882)	2
6 Lead DFN	ON Semi	DFN2020-6 (SOT1118)	6
CMAK/ CMPAK	Renesas	SOT323	3
CMPAK/ CMAK	Renesas	SOT323	3
CMPAK-5(T)	Renesas	SOT353	5
CMPAK-6	Renesas	SOT363	6
CP4	Toshiba	SOT143B	4
CS6	Toshiba	DFN1010-6 (SOT891)	6
CST3	Toshiba	DFN1006-3 (SOT883)	3
CST3	Toshiba	DFN1006B-3 (SOT883B)	3
CTS2 (FSC)	Toshiba	DFN1006-2 (SOD882)	2
CTS2 (FSC)	Toshiba	DFN1006D-2 (SOD882D)	2
D2PAK	Infineon	D2PAK (SOT404)	3
D2PAK	ON Semi	D2PAK (SOT404)	3
D2PAK	ST	D2PAK (SOT404)	3
D2PAK	Toshiba	D2PAK (SOT404)	3
D2PAK	Vishay	D2PAK (SOT404)	3
D2PAK 3	ON Semi	D2PAK (SOT404)	3
D2PAK*	Diodes Inc.	D2PAK (SOT404)	3
D2PAK-3	ON Semi	D2PAK (SOT404)	3
DFN1006-3	Diodes Inc.	DFN1006-3 (SOT883)	3
DFN1006H4-3	Diodes Inc.	DFN1006-3 (SOT883)	3
DFN1411*	Diodes Inc.	DFN1010D-3 (SOT1215)	3
DFN-5	ON Semi	LFPAK56 (SOT669)	4
DFN-8	ON Semi	LFPAK56D (SOT1205)	8
DSN2, 1.0 x 0.6	ON Semi	DFN1006D-2 (SOD882D)	2
DSN2, 1.6 x 0.8	ON Semi	DFN1608D-2 (SOD1608)	2
DSN2, 1.6 x 0.8	ON Semi	DFN1608D-2 (SOD1608)	2
EMD3/EMT3	Rohm	DFN1006-3 (SOT883)	3
EMT3	Rohm	DFN1006-3 (SOT883)	3
EMT3/EMD3	Rohm	DFN1006-3 (SOT883)	3
EMT3F*	Rohm	DFN1006-3 (SOT883)	3
ESM	Toshiba	DFN1006-3 (SOT883)	3
FM8	Toshiba	SOT96	8
FS6*	Toshiba	DFN1010B-6 (SOT1216)	6
H2PAK-2	ST	D2PAK (SOT404)	3
HSMT8	Rohm	LFPAK33 (SOT1210)	8
HSO8-8	Renesas	LFPAK56 (SOT669)	4
HSO8-8 Dual	Renesas	LFPAK56D (SOT1205)	8
HSOP8 (Dual)	Rohm	LFPAK56D (SOT1205)	8
HSOP8 (Single)	Rohm	LFPAK56 (SOT669)	4
HSOP8 (Single)	Rohm	LFPAK56E (SOT1023)	4
HUML2020L8 (Dual)	Rohm	DFN2020-6 (SOT1118)	6
HUML2020L8 (Single)	Rohm	DFN2020MD-6 (SOT1220)	6
I2PAK	ON Semi	I2PAK (SOT226)	3
I2PAK	ST	I2PAK (SOT226)	3

Type	Competitor	Nexperia	Pins/Leads
KMD2	Rohm	DFN1608D-2 (SOD1608)	2
LDBAK(S)-(1)	Renesas	D2PAK (SOT404)	3
LFPAK	Renesas	LFPAK56 (SOT669)	5
LFPAK56, HSON-8	Renesas	LFPAK56E (SOT1023)	4
LG A 1.0 x 0.6mm	Texas Instruments	DFN1006B-3 (SOT883B)	3
LLP1006-2L	Vishay	DFN1006-2 (SOD882)	2
LLP1006-2L	Vishay	DFN1006D-2 (SOD882D)	2
LLP1006-2M	Vishay	DFN1006-2 (SOD882)	2
LLP1006-2M	Vishay	DFN1006D-2 (SOD882D)	2
LLP75-7L	Vishay	DFN1616-6 (SOT1189)	6
LPDS/LPTS	Rohm	D2PAK (SOT404)	3
LPTS	Rohm	D2PAK (SOT404)	3
LPTS/LPDS	Rohm	D2PAK (SOT404)	3
M-Flat	Toshiba	SOD128	2
Micro 3	Int. Rectifier	SOT23	3
Micro 6	Int. Rectifier	SOT457	6
MICRO FOOT 0.8 x 0.8*	Vishay	DFN1010D-3 (SOT1215)	3
MICRO FOOT 1 x 1*	Vishay	DFN1010D-3 (SOT1215)	3
MICRO FOOT 1 x 1.2*	Vishay	DFN1010D-3 (SOT1215)	3
MICRO FOOT 1 x 1.5*	Vishay	DFN1010D-3 (SOT1215)	3
MICRO FOOT 1.6 x 1.6*	Vishay	DFN2020MD-6 (SOT1220)	6
MICRO FOOT*	Vishay	DFN2020MD-6 (SOT1220)	6
MicroFET	Fairchild	DFN2020MD-6 (SOT1220)	6
MicroFET 1.6 x 1.6*	Fairchild	DFN2020MD-6 (SOT1220)	6
MP-25(K)	Renesas	TO-220 (SOT78)	3
MP-25SK	Renesas	I2PAK (SOT226)	3
MP-25ZT	Renesas	D2PAK (SOT404)	3
MPAK	Renesas	SOT23	3
MPAK	Renesas	SOT23	3
MPAK-4R	Renesas	SOT143B	4
MPT3	Rohm	SOT89	3
PG-TD SON-8	Infineon	LFPAK56 (SOT669)	5
PG-TD- SON-8	Infineon	LFPAK56E (SOT1023)	4
PG-TDSON-8	Infineon	LFPAK56D (SOT1205)	8
PG-TDSON-8	Infineon	LFPAK56 (SOT669)	4
PG-TO220-3	Infineon	TO-220 (SOT78)	3
PG-TO262-3	Infineon	I2PAK (SOT226)	3
PG-TO263-3	Infineon	D2PAK (SOT404)	3
PG-TSDSON-8	Infineon	LFPAK33 (SOT1210)	8
PMDT	Rohm	SOD128	2
PMDU	Rohm	SOD123W	2
Power DI3333-8	Diodes Inc.	LFPAK33 (SOT1210)	8
Power DI5060-8	Diodes Inc.	LFPAK56D (SOT1205)	8
Power DI5060-8	Diodes Inc.	LFPAK56 (SOT669)	4
Power- DI5060-8	Diodes Inc.	LFPAK56E (SOT1023)	4
PowerFLAT (6x5)	ST	LFPAK56E (SOT1023)	4
PowerFLAT 3.3 x 3.3	ST	LFPAK33 (SOT1210)	8
PowerFLAT 5x6 Dual	ST	LFPAK56D (SOT1205)	8

Types with * show footprint compatibility only

Package cross reference list

Type	Competitor	Nexperia	Pins/Leads
PowerFLAT 5x6 Dual	ST	LFPAK56 (SOT669)	4
PowerDI123	Diodes Inc.	SOD123F	2
PowerDI123	Diodes Inc.	SOD123W	2
PowerDI323	Diodes Inc.	SOD323F	2
PowerDI5	Diodes Inc.	CFP15 (SOT1289)	3
PowerFLAT (6 x 5)	ST	LFPAK56 (SOT669)	5
PowerFLAT (6 x 5)	ST	LFPAK56D (SOT1205)	5
PowerPAK 1212-8	Vishay	LFPAK33 (SOT1210)	8
PowerPAK 8x8L	Vishay	LFPAK88 (SOT1235)	4
PowerPAK SC-70	Vishay	DFN2020-6 (SOT1118)	6
PowerPAK SC-70	Vishay	DFN2020MD-6 (SOT1220)	6
PowerPAK SC706L	Vishay	DFN2020-3 (SOT1061)	3
PowerPAK SC-70-6L	Vishay	DFN2020-6 (SOT1118)	6
PowerPAK SC-75*	Vishay	DFN2020MD-6 (SOT1220)	6
PowerPAK SC-75-6L*	Vishay	DFN2020MD-6 (SOT1220)	6
PowerPAK SO-8	Vishay	LFPAK56 (SOT669)	5
PowerPAK SO-8(L)	Vishay	LFPAK56 (SOT669)	4
PowerPAK SO-8(L)	Vishay	LFPAK56E (SOT1023)	4
PowerPAK SO-8L Dual	Vishay	LFPAK56D (SOT1205)	8
PW-Mini	Toshiba	SOT89	3
S08	Vishay	SOT96	8
SC59	Diodes Inc.	SOT23	3
SC70	ON Semi	SOT323	3
SC-70	ON Semi	SOT323	3
SC-70, 3 leads	Vishay	SOT323	3
SC70-3	AOS	SOT323	3
SC70-3	Vishay	SOT323	3
SC70-5L	Semtech	SOT353	5
SC70-6	AOS	SOT363	6
SC70-6	Fairchild	SOT363	6
SC70-6	Vishay	SOT363	6
SC70-6L	Semtech	SOT363	6
SC74 TSOP6	Infineon	SOT457	6
SC-74 TSOP-6	ON Semi	SOT457	6
SC75	Infineon	DFN1006-3 (SOT883)	3
SC75	ON Semi	DFN1006-3 (SOT883)	3
SC-75	ON Semi	DFN1006-3 (SOT883)	3
SC-75	Semtech	DFN1006-3 (SOT883)	3
SC75A	Vishay	DFN1006-3 (SOT883)	3
SC-75A	Vishay	DFN1006-3 (SOT883)	3
SC-88	ON Semi	SOT363	6
SC88/SC 7 0-6/SOT 363 6 LEAD	ON Semi	SOT363	6
SC-88A	ON Semi	SOT353	5
SC89-3	Fairchild	DFN1006-3 (SOT883)	3
SC89-3	ON Semi	DFN1006-3 (SOT883)	3
SC89-3	Vishay	DFN1006-3 (SOT883)	3
S-Flat	Toshiba	SOD123F	2

Type	Competitor	Nexperia	Pins/Leads
S-Flat	Toshiba	SOD123W	2
SLP1006P2	Semtech	DFN1006-2 (SOD882)	2
SLP1006P2T	Semtech	DFN1006D-2 (SOD882D)	2
SLP1006P3	Semtech	DFN1006-3 (SOT883)	3
SLP1006P3T	Semtech	DFN1006B-3 (SOT883B)	3
SLP1510N6	Semtech	DFN1410-6 (SOT886)	6
SLP1610N2	Semtech	DFN1608D-2 (SOD1608)	2
SLP1610P4	Semtech	DFN2510A-10 (SOT1176)	10
SLP1616P6	Semtech	DFN1616-6 (SOT1189)	6
SLP1713P8	Semtech	DFN1714-8 (SOT1166)	8
SLP1713P8	Semtech	DFN1714U-8 (SOT983)	8
SLP2513P12	Semtech	DFN2514-12 (SOT1167)	12
SLP3313P16	Semtech	DFN3314-16 (SOT1168)	16
SM6 VS-6	Toshiba	SOT457	6
SMA flat	ST	SOD128	2
SMD TO-263	Renesas	D2PAK (SOT404)	3
SMD6/SMT6	Rohm	SOT457	6
SMD6/SMZ6	Rohm	SOT457	6
S-Mini	Toshiba	SOT23	3
S-Mini TSM	Toshiba	SOT23	3
SMPAK	Renesas	DFN1006-3 (SOT883)	3
SMPC TO-277A	Vishay	CFP15 (SOT1289)	3
SMT3	Rohm	SOT23	3
SMT5*	Rohm	SOT457	6
SMT6	Rohm	SOT457	6
SMZ6/SMD6	Rohm	SOT457	6
SO-8 FL	ON Semi	LFPAK56 (SOT669)	5
SO-8 FL, DFN-5	ON Semi	LFPAK56E (SOT1023)	4
SO-8FL Dual	ON Semi	LFPAK56D (SOT1205)	8
SO-8FL Dual	ON Semi	LFPAK56 (SOT669)	4
SOD-123	ST	SOD123F	2
SOD-123-FL	ON Semi	SOD123F	2
SOD-123-FL	ON Semi	SOD123W	2
SOD323	Infineon	SOD323	2
SOD323	Semtech	SOD323	2
SOD323	Vishay	SOD323	2
SOD-323	Diodes Inc.	SOD323	2
SOD-323	ON Semi	SOD323	2
SOD-323	ST	SOD323	2
SOD882	ST	DFN1006-2 (SOD882)	2
SOD882T	ST	DFN1006D-2 (SOD882D)	2
SOD923-2*	ON Semi	DFN1006-2 (SOD882)	2
SOIC-8 NB	ON Semi	SOT96	8
SON 2x2	Texas Instruments	DFN2020MD-6 (SOT1220)	6
SON 3x3*	Texas Instruments	DFN2020MD-6 (SOT1220)	6
SOP / DSOP Advance	Toshiba	LFPAK56E (SOT1023)	4
SOP / DSOP Advance	Toshiba	LFPAK56 (SOT669)	4
SOP8	Rohm	SOT96	8

Types with * show footprint compatibility only

Package cross reference list

Type	Competitor	Nexperia	Pins/Leads
SOP-8	Renesas	SOT96	8
SOT 143	Infineon	SOT143B	4
SOT063*	ON Semi	DFN1010B-6 (SOT1216)	6
SOT-143	Diodes Inc.	SOT143B	4
SOT-143	Semtech	SOT143B	4
SOT223	Diodes Inc.	SOT223	4
SOT223	Fairchild	SOT223	4
SOT223	Infineon	SOT223	4
SOT223	ON Semi	SOT223	4
SOT223	Vishay	SOT223	4
SOT-223	Diodes Inc.	SOT223	4
SOT-223	Infineon	SOT223	4
SOT-223	ON Semi	SOT223	4
SOT-223	ON Semi	SOT223	4
SOT-223	ST	SOT223	4
SOT23	AOS	SOT23	3
SOT23	Diodes Inc.	SOT23	3
SOT23	Infineon	SOT23	3
SOT23	ON Semi	SOT23	3
SOT23	Semtech	SOT23	3
SOT23	ST	SOT23	3
SOT23	Vishay	SOT23	3
SOT-23	Diodes Inc.	SOT23	3
SOT-23	ON Semi	SOT23	3
SOT23-3	AOS	SOT23	3
SOT23-3	Diodes Inc.	SOT23	3
SOT23-3	ON Semi	SOT23	3
SOT23-5	AOS	SOT457	6
SOT23-5	Diodes Inc.	SOT457	6
SOT23-6	Diodes Inc.	SOT457	6
SOT23-6	Diodes Inc.	SOT457	6
SOT23-6	ST	SOT457	6
SOT23-6L	Semtech	SOT457	6
SOT23F	Diodes Inc.	SOT23	3
SOT23F	Toshiba	SOT23	3
SOT26	Diodes Inc.	SOT457	6
SOT323	Diodes Inc.	SOT323	3
SOT323	Fairchild	SOT323	3
SOT323	Infineon	SOT323	3
SOT-323	Diodes Inc.	SOT323	3
SOT-323	ST	SOT323	3
SOT353	Diodes Inc.	SOT353	5
SOT353	Diodes Inc.	SOT363	6
SOT353	Vishay	SOT353	5
SOT363	Diodes Inc.	SOT363	6
SOT363	Infineon	SOT363	6
SOT-363	Diodes Inc.	SOT363	6
SOT523	Diodes Inc.	DFN1006-3 (SOT883)	3

Type	Competitor	Nexperia	Pins/Leads
SOT523F	Fairchild	DFN1006-3 (SOT883)	3
SOT723*	ON Semi	DFN1010D-3 (SOT1215)	3
SOT723-3*	ON Semi	DFN1010D-3 (SOT1215)	3
SOT89	Diodes Inc.	SOT89	3
SOT89	Infineon	SOT89	3
SOT-89	ON Semi	SOT89	3
SOT89-3L	Diodes Inc.	SOT89	3
SOT963	ON Semi	DFN1010-6 (SOT891)	6
SOT963*	Diodes Inc.	DFN1010B-6 (SOT1216)	6
SRP-F	Renesas	SOD123W	2
SS CSP2	Toshiba	DFN1006-3 (SOT883)	3
SSD3/SST3	Rohm	SOT23	3
SSM	Toshiba	DFN1006-3 (SOT883)	3
SSOT3	Fairchild	SOT23	3
SSOT6	Fairchild	SOT457	6
SSOT6 FLMP	Fairchild	SOT457	6
SST3	Rohm	SOT23	3
SST3/SSD3	Rohm	SOT23	3
Stmite flat	ST	SOD123W	2
T0263	Diodes Inc.	D2PAK(SOT404)	3
T0263-3	Infineon	D2PAK (SOT404)	3
Thin PowerPAK SC70	Vishay	DFN2020MD-6 (SOT1220)	6
Thin PowerPAK SC-70	Vishay	DFN2020-6 (SOT1118)	6
Thin PowerPAK SC75*	Vishay	DFN2020MD-6 (SOT1220)	6
TO220	Infineon	TO-220 (SOT78)	3
TO-220	ST	TO-220 (SOT78)	3
TO-220	Toshiba	TO-220 (SOT78)	3
TO-220	Vishay	TO-220 (SOT78)	3
TO220-3	Diodes Inc.	TO-220 (SOT78)	3
TO-220-3	ON Semi	TO-220 (SOT78)	3
TO-220-3L	ON Semi	TO-220 (SOT78)	3
TO-220AB	Vishay	TO-220 (SOT78)	3
TO-220F-3FS	ON Semi	TO-220 (SOT78)	3
TO-220FM	Rohm	TO-220 (SOT78)	3
TO-220S	Renesas	D2PAK (SOT404)	3
TO-220SM	Toshiba	D2PAK (SOT404)	3
TO262	Infineon	I2PAK (SOT226)	3
TO-262	Renesas	I2PAK (SOT226)	3
TO-262	Vishay	I2PAK (SOT226)	3
TO-262-2L	ON Semi	I2PAK (SOT226)	3
TO-262-3L	ON Semi	I2PAK (SOT226)	3
TO263	Diodes Inc.	D2PAK (SOT404)	3
TO-263	Renesas	D2PAK-7 (SOT427)	7
TO-263	Renesas	D2PAK (SOT404)	3
TO-263	Vishay	D2PAK (SOT404)	3
TO-263 3-lead	Vishay	D2PAK (SOT404)	3
TO-263-2L	ON Semi	D2PAK (SOT404)	3
TO-263AB	Vishay	D2PAK (SOT404)	3

Types with * show footprint compatibility only

Package cross reference list

Type	Competitor	Nexperia	Pins/Leads
To-LL	Infineon	LFPK88 (SOT1235)	4
To-LL	ON Semi	LFPK88 (SOT1235)	4
TSLP-2-1	Infineon	DFN1006-2 (SOD882)	2
TSLP-2-7/-17	Infineon	DFN1006D-2 (SOD882D)	2
TSLP-3-1, -15	Infineon	DFN1006B-3 (SOT883B)	3
TSLP-3-4	Infineon	DFN1006-3 (SOT883)	3
TSLP-9-1	Infineon	DFN2510A-10 (SOT 1176)	10
TSMT5*	Rohm	SOT457	6
TSMT6	Rohm	SOT457	6
TSNP-2-2	Infineon	DFN1608D-2 (SOD 1608)	2
TSON Advance	Toshiba	LFPK33 (SOT1210)	8
TSOP6	AOS	SOT457	6
TSOP6	ON Semi	SOT457	6
TSOP6	Vishay	SOT457	6
TSOP-6	Renesas	SOT457	6
TSOP-6/ TSOP6	Vishay	SOT457	6
TSST8*	Rohm	DFN2020MD-6 (SOT1220)	6
TUMT3	Rohm	SOT323	3
TUMT5*	Rohm	DFN2020-6 (SOT1118)	6
TUMT6*	Rohm	DFN2020-6 (SOT1118)	6
UDFN 1.6 x 1.6	ON Semi	DFN1616-6 (SOT1189)	6
UDFN 1.7 x 1.35, 0.4P	ON Semi	DFN1714U-8 (SOT983)	8
UDFN10 2.5 x 1, 0.5P	ON Semi	DFN2510A-10 (SOT1176)	10
UDFN12 2.5 x 1.35, 0.4P	ON Semi	DFN2514-12 (SOT1167)	12
U-DFN2020-3 Type B 2.0 x 2.0 x 0.6	Diodes Inc.	DFN2020-3 (SOT1061)	3
U-DFN2020-6	Diodes Inc.	DFN2020MD-6 (SOT1220)	6
UDFN2020-6 Type B	Diodes Inc.	DFN2020-6 (SOT1118)	6
UDFN2020-6 Type E	Diodes Inc.	DFN2020MD-6 (SOT1220)	6
U-DFN2523-6*	Diodes Inc.	DFN2020MD-6 (SOT1220)	6
UDFN6	ON Semi	DFN2020MD-6 (SOT1220)	6
UDFN6	Toshiba	DFN2020-6 (SOT1118)	6
UDFN-6 WDFN6	ON Semi	DFN2020MD-6 (SOT1220)	6
UDFN6B	Toshiba	DFN2020MD-6 (SOT1220)	6
UF6	Toshiba	SOT363	6
UF6/ USV/ US6	Toshiba	SOT363	6
UMD2	Rohm	SOD323F	2
UMD3/UMT3	Rohm	SOT323	3
UMD5/UMT5	Rohm	SOT353	5
UMD6/ UMT6	Rohm	SOT363	6
UMLP 1.6 x 1.6*	Fairchild	DFN2020MD-6 (SOT1220)	6
UMT3	Rohm	SOT323	3
UMT3F*	Rohm	SOT323	3
UMT5/ UMD5	Rohm	SOT353	5
UMT6	Rohm	SOT363	6
UMT6/ UMD6	Rohm	SOT363	6
UPAK (SOT89)	Renesas	SOT89	3
URP	Renesas	SOD323	2

Type	Competitor	Nexperia	Pins/Leads
US6	Toshiba	SOT363	6
US6/ UF6/ USV	Toshiba	SOT363	6
use	Toshiba	SOD323	2
US-Flat	Toshiba	SOD323F	2
USM	Toshiba	SOT323	3
USV	Toshiba	SOT353	5
USV	Toshiba	SOT363	6
USV/ US6/ UF6/	Toshiba	SOT363	6
VESM*	Toshiba	DFN1010D-3 (SOT1215)	3
VML0806*	Rohm	DFN1006B-3 (SOT883B)	3
VML1006	Rohm	DFN1006-3 (SOT883)	3
VMN2*	Rohm	DFN1006-2 (SOD882)	2
VMN2*	Rohm	DFN1006D-2 (SOD882D)	2
VMN3*	Rohm	DFN1006-3 (SOT883)	3
VMT3*	Rohm	DFN1010D-3 (SOT1215)	3
VMT6*	Rohm	DFN1010B-6 (SOT1216)	6
VS6	Toshiba	SOT457	6
WDFN3	ON Semi	DFN2020-3 (SOT1061)	3
W-DFN3020-8*	Diodes Inc.	DFN2020-6 (SOT1118)	6
WDFN6	ON Semi	DFN2020-6 (SOT1118)	6
WDFN6	ON Semi	DFN2020MD-6 (SOT1220)	6
WDFN-8	ON Semi	LFPK33 (SOT1210)	8
WLL-2-2	Infineon	DSN0402B-2 (SOD992B)	2
WLP1.5x 1.5*	Texas Instruments	DFN2020MD-6 (SOT1220)	6
WLPI.Ox 1.0*	Texas Instruments	DFN1010D-3 (SOT1215)	3
WLPI.Ox 1.5*	Texas Instruments	DFN2020MD-6 (SOT1220)	6
X1 -DFN 1006-3	Diodes Inc.	DFN1006-3 (SOT883)	3
X1-DFN1212-3*	Diodes Inc.	DFN1010D-3 (SOT1215)	3
X1-DFN1616-6*	Diodes Inc.	DFN2020MD-6 (SOT1220)	6
X2-DFN0806-3	Diodes Inc.	DFN1006-3 (SOT883)	3
X2-DFN1006-2	Diodes Inc.	DFN1006D-2 (SOD882D)	2
X2-DFN1006-3	Diodes Inc.	DFN1006B-3 (SOT883B)	3
X2-DFN1010-3	Diodes Inc.	DFN1010D-3 (SOT1215)	3
X2-DFN1310-6*	Diodes Inc.	DFN1010B-6 (SOT1216)	6
X2-DFN2015-3*	Diodes Inc.	DFN2020MD-6 (SOT1220)	6
X2-DFN2020-6	Diodes Inc.	DFN2020MD-6 (SOT1220)	6
XDFN3	ON Semi	DFN1006-3 (SOT883)	3
XI-DFN1006-2	Diodes Inc.	DFN1006-2 (SOD882)	2















Types with * show footprint compatibility only

Package cross reference matrix

Pins/ leads	Nexperia	Industry standard names	Size (l x w x h) (mm)	P _{tot} (mW)	Package	Competitor synonyms									
						Rohm	Toshiba	ON Semi	Renesas	Infineon	Diodes Inc	ST	Vishay	Semtech	
2	DFN1006-2 (SOD882)		1.0 x 0.6 x 0.48	250		(VMN2)	CTS2 (FSC)	(SOD923-2)		TSLP-2-1	XI-DFN1006-2	SOD 882 uQFN-2L	LLP1006-2M LLP1006-2L	SLP1006P2	
	DFN1006D-2 (SOD882D)		1.0 x 0.6 x 0.37	250		(VMN2)	CTS2 (FSC)	DSN2 1.0 x 0.6		TSLP-2-7/ -17	X2- DFN1006-2	SOD882T	LLP1006-2L LLP1006-2M	SLP1006P2T	
	DFN1608D-2 (SOD1608)		1.6 x 0.8 x 0.37	780		KMD2		DSN2 1.6 x 0.8		TSNP-2-2				SLP1610N2	
	SOD123F		2.6 x 1.6 x 1.1	830			S-Flat	SOD-123-FL			PowerDI123	SOD-123			
	SOD123W		2.6 x 1.7 x 1.0	900		PMDU	S-Flat	SOD-123-FL	SRP-F		PowerDI123	Strmite flat			
	SOD128		3.8 x 2.5 x 1.0	1000		PMDT	M-Flat					SMA flat			
	SOD323	SC-76	1.7 x 1.25 x 0.95	400			USC	SOD-323	URP	SOD323	SOD-323	SOD-323	SOD323	SOD323	
SOD323F	SC-90	1.7 x 1.25 x 0.7	830		UMD2	US-Flat				PowerDI323					
3	CFP15 (SOT1289)		5.8 x 4.3 x 0.78	1200							PowerDi5		SMPC TO-277A		
	DFN1006-3 (SOT883)	SC-101	1.0 x 0.6 x 0.48	250		VML1006	SS CSP2	XDFN3		TSLP-3-4	X1-DFN 1006-3			SLP1006P3	
	DFN1006B-3 (SOT883B)		1.0 x 0.6 x 0.37	250		VML1006	CST3	XDFN3		TSLP-3-1, -15	X2- DFN1006-3			SLP1006P3T	
	DFN1010D-3 (SOT1215)		1.1 x 1.0 x 0.37	325		(VMT3)	(VESM)	(SOT723)			X2- DFN1010-3				
	DFN2020-3 (SOT1061)	HUSON3	2.0 x 2.0 x 0.62	1300				WDFN3			U-DFN2020-3 Type B 2.0 x 2.0 x 0.6		PowerPAK SC706L		
	DFN2020D-3 (SOT1061D)		2.0 x 2.0 x 0.62	1300				WDFN3			U-DFN2020-3 Type B 2.0 x 2.0 x 0.6		PowerPAK SC706L		
	D2PAK (SOT404)		11.0 x 11.0 x 4.3			LPDS/ LPTS	TO- 220SM D2PAK	D2PAK D2PAK 3 TO-263-2L	TO-220S/ SMD TO-263 LDPK(S)-(1) MP-25Z	D2PAK, PG- TO263-3	T0263 (D2PAK)	D2PAK, H2PAK-2	TO-263 3-lead TO-263AB / D2PAK TO-263		
	SOT23		2.9 x 1.3 x 1.0	250		SSD3/ SST3	S-Mini TSM	SOT-23	MPAK	SOT23	SOT-23	SOT23	SOT23	SOT23	SOT23
	SOT323	SC-70	2.0 x 1.25 x 0.95	200		UMD3/ UMT3 TUMT3	USM	SC-70	CMAK/ CMPAK	SOT323	SOT-323	SOT-323	SC-70 3 leads	SOT-323	
	TO-220 (SOT78)		15.6 x 10 x 4.4			TO-220FM	TO-220	TO-220-3L, TO-220F-3FS, TO-220-3	MP-25(K)	PG- TO220-3, TO220	TO220-3	TO-220	TO-220, TO- 220AB		
I2PAK (SOT226)		11 x 10 x 4.3					I2PAK, TO-262-2L, TO-262-3L	MP-25SK, TO-262	PG- TO262-3, TO262		I2PAK	TO-262			
4	SOT143B		2.9 x 1.3 x 1.0	250			CP4		MPAK-4R	SOT143	SOT-143			SOT-143	
	LFPK56 (SOT669)	Power- S08	4.9 x 4.45 x 1.0	3950		HSOP8 (Single)	SOP / DSOP Advance	SO-8 FL, DFN-5	LFPK56, HSOP-8	PG-TD- SON-8	Power- Di5060-8	Power- FLAT (6x5)	PowerPAK SO-8(L)		
	LFPK56E (SOT1023)		6.2 x 5.3 x 1.1	500W		HSOP8 (Single)	SOP / DSOP Advance	SO-8 FL, DFN-5	LFPK56, HSOP-8	PG-TD- SON-8	Power- Di5060-8	Power- FLAT (6x5)	PowerPAK SO-8(L)		
	SOT223	SC-73	6.5 x 3.5 x 1.65	1700				SOT-223		SOT223	SOT-223		SOT223		
5	LFPK88 (SOT1235)		8 x 8 x 1.6					To-LL		To-LL			PowerPAK 8x8L		
	SOT353	SC-88 A	2.0 x 1.25 x 0.95	300		UMD5/ UMT5	USV	SC-88 A	CMPAK- 5C0		SOT353		SOT353	SC70-5L	

Types in brackets (...) show footprint compatibility only

Package cross reference matrix

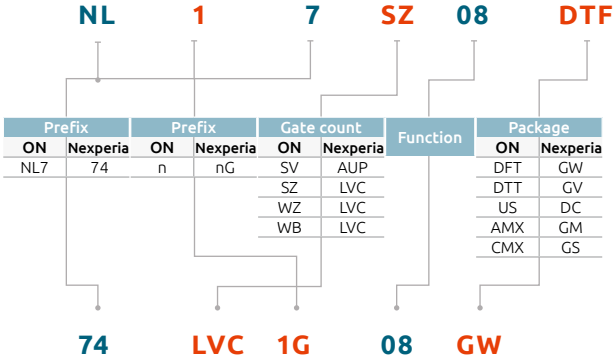
Pins/ leads	Nexperia	Industry standard names	Size (l x w x h) (mm)	P _{tot} (mW)	Package	Competitor synonyms								
						Rohm	Toshiba	ON Semi	Renesas	Infineon	Diodes Inc	ST	Vishay	Semtech
6	DFN1010-6 (SOT891)	XSON6	1.0 x 1.0 x 0.48				CS6	SOT963						
	DFN1010B-6 (SOT1216)		1.1 x 1.0 x 0.37	350		(VMT6)	(FS6)	(SOT063)			(SOT963)			
	DFN1410-6 (SOT886)	XSON6	1.45 x 1.0 x 0.48	250									SLP1510N6	
	DFN1616-6 (SOT1189)	HXSON6	1.6 x 1.6 x 0.48					UDFN 1.6 x 1.6				LLP75-/L	SLP1616P6	
	DFN2020-6 (SOT1118)		2.0 x 2.0 x 0.62	1300		HU- ML2020L8 (Dual)	UDFN6	6 Lead DFN WDFN6			UDFN2020- 6 Type B		PowerPAK SC-70 Thin PowerPAK SC-70	
	DFN2020D-6 (SOT1118D)		2.0 x 2.0 x 0.62	1300		HU- ML2020L8 (Dual)	UDFN6	6 Lead DFN WDFN6			UDFN2020- 6 Type B		PowerPAK SC-70 Thin PowerPAK SC-70	
	DFN- 2020MD-6 (SOT1220)		2.0 x 2.0 x 0.62	1250		HU- ML2020L8 (Single)	UDFN6B	UDFN-6 WDFN6			UDFN2020- 6 Type E		PowerPAK SC-70 Thin PowerPAK SC-70	
	SOT363	SC-88	2.0 x 1.25 x 0.95	300		UMD6/ UMT6	US6 UF6 USV	SC-88	CMPAK-6	SOT363	SOT-363		SC70-6	SC70-6L
	SOT457	SC-74	2.9 x 1.5 x 1.0	750		SMD6/ SMT6	SM6 VS-6	SC-74 TSOP-6	TSOP-6	SC74 TSOP6	SOT23-6 SOT26		TSOP6 TSOP-6	SOT23-6L
8	LFPAK33 (SOT1210)		3.3 x 3.3 x 0.85	790		HSMT8	TSO Advance	µ8FL, WDFN-8		PG-TSD- SON-8	Power DI3333-8	Power FLAT 3.3 x 3.3	PowerPAK 1212-8	
	LFPAK56D (SOT1205)		4.9 x 4.45 x 1.0	680		HSOP8 (Dual)		SO-8FL Dual, DFN-8	HSO N-8 dual	PG-TD- SON-8	Power DI5060-8	Power FLAT 5x6 Dual	PowerPAK SO-8L Dual	
	SOT96	S08	4.9 x 3.9 x 1.75	1500		SOP8	FM8	SOIC-8 NB	SOP-8				S08	
	DFN1714-8 (SOT 1166)	HUSON8	1.7 x 1.35 x 0.52										SLP1713P8	
	DFN1714U-8 (SOT983)	HXSON8	1.7 x 1.35 x 0.48					UDFN 1.7 x 1.35, 0.4P					SLP1713P8	
10	DFN2510-10 (SOT1165)	XSON10	2.5 x 1.0 x 0.48					UDFN10 2.5 x 1, 0.5P		TSLP-9-1		pQFN-10L	SLP1610P4	
	DFN2510A-10 (SOT1176)	XSON10	2.5 x 1.0 x 0.48					UDFN10 2.5 x 1, 0.5P		TSLP-9-1		pQFN-10L	SLP1610P4	
	DFN2626-10 (SOT1197)		2.6 x 2.6 x 0.48					UDFN10 2.6 x 2.6, 0.5P					SLP2626P10	
12	DFN2512-12 (SOT1158)	HXSON12	2.5 x 1.2 x 0.48					UDFN12, 2.5 x 1.2, 0.4P						
	DFN2514-12 (SOT1167)	HUSON12	2.5 x 1.35 x 0.53					UDFN12, 2.5 x 1.35, 0.4P					SLP2513P12	
16	DFN3312-16 (SOT1159)	HXSON16	3.3 x 1.2 x 0.48					UDFN 16, 3.5 x 1.2, 0.4P						
	DFN3314-16 (SOT1168)	HUSON16	3.3 x 1.35 x 0.53										SLP3313P16	

Types in brackets (...) show footprint compatibility only

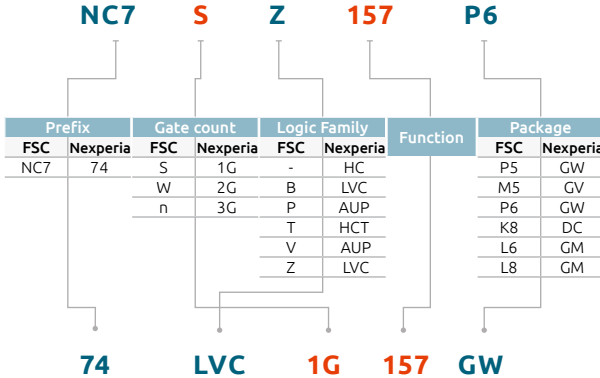
Competitive cross reference - Logic

This cross reference allows you to match a competitor's part number to a Nexperia part number. Once you have the equivalent part number, check the Nexperia website www.nexperia.com/logic to confirm that the particular configuration is released.

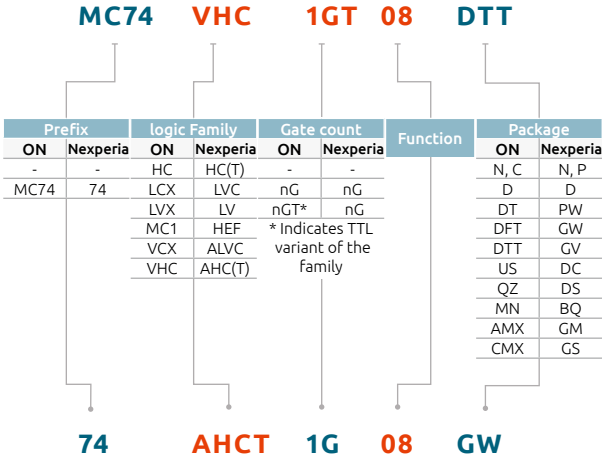
On semiconductor low pin count logic



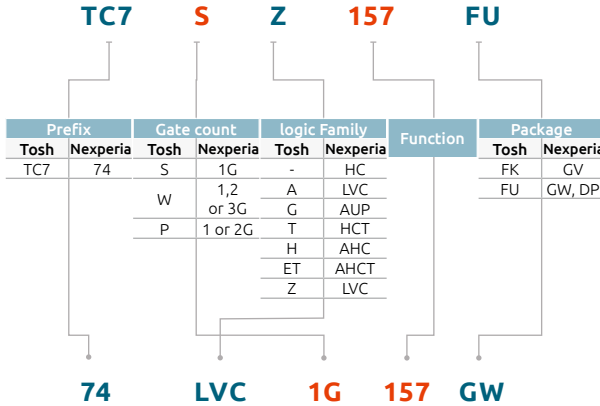
Fairchild semiconductor tiny logic



On semiconductors logic

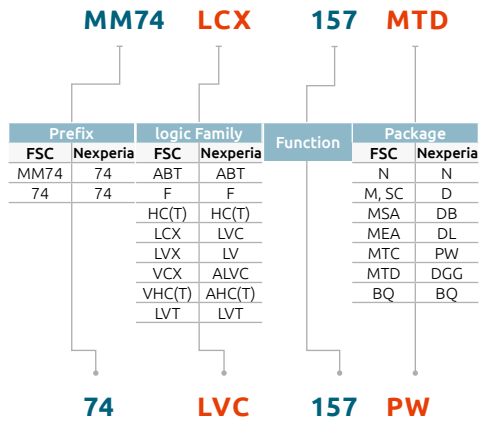


Toshiba one gate

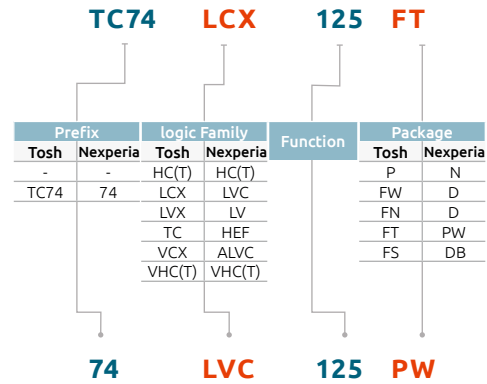


Competitive cross reference - Logic

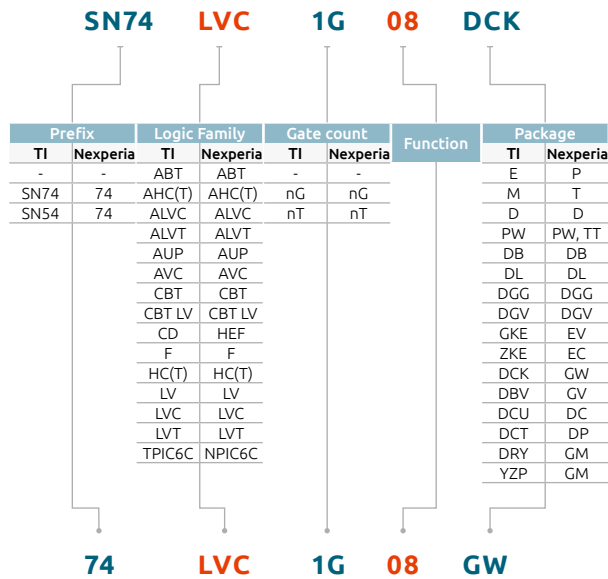
Fairchild semiconductor standard logic



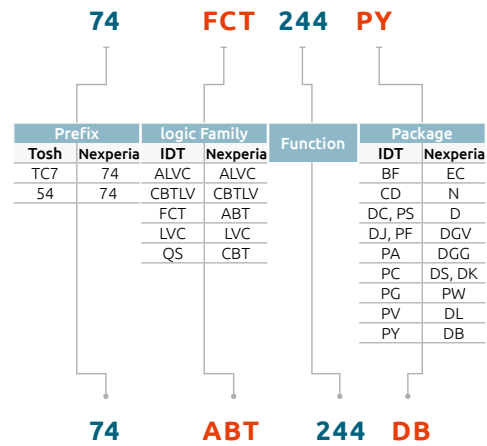
Toshiba standard logic



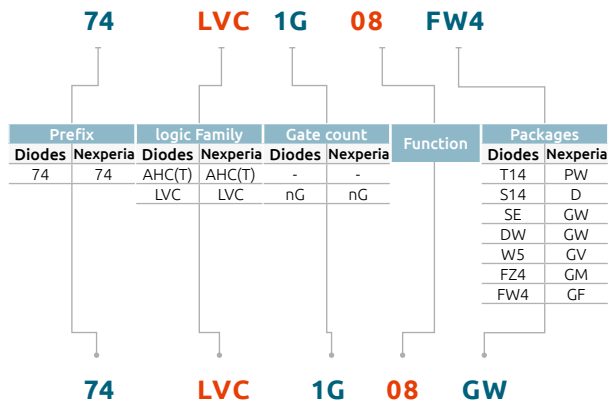
Texas instruments logic



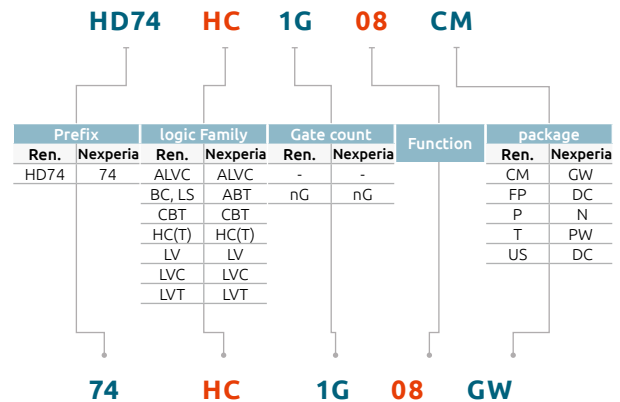
IDT logic



Diodes Inc. logic



Renesas logic



Product orientation (tape and reel pack)

2 pin packages	Orientation in tape	Package	Packing 12NC ending	
			DFN1006-2 (SOD882)	315
			DFN1006D-2 (SOD882D)	315
			DFN1608D-2 (SOD1608)	315
			DSN0402B-2 (SOD992B)	315
			DSN1608-2 (SOD963&964)	315
			SOD80	115, 135
			SOD123F	115
			CFP3 (SOD123W)	115
			SOD123	115, 118
			CFP5 (SOD128)	115
			SOD323	115, 135
			SOD323F	115

3 pin packages	Orientation in tape	Package	Packing 12NC ending		Orientation in tape	Package	Packing 12NC ending			
			SOT89		146			DFN1010D-3 (SOT1215)	147	
									DFN2020-3 (SOT1061)	115, 135
									DFN2020D-3 (SOT1061D)	115, 135
									SOT89	115, 135
									SOT89	115, 135
							D2PAK (SOT404)	118		
		Orientation in tape	Package		Packing 12NC ending		Orientation in tape	Package	Packing 12NC ending	
			DFN1006-3 (SOT883)		315				SOT89	147
			DFN1006B-3 (SOT883B)		315					
		SOT23	185, 215, 235				CFP15 (SOT1289)	139, 146		
		SOT323	115, 135							
	SOT416	115, 135								

4 pin packages	Orientation in tape	Package	Packing 12NC ending		Orientation in tape	Package	Packing 12NC ending		
			LFPAK56 (SOT669)		115				
			LFPAK56E (SOT1023)		115				
			LFPAK88 (SOT1235)		118				
		Orientation in tape	Package		Packing 12NC ending		Orientation in tape	Package	Packing 12NC ending
			SOT143B		215, 235				
		SOT223	115, 135						
	DFN1010-4 (SOT1194)	115							

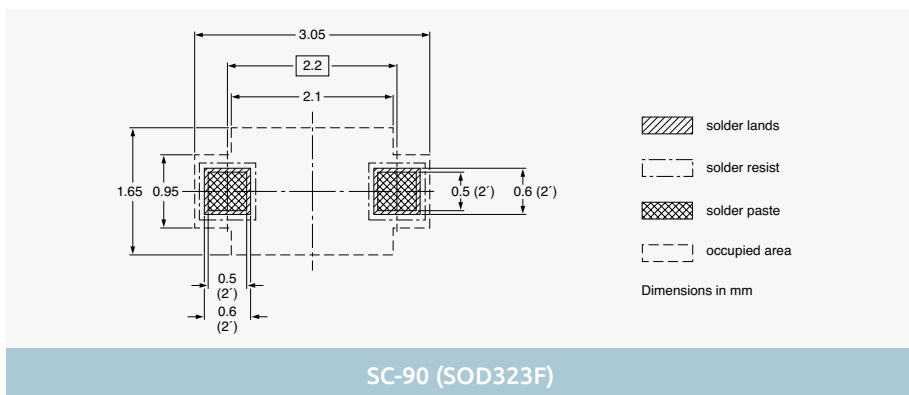
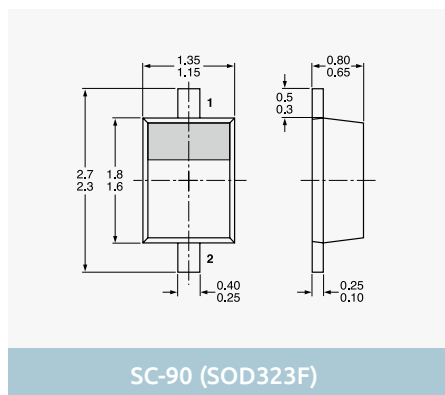
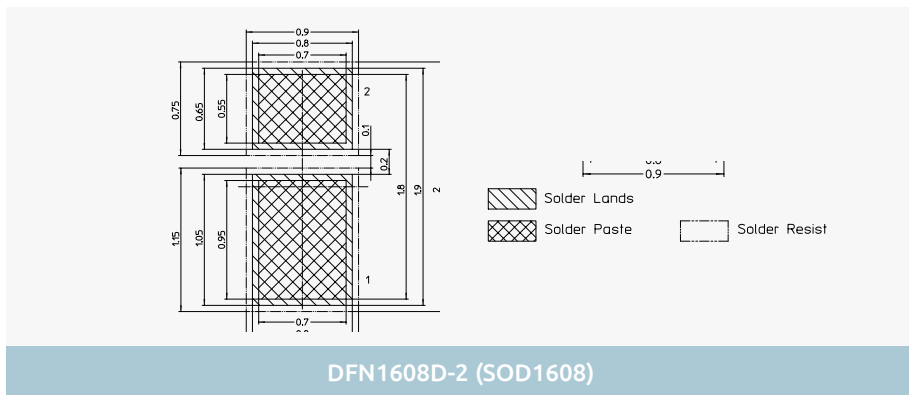
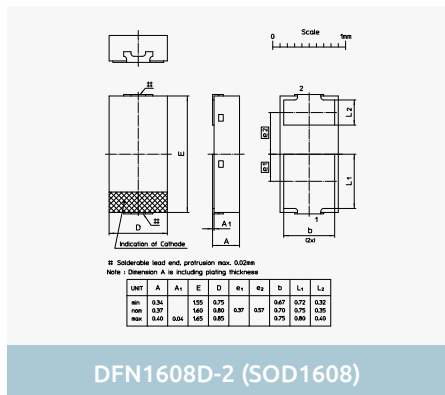
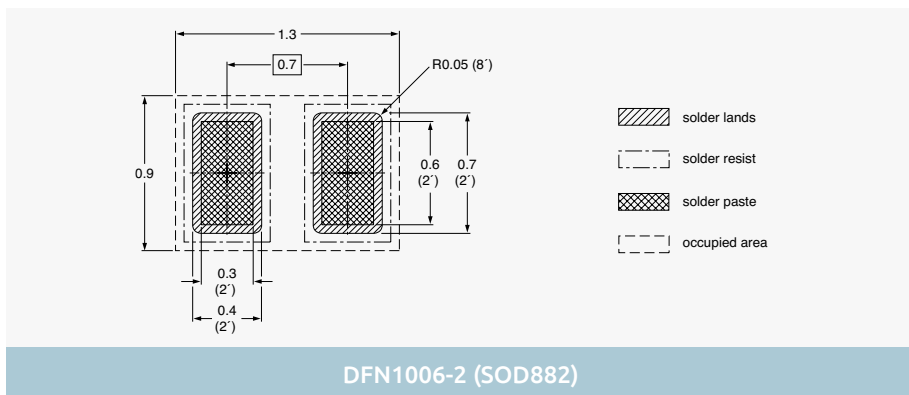
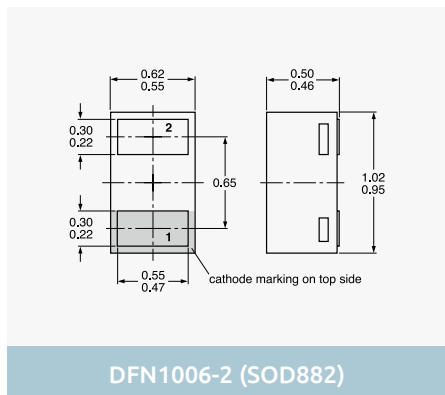
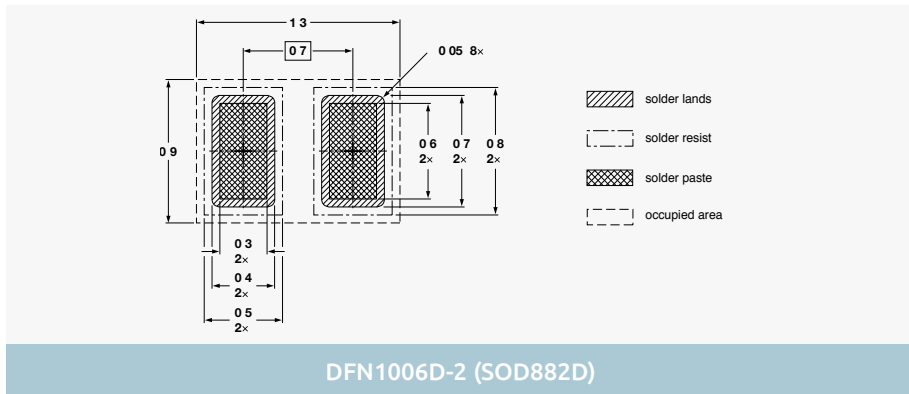
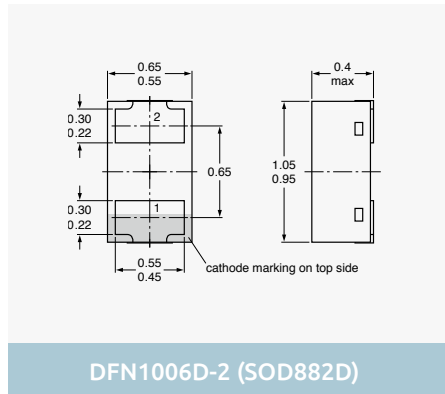
5 pin packages	Orientation in tape	Package	Packing 12NC ending		Orientation in tape	Package	Packing 12NC ending		
								SOT353	115, 135
	Orientation in tape	Package	Packing 12NC ending		Orientation in tape	Package	Packing 12NC ending		
		SOT753	125						
		UMTS (SOT353-1)	125						
	SO5 (SOT753)	125							

Packing methods

6 pin packages	Orientation in tape	Package	Packing 12NC ending	Orientation in tape	Package	Packing 12NC ending
			DFN1410-6 (SOT886)	115		DFN1412-6 (SOT1268)
		DFN1616-6 (SOT1189)	115	DFN2020-6 (SOT1118)		115
		DFN2020MD-6 (SOT1220)	184	DFN2020D-6 (SOT1118D)		115
		LFPAK33 (SOT1210)	115	DFN2020MD-6 (SOT1220)		115
		LFPAK56D (SOT1205)	115	SOT363		115, 135
		XSON6 (SOT886)	125	SOT457		115, 135
				DFN0606B-6		147
Orientation in tape	Package	Packing 12NC ending	Orientation in tape	Package	Packing 12NC ending	
		DFN1010-6 (SOT891)	132			
		DFN1410-6 (SOT886)	132			
		DFN2020MD-6 (SOT1220)	125			
		SOT363	125, 165			
		SOT457	125, 165			
		XSON6 (SOT891)	125			
		SC-88 (SOT363)	125			
		SC-74 (SOT457)	125			

multi I/O pin packages	Orientation in tape	Package	Packing 12NC ending	Orientation in tape	Package	Packing 12NC ending
			DFN2110-9 (SOT1178)	115		
		DFN2111-7 (SOT1358)	471			
		DFN2510A-10 (SOT1176)	115			
		DFN2520-9 (SOT1333)	132			
		SO8 (SOT96-1)	118			
		XQFN10 (SOT1337-1)	115			
		TSSOP10 (SOT552-1)	118			
		DHVQFN14 (SOT762-1)	115			
		TSSOP14 (SOT402-1)	118			
		SSOP16 (SOT519-1)	118			
		TSSOP16 (SOT403-1)	118			
		SO16 (SOT109-1)	118			
		TSSOP20 (SOT360-1)	118			
		SO20 (SOT163-1)	118			
		DHXQFN20 (SOT1045-2)	115			
		DHVQFN20 (SOT764-1)	115			
		SO24 (SOT137-1)	118			
		DHVQFN24 (SOT815-1)	118			
		TSSOP24 (SOT355-1)	118			
		TSSOP48 (SOT362-1)	118			
	TSSOP48 (SOT480-1)	118				
	TSSOP56 (SOT364-1)	118				
Orientation in tape	Package	Packing 12NC ending	Orientation in tape	Package	Packing 12NC ending	
		VSSOP8 (SOT765-1)	125			
		TSSOP8 (SOT505-2)	125			

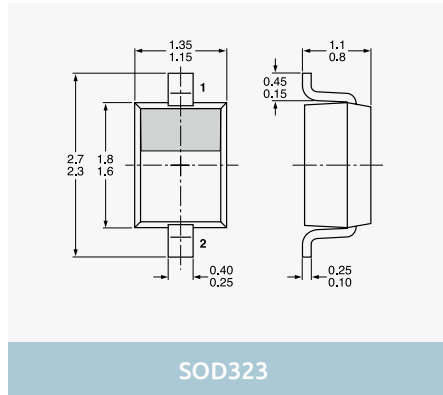
2-pin SMD packages



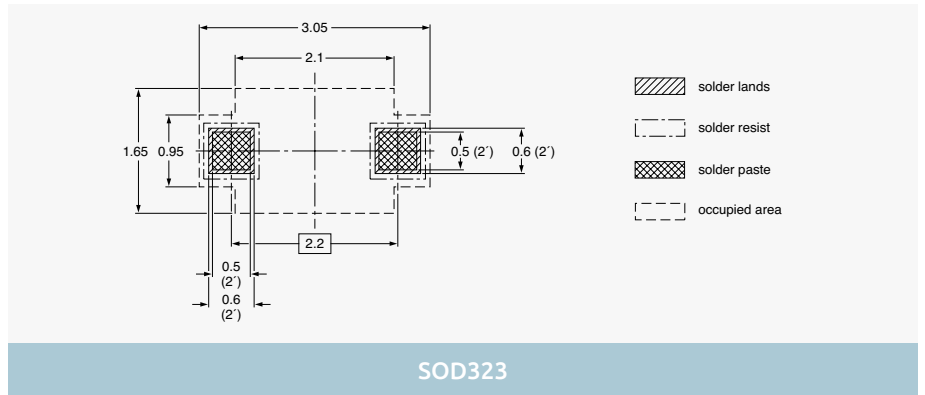
Dimensions in mm

Images are for reference only, for detailed drawings please visit nexperia.com/packages

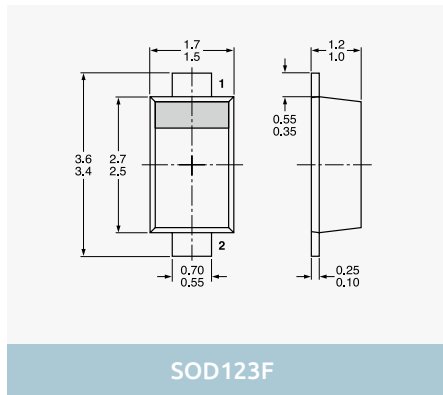
2-pin SMD packages



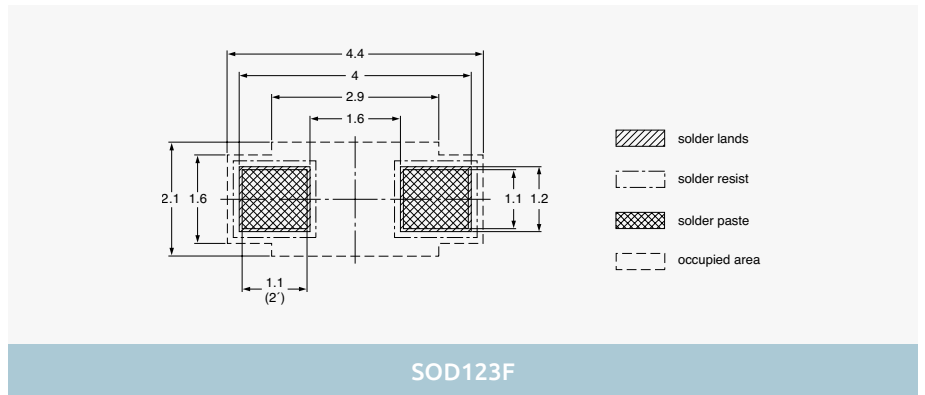
SOD323



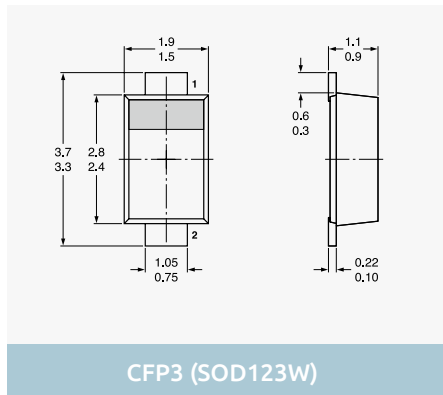
SOD323



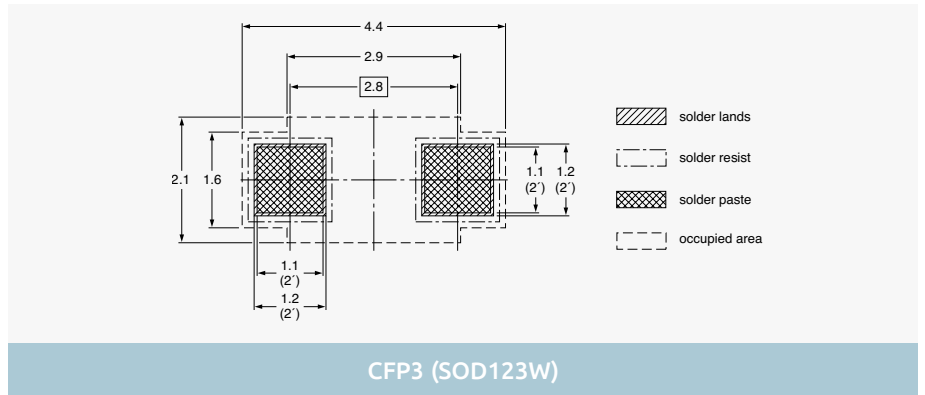
SOD123F



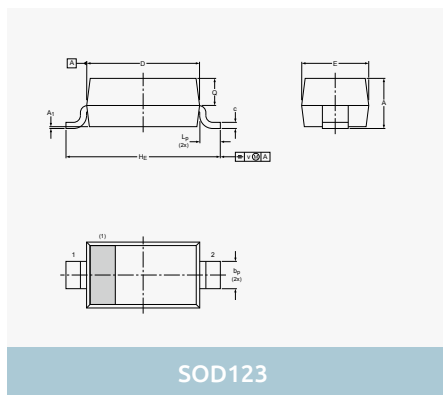
SOD123F



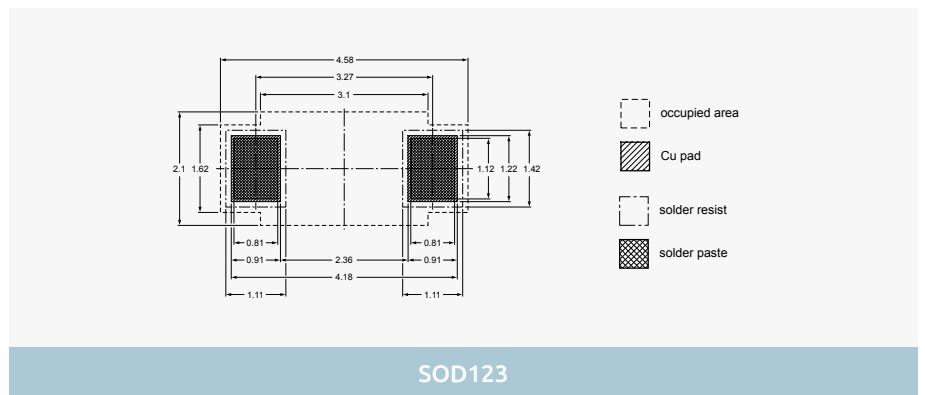
CFP3 (SOD123W)



CFP3 (SOD123W)



SOD123

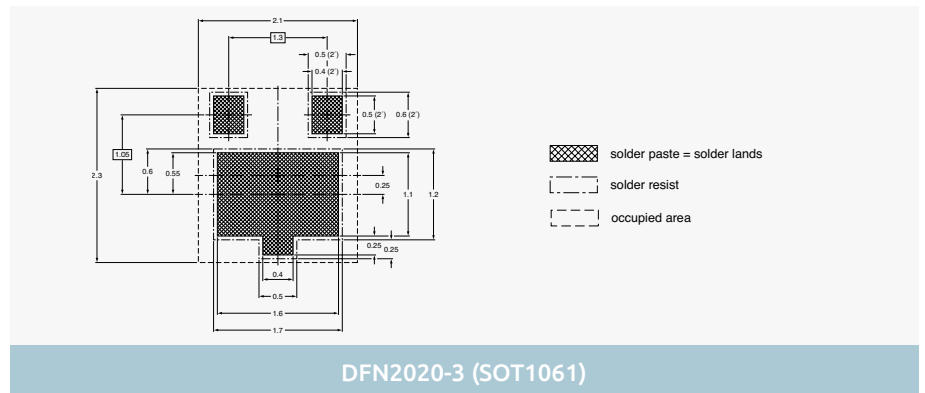
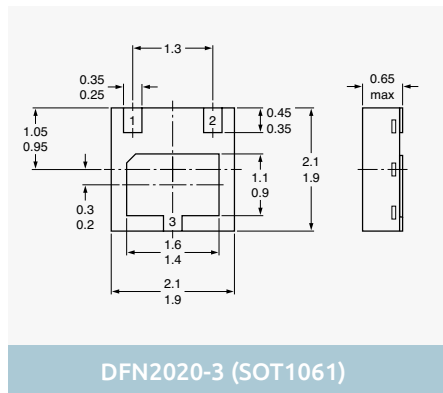
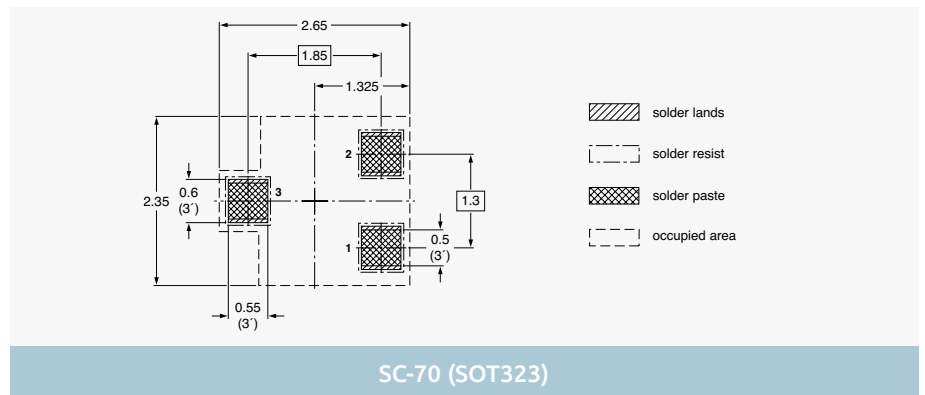
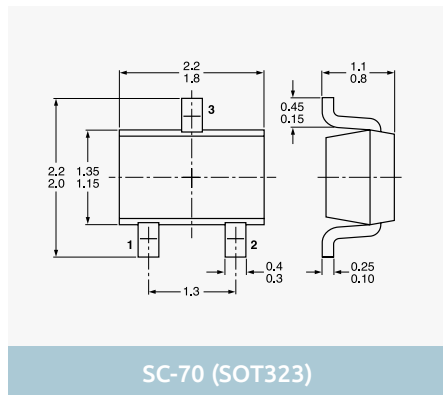
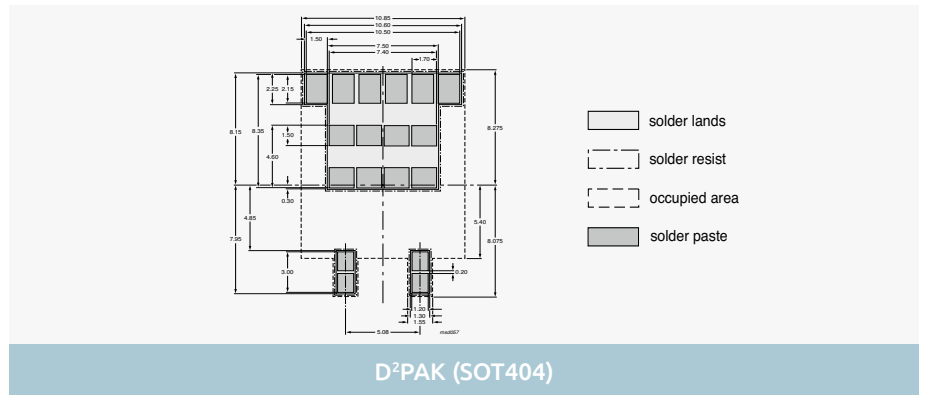
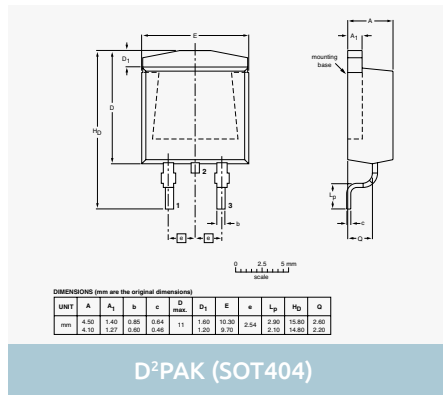
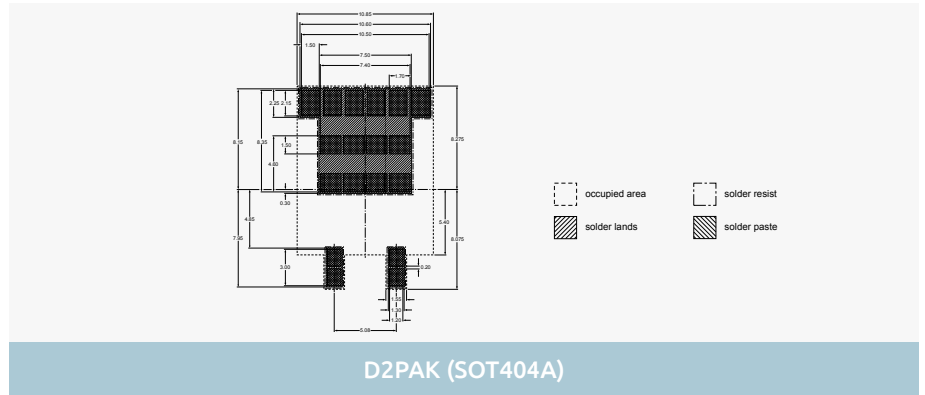
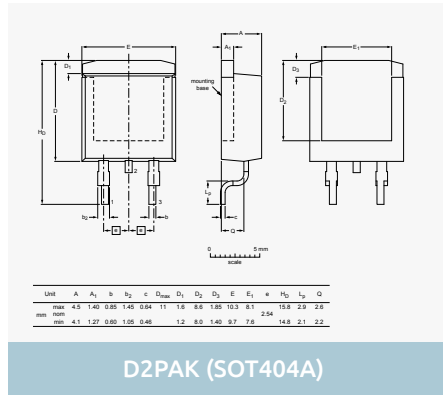


SOD123

Dimensions in mm

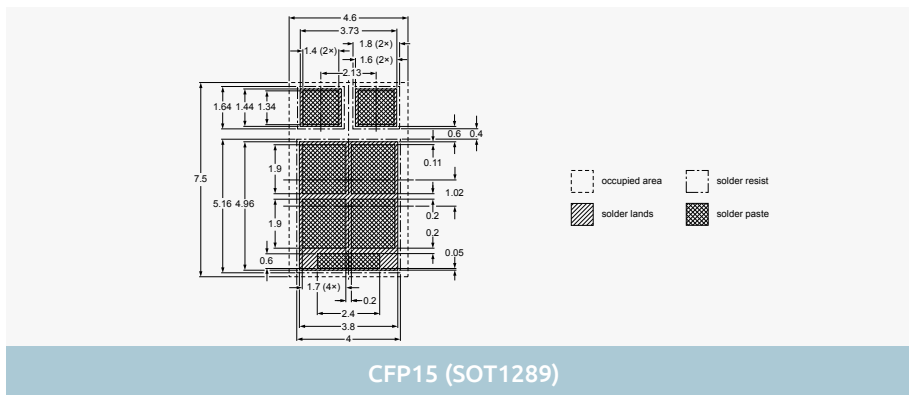
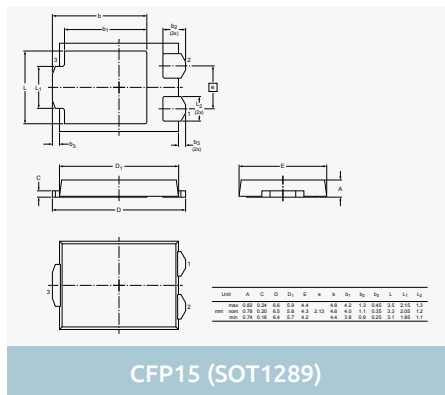
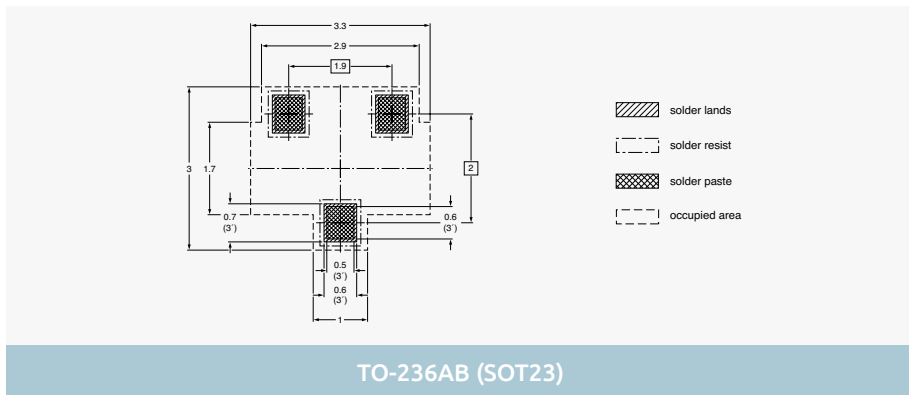
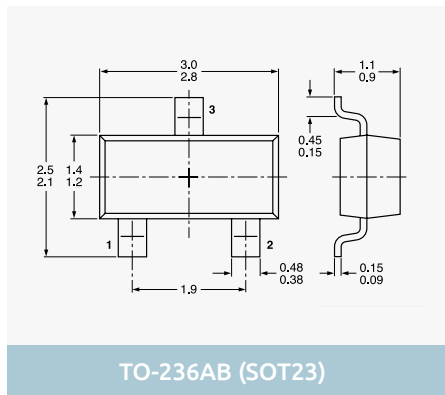
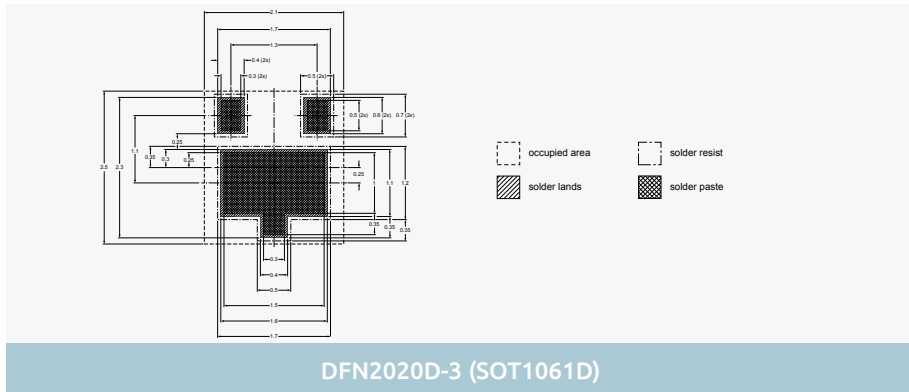
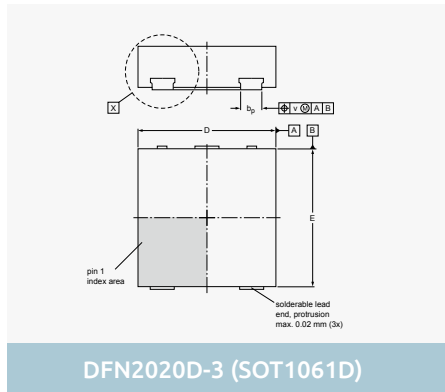
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3-pin SMD packages

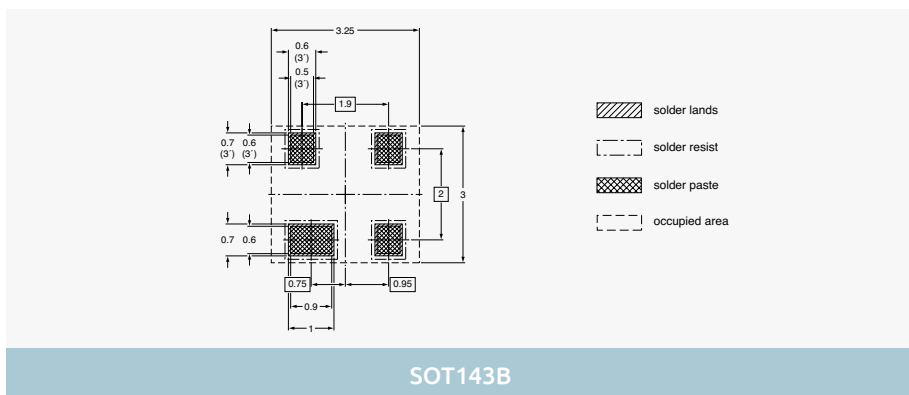
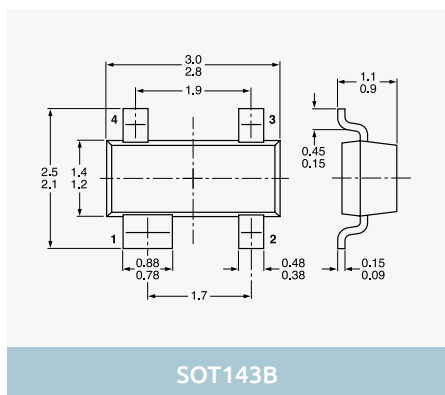


Dimensions in mm

3-pin SMD packages



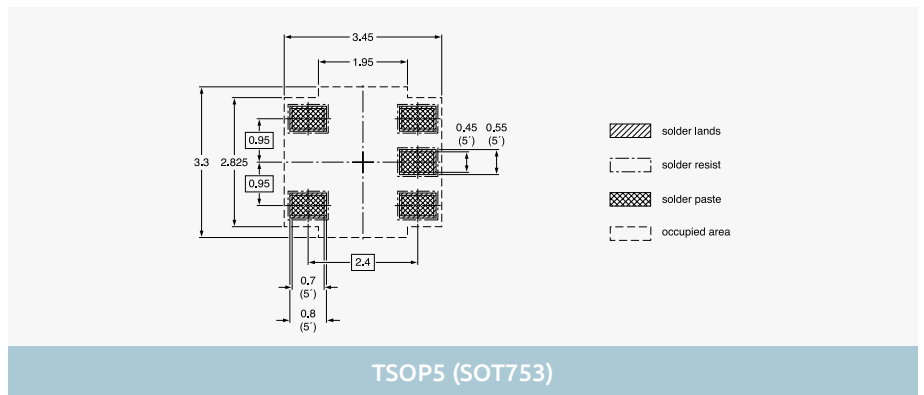
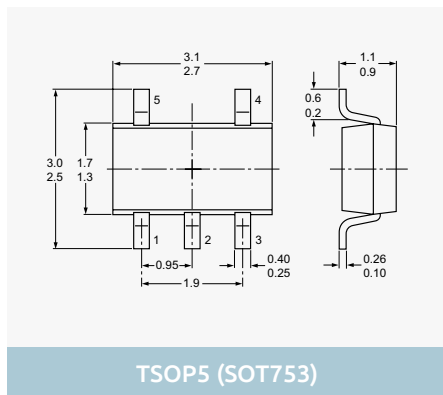
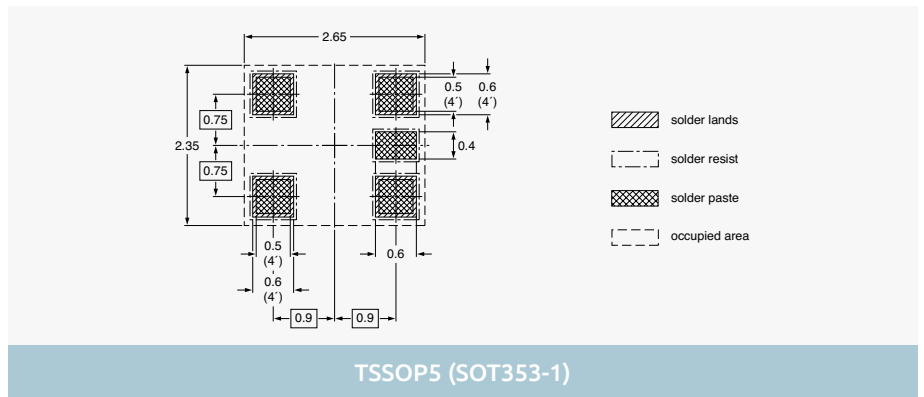
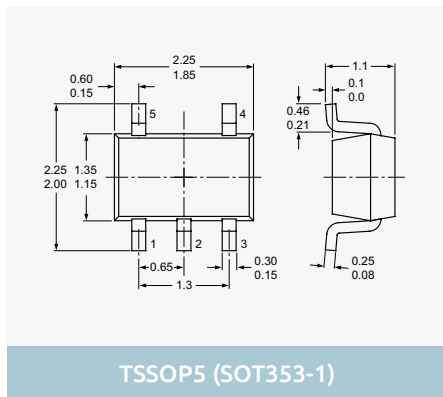
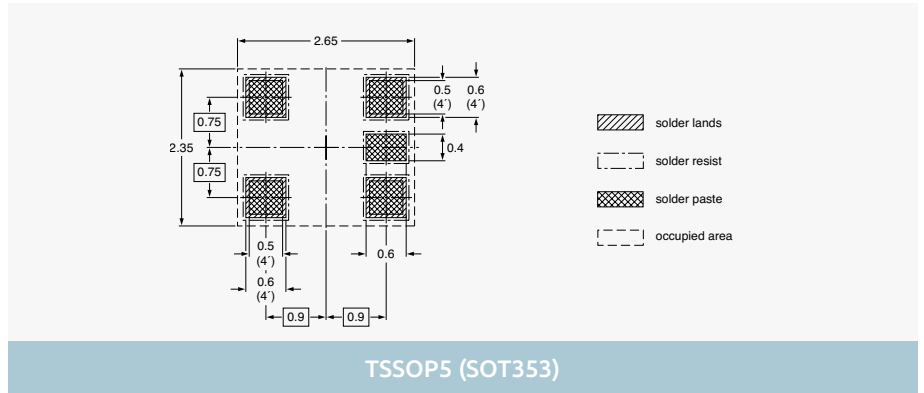
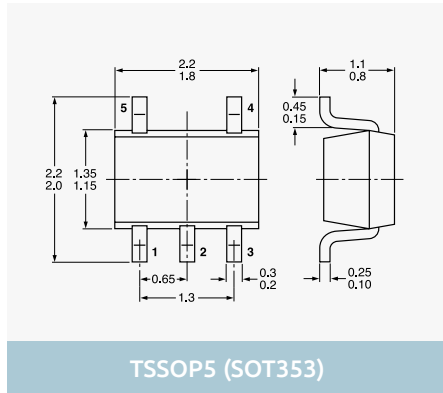
4-pin SMD packages



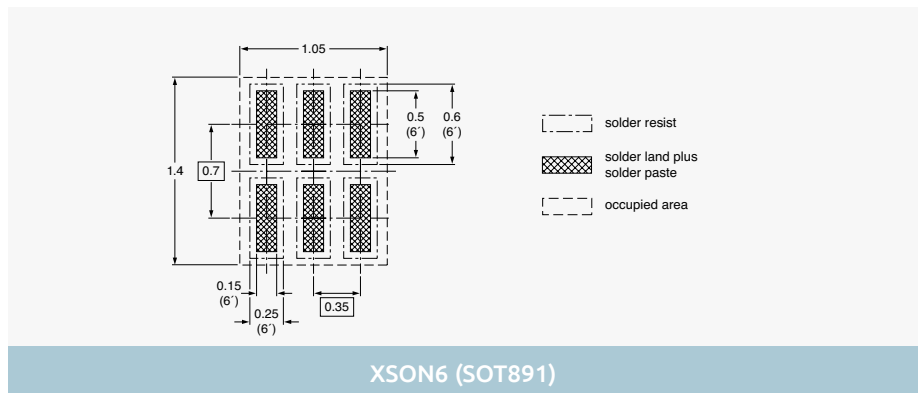
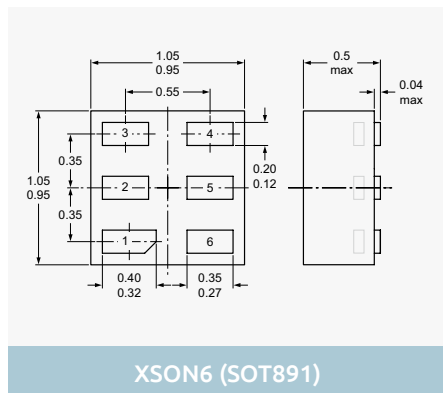
Dimensions in mm

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5-pin SMD packages



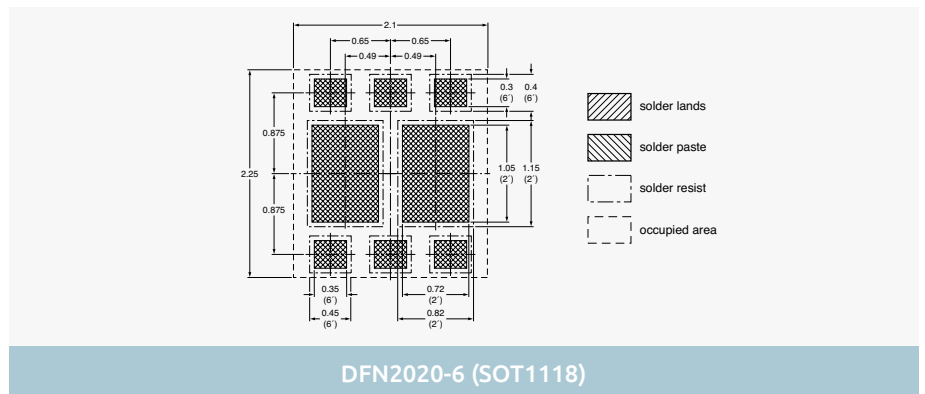
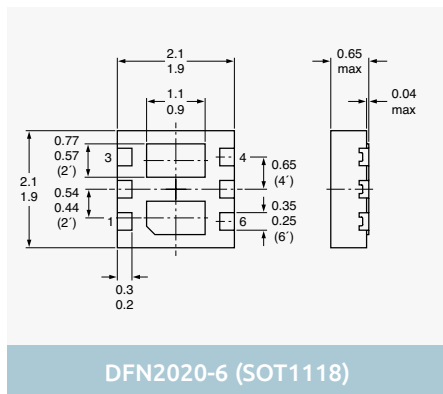
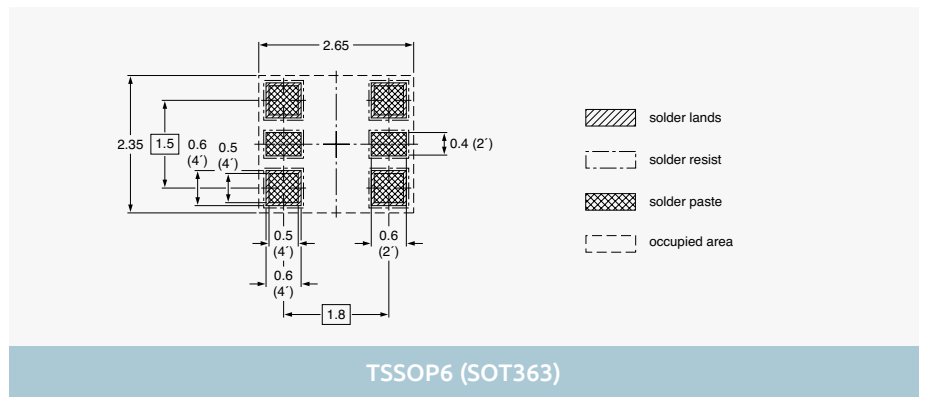
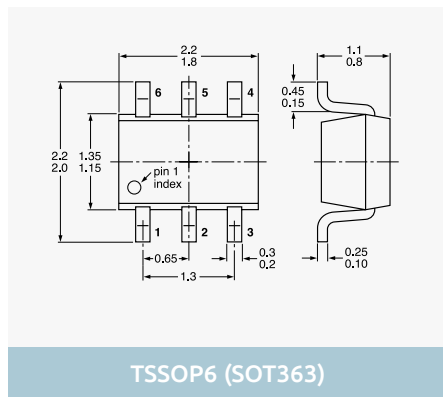
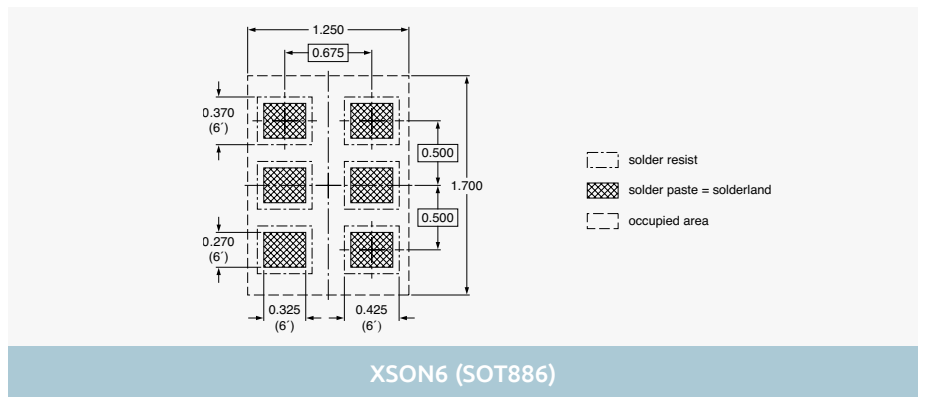
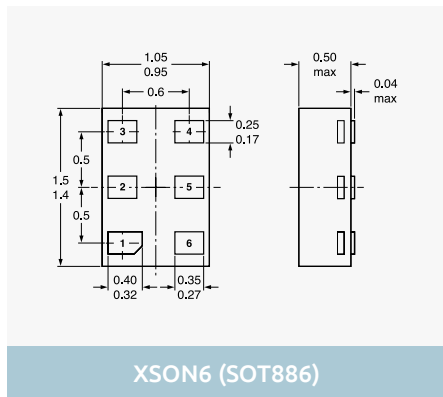
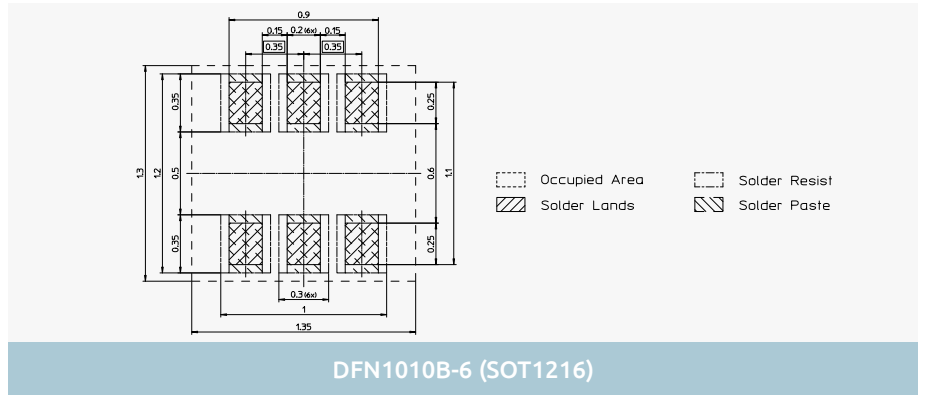
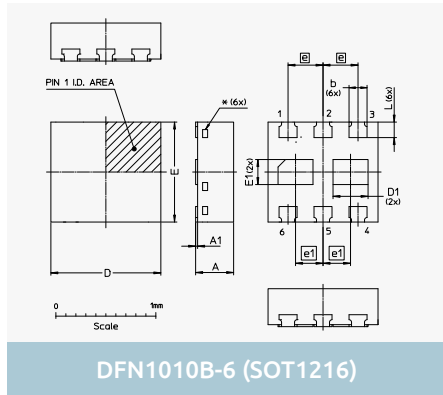
6-pin SMD packages



Dimensions in mm

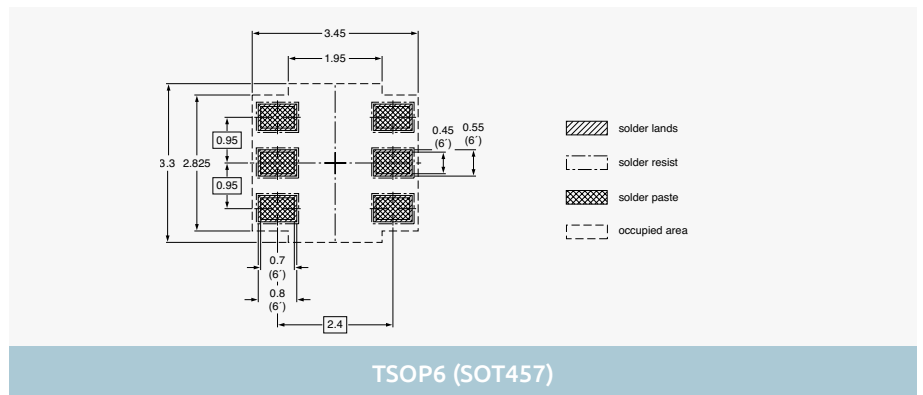
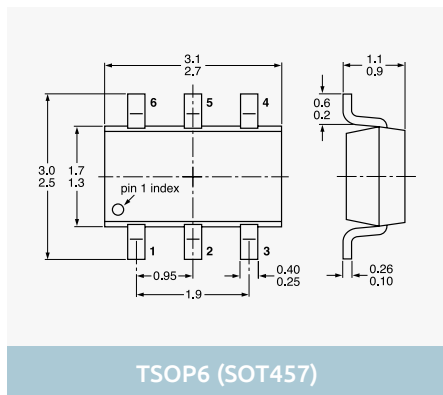
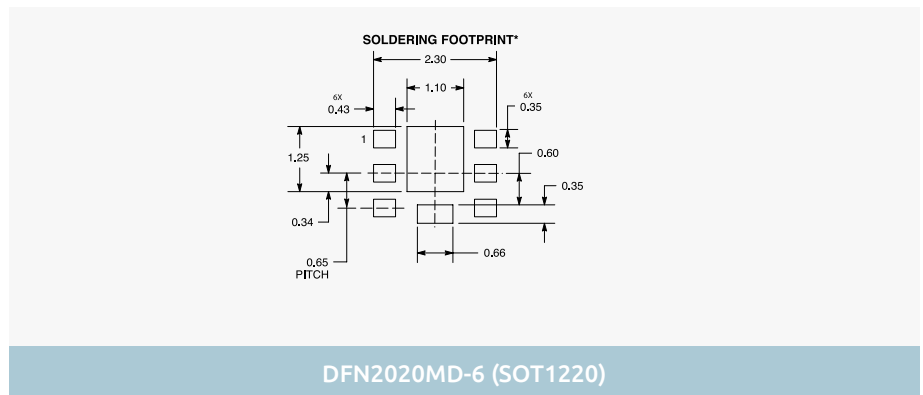
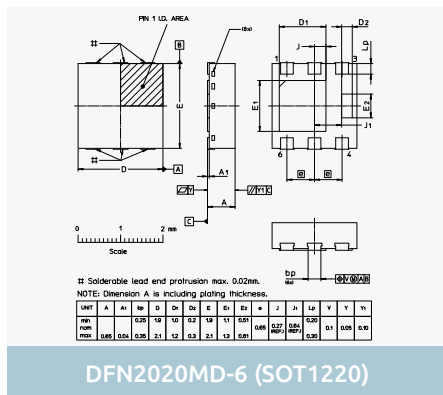
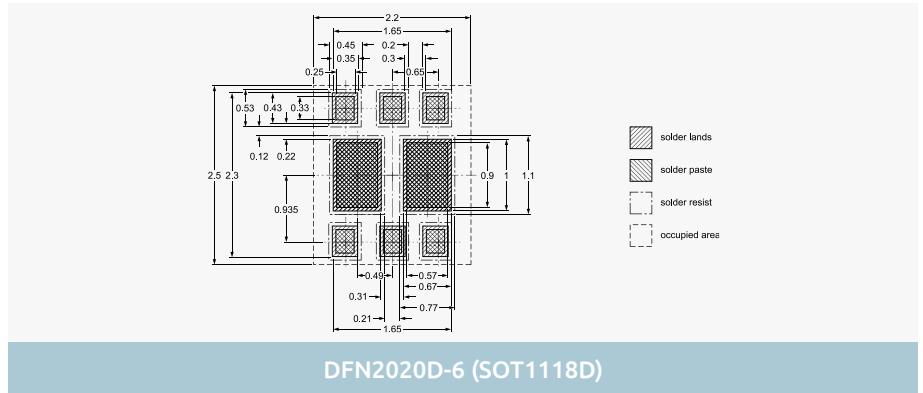
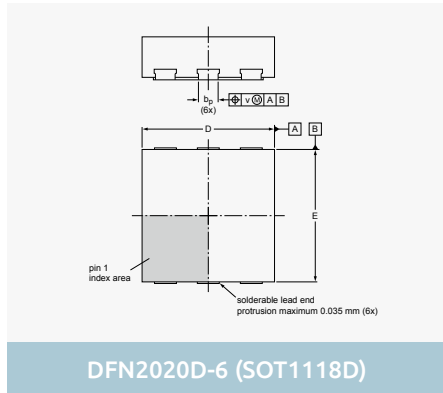
Images are for reference only, for detailed drawings please visit nexperia.com/packages

6-pin SMD packages

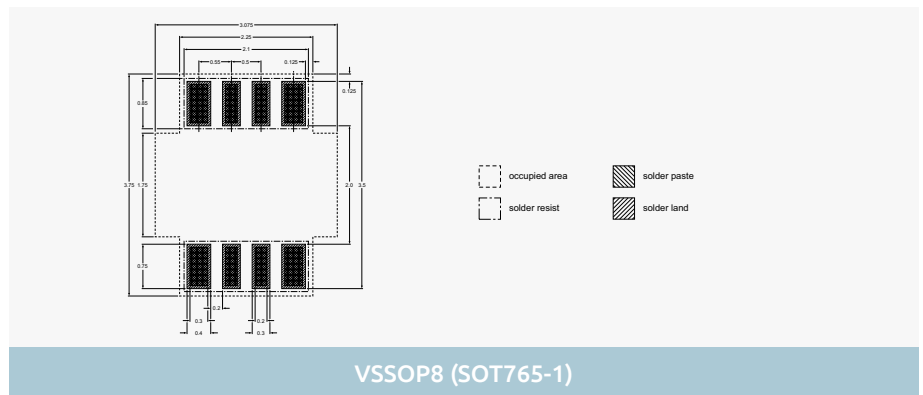
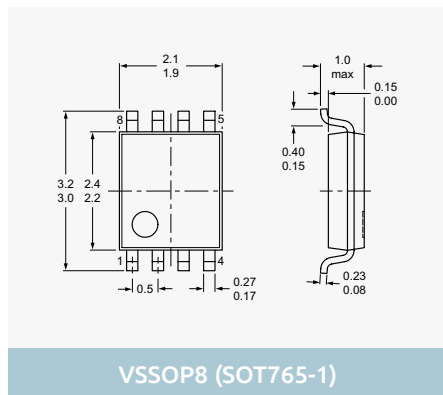


Dimensions in mm

6-pin SMD packages



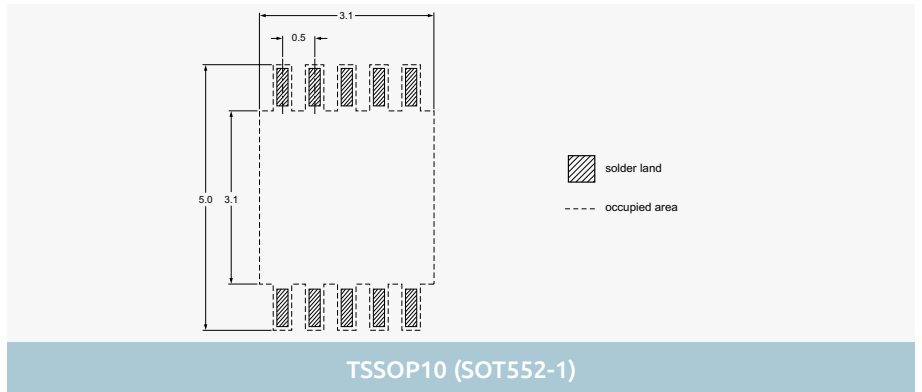
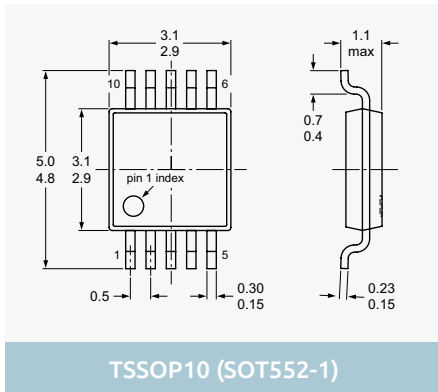
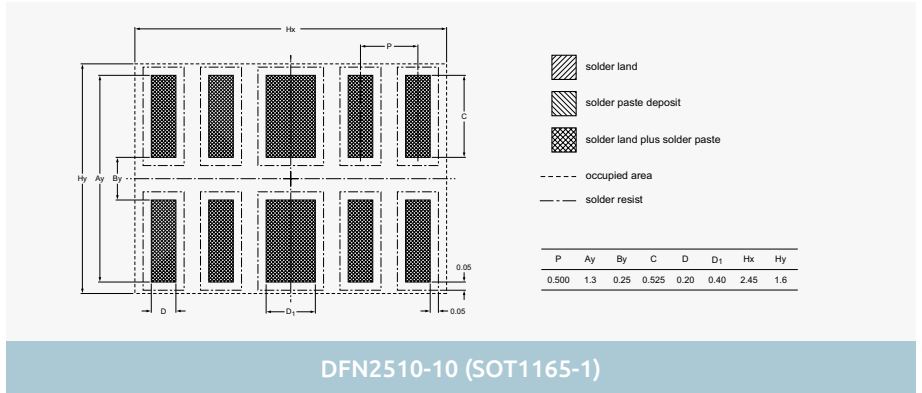
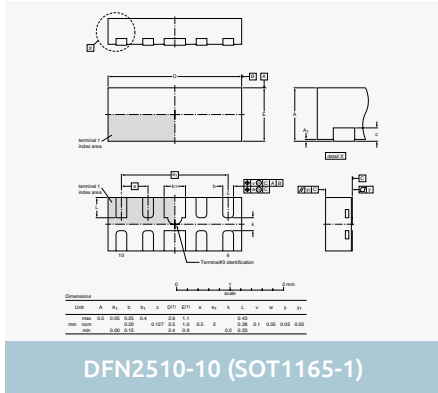
8-pin SMD packages



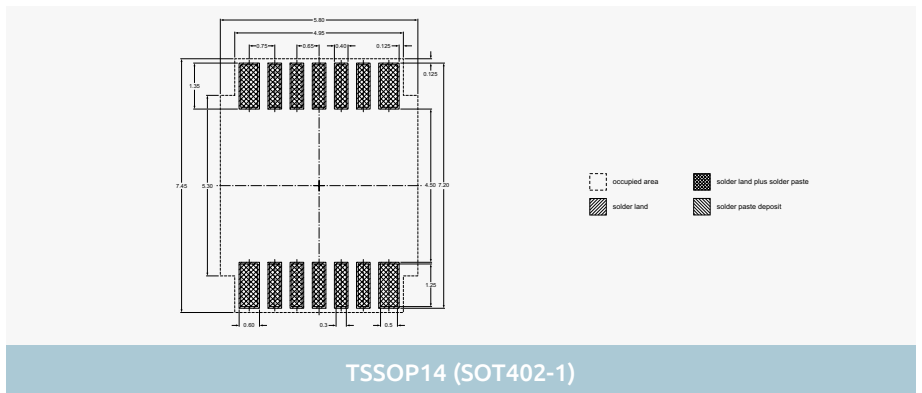
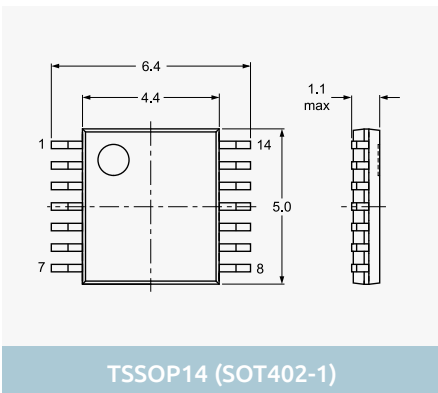
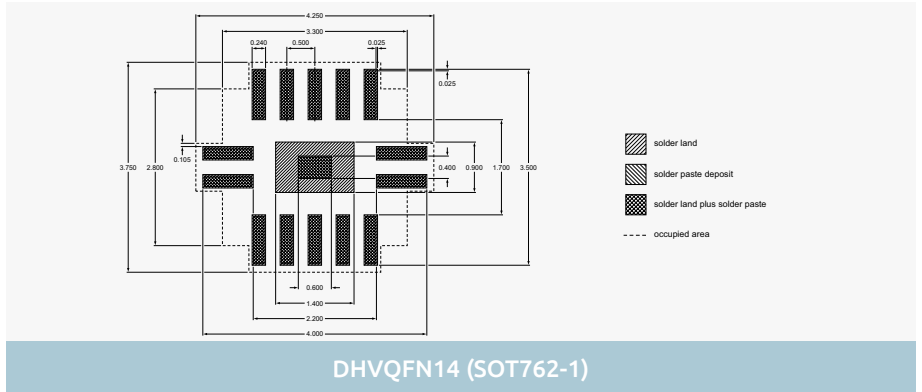
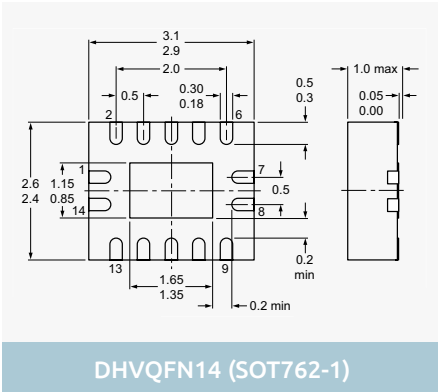
Dimensions in mm

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10-pin SMD packages



14-pin SMD packages

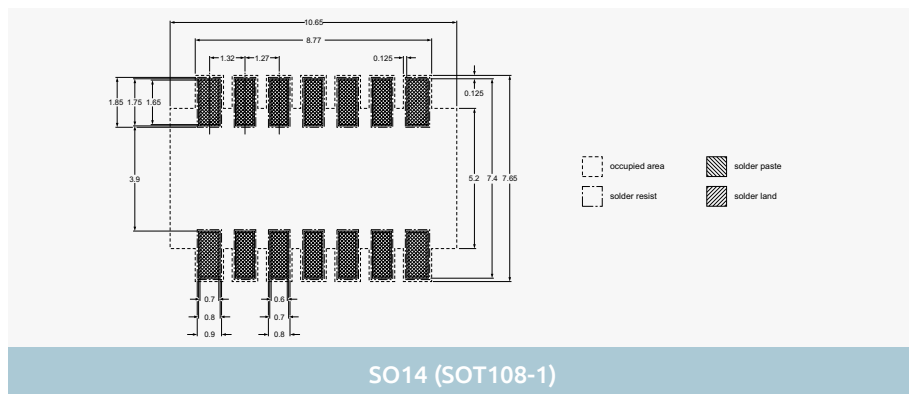
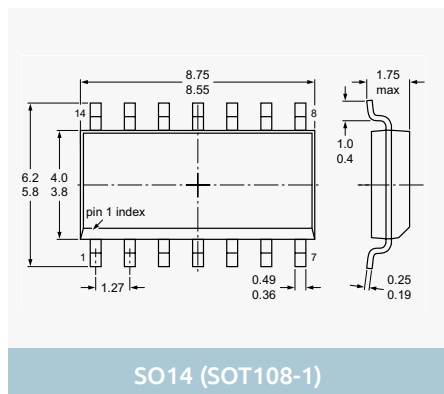


Dimensions in mm

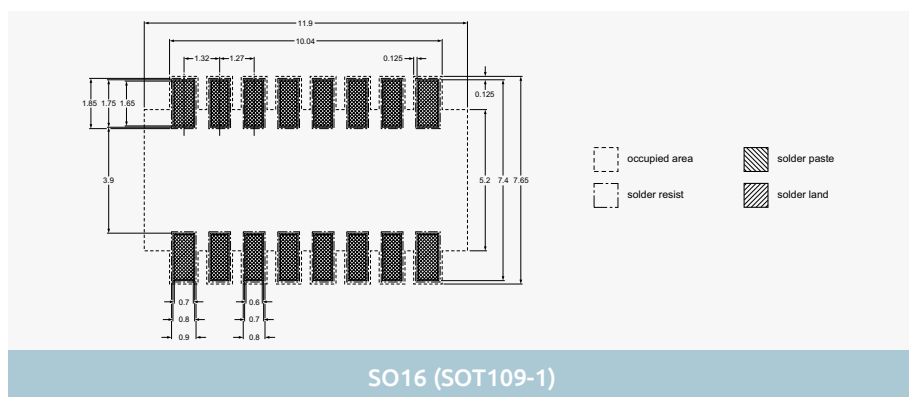
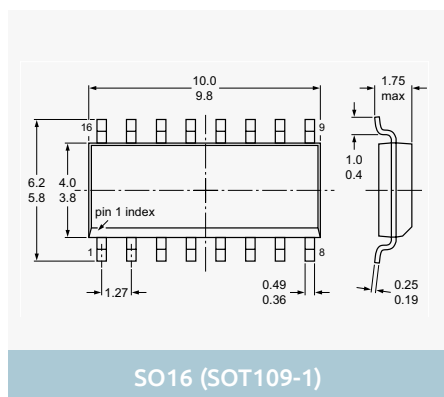
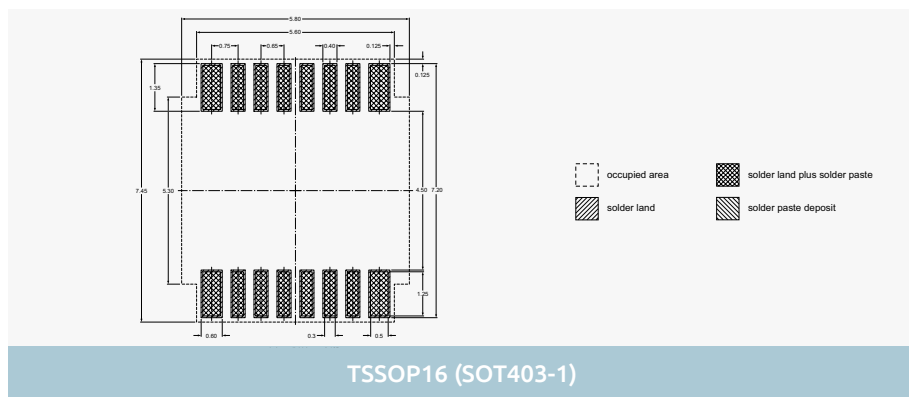
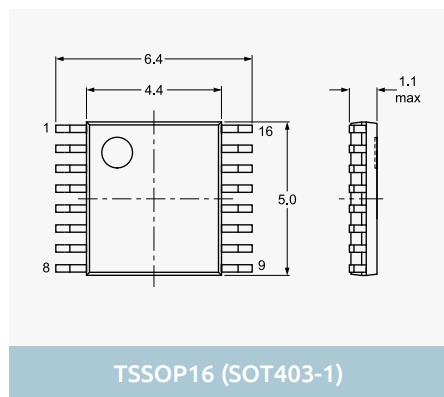
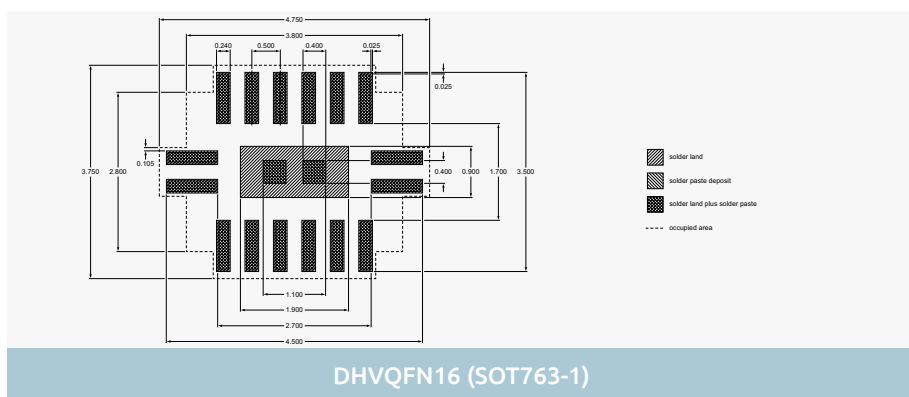
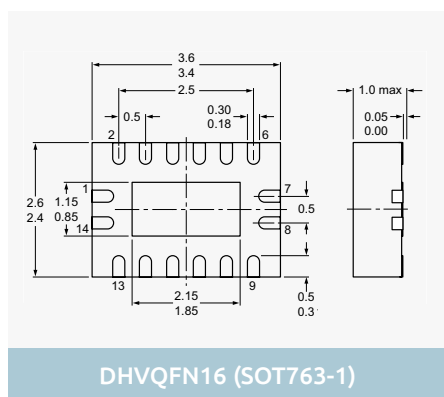
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Minimized outline drawings and reflow soldering footprint

14-pin SMD packages



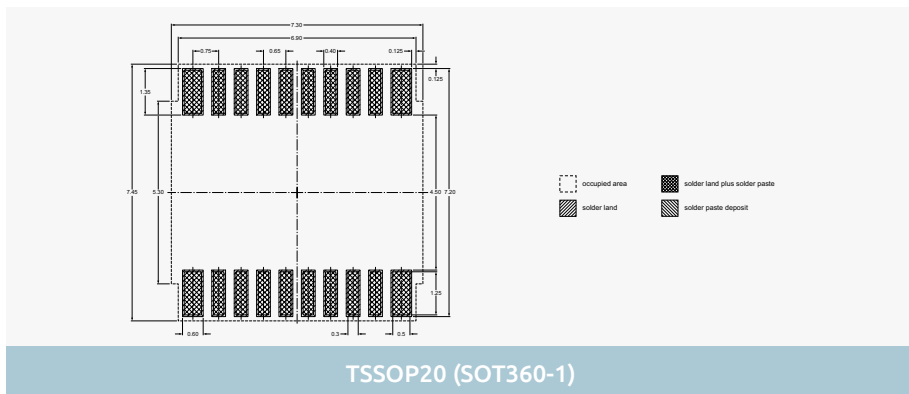
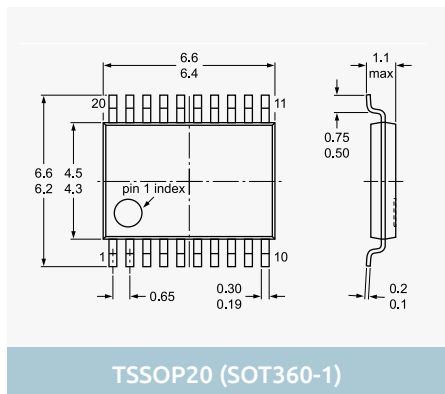
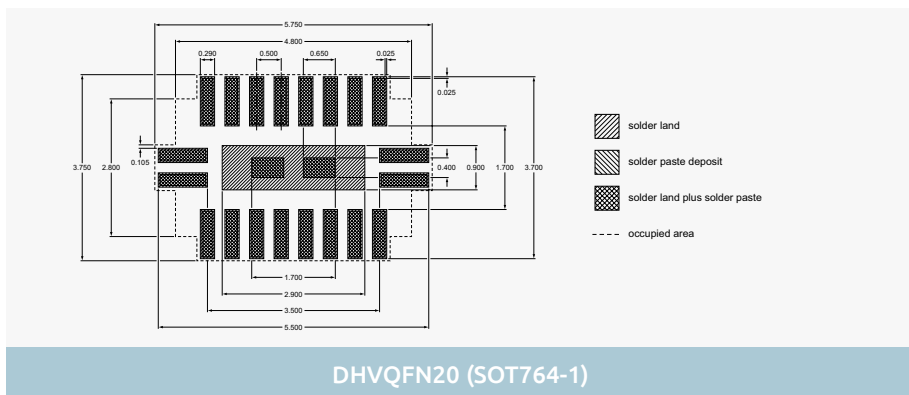
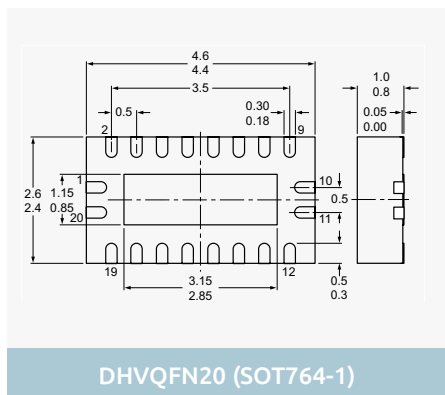
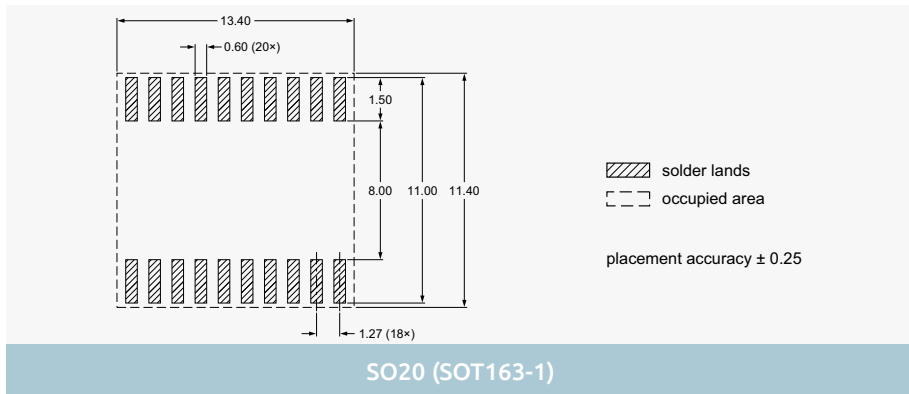
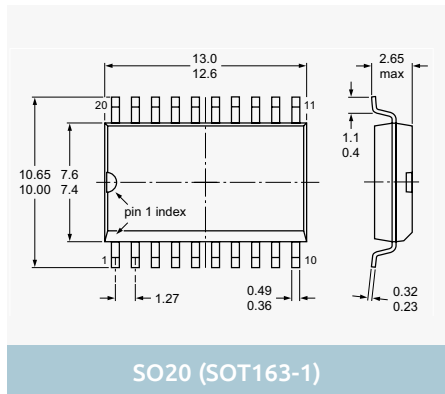
16-pin SMD packages



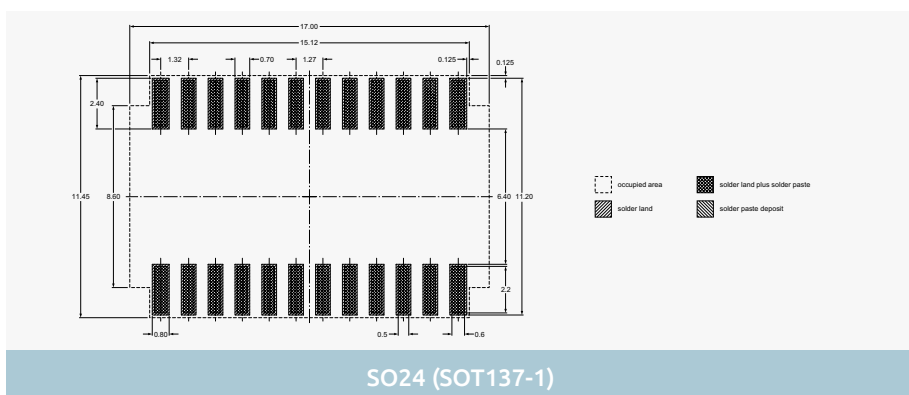
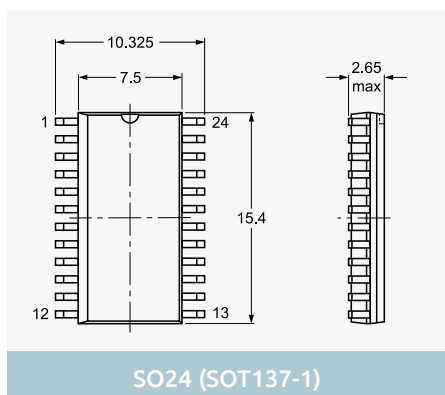
Dimensions in mm

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20-pin SMD packages



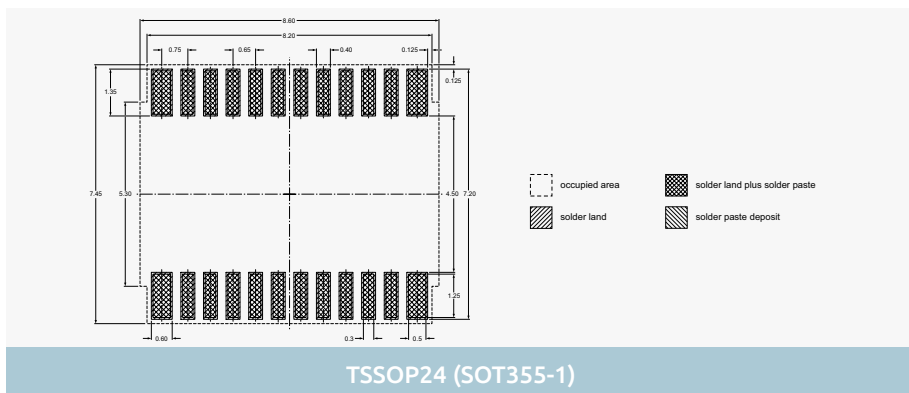
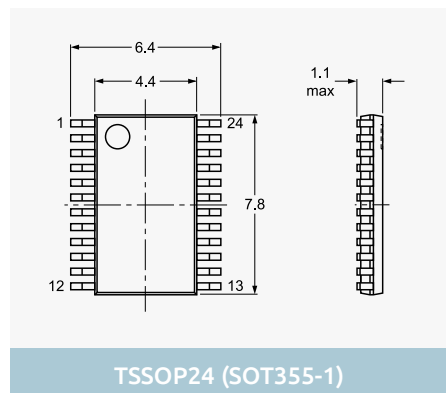
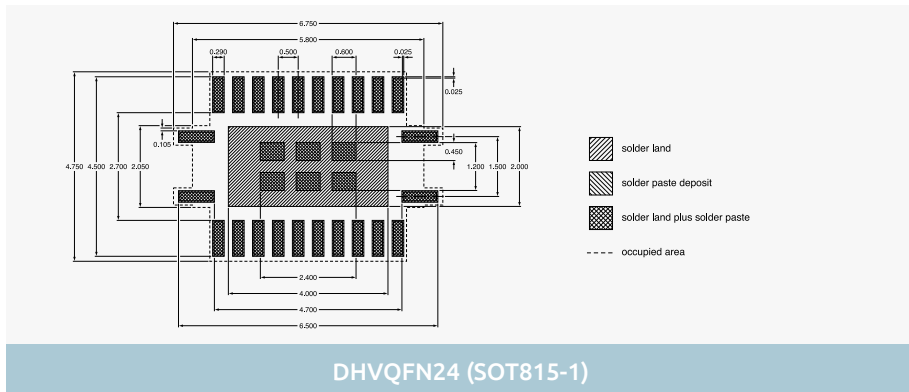
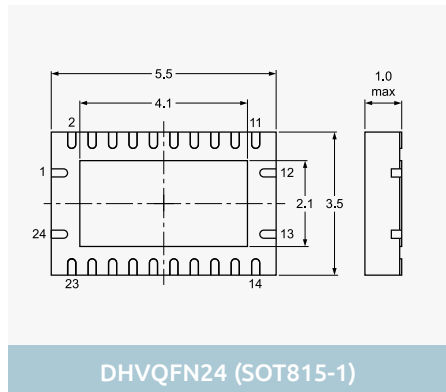
24-pin SMD packages



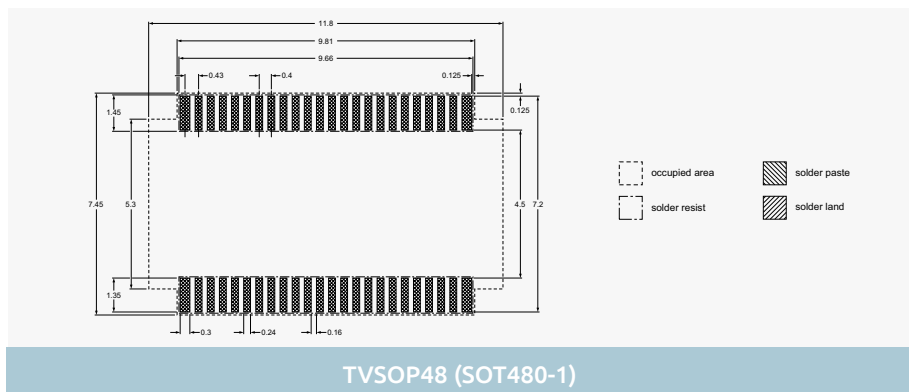
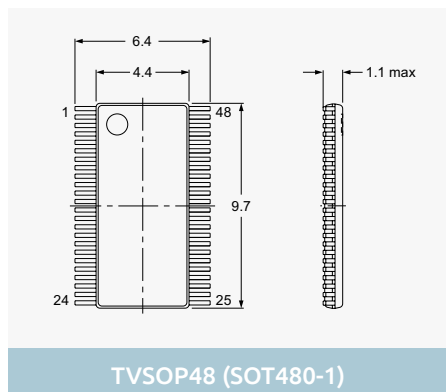
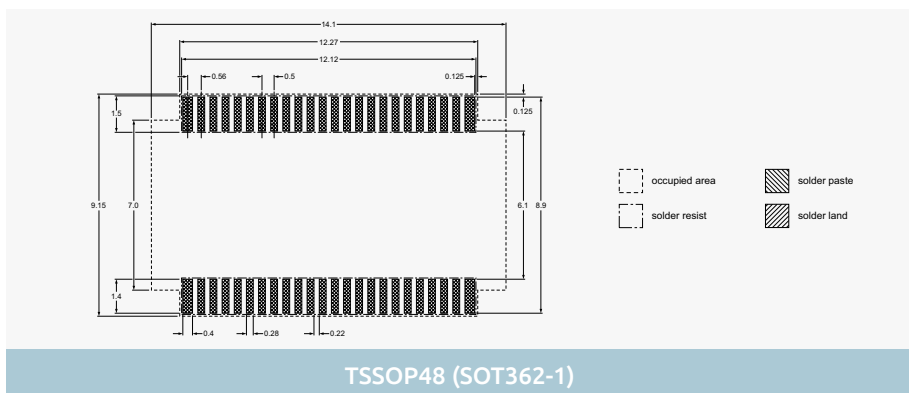
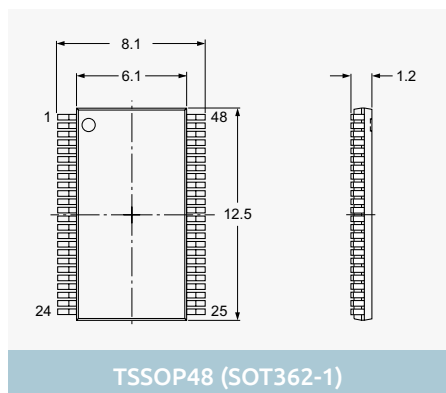
Dimensions in mm

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24-pin SMD packages



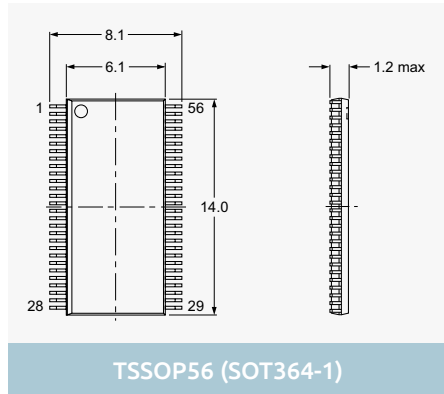
48-pin SMD packages



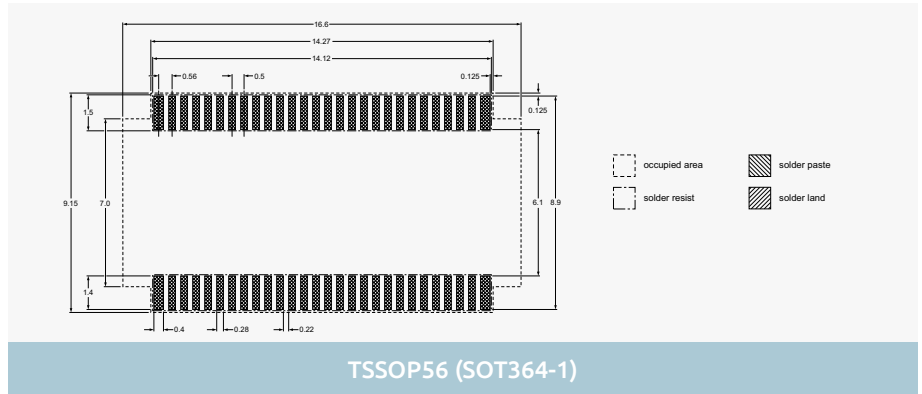
Dimensions in mm

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56-pin SMD packages



TSSOP56 (SOT364-1)



TSSOP56 (SOT364-1)

Dimensions in mm

Dimensions in mm

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